

A large, light blue stylized graphic of a spider, positioned diagonally across the page. It features a circular body and a long, curved leg extending towards the top right.

**SPIDER+ 12V**

**TLE75242-EMH**

SPI Driver for Enhanced Relay Control

**Data Sheet**

Rev. 1.0, 2016-06-22

**Automotive Power**

## Table of Contents

<b>1</b>	<b>Overview</b>	<b>6</b>
<b>2</b>	<b>Block Diagram and Terms</b>	<b>10</b>
2.1	Block Diagram	10
2.2	Terms	11
<b>3</b>	<b>Pin Configuration</b>	<b>12</b>
3.1	Pin Assignment	12
3.2	Pin Definitions and Functions	13
<b>4</b>	<b>General Product Characteristics</b>	<b>15</b>
4.1	Absolute Maximum Ratings	15
4.2	Functional Range	17
4.3	Thermal Resistance	18
4.3.1	PCB set up	18
4.3.2	Thermal Impedance	20
<b>5</b>	<b>Control Pins</b>	<b>21</b>
5.1	Input pins	21
5.2	IDLE pin	21
5.3	Electrical Characteristics Control Pins	23
<b>6</b>	<b>Power Supply</b>	<b>24</b>
6.1	Operation Modes	27
6.1.1	Power-up	29
6.1.2	Sleep mode	29
6.1.3	Idle mode	29
6.1.4	Active mode	29
6.1.5	Limp Home mode	29
6.1.6	Definition of Power Supply modes transition times	30
6.2	Reset condition	30
6.2.1	Undervoltage on $V_S$	30
6.2.2	Low Operating Power on $V_{DD}$	31
6.3	Electrical Characteristics Power Supply	32
<b>7</b>	<b>Power Stages</b>	<b>39</b>
7.1	Output ON-state resistance	39
7.1.1	Switching Resistive Loads	39
7.1.2	Inductive Output Clamp	39
7.1.3	Maximum Load Inductance	41
7.2	Inverse Current Behavior	41
7.3	Switching Channels in parallel	42
7.4	“Bulb Inrush Mode” (BIM)	42
7.5	Automatic PWM Generator	43
7.6	Electrical Characteristics Power Stages	46
<b>8</b>	<b>Protection Functions</b>	<b>51</b>
8.1	Over Load Protection	51
8.2	Over Temperature Protection	51
8.3	Over Temperature and Over Load Protection in Limp Home mode	52
8.4	Reverse Polarity Protection	52
8.5	Over Voltage Protection	52
8.6	Electrical Characteristics Protection	53

## Table of Contents

<b>9</b>	<b>Diagnosis</b>	55
9.1	Over Load and Over Temperature	55
9.2	Output Status Monitor	55
9.3	Open Load at ON	57
9.3.1	Open Load at ON - direct channel diagnosis	58
9.3.2	Open Load at ON - diagnosis loop	58
9.3.3	<b>OLON</b> bit	60
9.4	Electrical Characteristics Diagnosis	61
<b>10</b>	<b>Serial Peripheral Interface (SPI)</b>	63
10.1	SPI Signal Description	63
10.2	Daisy Chain Capability	64
10.3	Timing Diagrams	65
10.4	Electrical Characteristics	66
10.5	SPI Protocol	69
10.6	SPI Registers Overview	72
10.6.1	Standard Diagnosis	72
10.6.2	Register structure	74
10.6.3	Register summary	78
10.6.4	SPI command quick list	79
<b>11</b>	<b>Application Information</b>	81
11.1	Further Application Information	82
<b>12</b>	<b>Package Outlines</b>	83
<b>13</b>	<b>Revision History</b>	85

## List of Figures

Figure 1	Block Diagram of TLE75242-EMH	10
Figure 2	Voltage and Current definition	11
Figure 3	Pin Configuration TLE75242-EMH in PG-SSOP-24-9	12
Figure 4	2s2p PCB Cross Section	18
Figure 5	PC Board for Thermal Simulation with 600 mm <sup>2</sup> Cooling Area	19
Figure 6	PC Board for Thermal Simulation with 2s2p Cooling Area	19
Figure 7	Typical Thermal Impedance. PCB setup according <a href="#">Chapter 4.3.1</a>	20
Figure 8	Typical Thermal Resistance. PCB setup 1s0p	20
Figure 9	Input Mapping	21
Figure 10	TLE75242-EMH Internal Power Supply concept	24
Figure 11	“Cranking Operative Range”	25
Figure 12	Operation Mode state diagram	28
Figure 13	Transition Time diagram	30
Figure 14	$V_S$ Undervoltage Behavior	31
Figure 15	Switching a Resistive Load	39
Figure 16	Output Clamp concept	40
Figure 17	Output Clamp concept	40
Figure 18	Output Clamp concept	41
Figure 19	Bulb Inrush Mode (BIM) operation	43
Figure 20	PWM Generator Mappings	45
Figure 21	Over Load current thresholds	51
Figure 22	Latch OFF at Over Load	51
Figure 23	Restart timer in Limp Home mode	52
Figure 24	Output Status Monitor timing	55
Figure 25	Output Status Monitor - concept (Low-Side channels)	56
Figure 26	Output Status Monitor - concept (auto-configurable channel as High-Side)	56
Figure 27	Output Status Monitor - concept (Auto-configurable channel as Low-Side)	57
Figure 28	Output Status Monitor - concept (High-Side channels)	57
Figure 29	Open Load at ON timings (direct channels diagnosis)	58
Figure 30	Open Load at ON timings (diagnosis loop - channels driven by micro-controller directly)	59
Figure 31	Open Load at ON timings (diagnosis loop - channels driven by internal PWM Generators)	60
Figure 32	Serial Peripheral Interface	63
Figure 33	Combinatorial Logic for TER bit	63
Figure 34	Daisy Chain Configuration	64
Figure 35	Data Transfer in Daisy Chain Configuration	65
Figure 36	Timing Diagram SPI Access	65
Figure 37	Relationship between SI and SO during SPI communication	69
Figure 38	Register content sent back to $\mu C$	69
Figure 39	TLE75242-EMH response after a error in transmission	70
Figure 40	TLE75242-EMH response after coming out of Power-On reset at $V_{DD}$	70
Figure 41	TLE75242-EMH response after a command syntax error	70
Figure 42	TLE75242-EMH Application Diagram	81
Figure 43	PG-SSOP-24-9 Package drawing	83
Figure 44	TLE75242-EMH Package pads and stencil	83

## List of Tables

Table 1	Product Summary	6
Table 2	Absolute Maximum Ratings	15
Table 3	Functional range	17
Table 4	Thermal Resistance	18
Table 5	Electrical Characteristics: Control Pins	23
Table 6	Device capability as function of $V_S$ and $V_{DD}$	26
Table 7	Device function in relation to operation modes, $V_S$ and $V_{DD}$ voltages	28
Table 8	Electrical Characteristics Power Supply	32
Table 9	<b>HWCR_PWM.ADJ</b> coefficients overview	43
Table 10	Electrical Characteristics: Power Stage	46
Table 11	Electrical Characteristics Protection	53
Table 12	Electrical Characteristics Diagnosis	61
Table 13	Electrical Characteristics Serial Peripheral Interface (SPI)	66
Table 14	SPI Command summary	71
Table 15	Standard Diagnosis	72
Table 16	Register structure - all registers (with the exclusion of <b>PWM_CR0</b> and <b>PWM_CR1</b> )	74
Table 17	Register structure - <b>PWM_CR0</b> and <b>PWM_CR1</b>	74
Table 18	Register addressing space	74
Table 19	Addressable registers (basic functions)	78
Table 20	Addressable registers (advanced functions)	78
Table 21	SPI command quick list	79
Table 22	Suggested Component values	81



## 1 Overview

### Features

- 16-bit serial peripheral interface for control and diagnosis
- Daisy Chain capability SPI also compatible with 8-bit SPI devices
- 2 CMOS compatible parallel input pins with Input Mapping functionality
- Cranking capability down to  $V_S = 3.0\text{ V}$  (supports LV124)
- Digital supply voltage range compatible with 3.3 V and 5 V microcontrollers
- Bulb Inrush Mode (BIM) to drive 2 W lamps and electronic loads
- Two internal PWM Generators for  $\mu\text{C}$  offload
- Independent supply pin ( $V_{S\_HS}$ ) for high-side channels
- Very low quiescent current (with usage of IDLE pin)
- Limp Home mode (with usage of IDLE and IN pins)
- Green Product (RoHS compliant)
- AEC Qualified

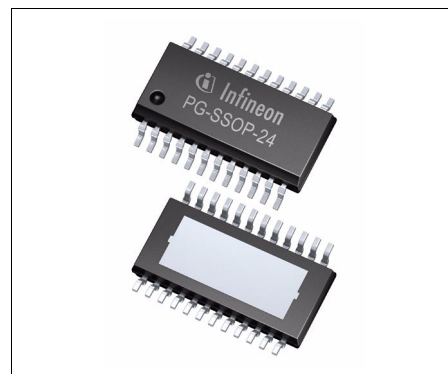
### Description

The TLE75242-EMH is an eight channel low-side and high-side power switch in PG-SSOP-24-9 package providing embedded protective functions. It is specially designed to control relays and LEDs in automotive and industrial applications.

A serial peripheral interface (SPI) is utilized for control and diagnosis of the loads as well as of the device. For direct control and PWM there are two input pins available connected to two outputs by default. Additional or different outputs can be controlled by the same input pins (programmable via SPI).

**Table 1 Product Summary**

Parameter	Symbol	Values
Analog supply voltage	$V_S$	3.0 V ... 28 V
Digital supply voltage	$V_{DD}$	3.0 V ... 5.5 V
Minimum overvoltage protection	$V_{S(AZ)}$	42 V (see <a href="#">Chapter 8.5</a> for details)
Maximum on-state resistance at $T_J = 150\text{ }^\circ\text{C}$	$R_{DS(ON)}$	2.2 $\Omega$
Nominal load current ( $T_A = 85\text{ }^\circ\text{C}$ , all channels)	$I_{L(NOM)}$	330 mA
Maximum Energy dissipation - repetitive	$E_{AR}$	10 mJ @ $I_{L(EAR)} = 220\text{ mA}$
Minimum Drain to Source clamping voltage	$V_{DS(CL)}$	42 V (when used as low-side switches)



**PG-SSOP-24-9**

Package	Marking
PG-SSOP-24-9	TLE75242EMH

**Table 1**     **Product Summary** (cont'd)

Parameter	Symbol	Values
Maximum Source to Ground clamping voltage	$V_{OUT\_S(CL)} V_{OUT(CL)}$	-16 V
Maximum overload switch OFF threshold	$I_{L(OVL0)}$	2.3 A
Maximum total quiescent current at $T_J \leq 85\text{ °C}$	$I_{SLEEP}$	5 $\mu$ A
Maximum SPI clock frequency	$f_{SCLK}$	5 MHz

### Applications

- Low-side and High-side switches for 12 V in automotive or industrial applications such as lighting, heating, motor driving, energy and power distribution
- Especially designed for driving relays, LEDs and motors.

### Protective Functions

- Reverse battery protection on  $V_S$  without external components
- Short circuit to ground and battery protection
- Stable behavior at under voltage conditions ("Lower Supply Voltage Range for Extended Operation")
- Over Current latch OFF
- Thermal shutdown latch OFF
- Overvoltage protection
- Loss of ground protection
- Loss of battery protection
- Electrostatic discharge (ESD) protection

### Diagnostic Features

- Latched diagnostic information via SPI register
- Over Load detection at ON state
- Open Load detection at OFF state using Output Status Monitor function
- Output Status Monitor
- Input Status Monitor
- Open Load detection at ON state

### Application Specific Functions

- Fail-safe activation via Input pins in Limp-Home Mode
- SPI with Daisy Chain capability
- Safe operation at low battery voltage (cranking)
- 2 W lamps, 5 W lamps with two channels in parallel mode and enhanced capacitive loads driving capability (Bulb Inrush Mode)
- Two independent internal PWM generators to drive e.g. LEDs
- One supply pin for high-side switches independent from main supply pin  $V_S$

### Detailed Description

The TLE75242-EMH is an eight channel low-side and high-side switch providing embedded protective functions. The output stages incorporate two low-side, four high-side and two auto-configurable high-side or low-side switches (typical  $R_{DS(ON)}$  at  $T_J = 25^\circ\text{C}$  is 1  $\Omega$ ). The auto-configurable switches can be utilized in high-side or low-side configuration just by connecting the load accordingly. Protection and diagnosis functions adjust automatically to the hardware configuration. Driving a load from high-side offers the possibility to perform Open Load at ON diagnosis.

The 16-bit serial peripheral interface (SPI) is utilized to control and diagnose the device and the loads. The SPI interface provides daisy chain capability in order to assemble multiple devices (also devices with 8 bit SPI) in one SPI chain by using the same number of microcontroller pins.

This device is designed for low supply voltage operation, therefore being able to keep its state at low battery voltage ( $V_S \geq 3.0\text{ V}$ ). The SPI functionality, including the possibility to program the device, is available only when the digital power supply is present (see [Chapter 6](#) for more details).

The TLE75242-EMH is equipped with two input pins that are connected to two configurable outputs, making them controllable even when the digital supply voltage is not available. With the Input Mapping functionality it is possible to connect the input pins to different outputs, or assign more outputs to the same input pin. In this case more channels can be controlled with one signal applied to one input pin.

In Limp Home mode (Fail-Safe mode) the input pins are directly routed to channels 2 and 3. When IDLE pin is “low”, it is possible to activate the two channels using the input pins independently from the presence of the digital supply voltage.

The device provides diagnosis of the load via Open Load at ON state, Open Load at OFF state (with [DIAG\\_OSM.OUTn](#) bits) and short circuit detection. For Open Load at OFF state detection, a internal current source  $I_{OL}$  can be activated via SPI.

Each output stage is protected against short circuit. In case of Overload, the affected channel switches OFF when the Overload Detection Current  $I_{L(OVLn)}$  is reached and can be reactivated via SPI. In Limp Home mode operation, the channels connected to an input pin set to “high” restart automatically after Output Restart time  $t_{RETRY(LH)}$  is elapsed. Temperature sensors are available for each channel to protect the device against Over Temperature.

The power transistors are built by N-channel power MOSFET with one central chargepump for auto-configurable and high-side channels. The inputs are ground referenced TTL compatible. The device is monolithically integrated in Smart Power Technology.

## 2 Block Diagram and Terms

### 2.1 Block Diagram

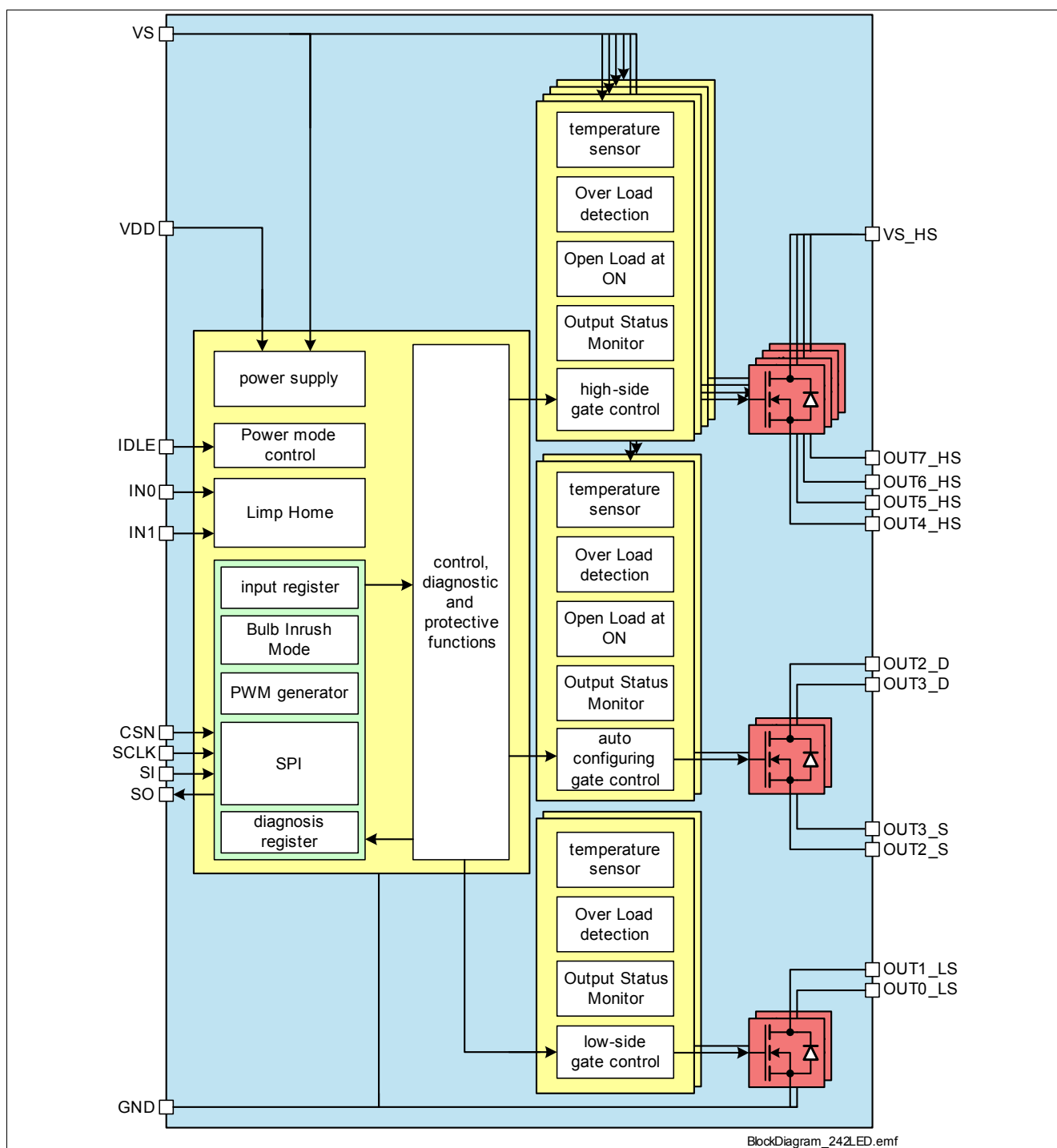


Figure 1 Block Diagram of TLE75242-EMH

## 2.2 Terms

**Figure 2** shows all terms used in this data sheet, with associated convention for positive values.

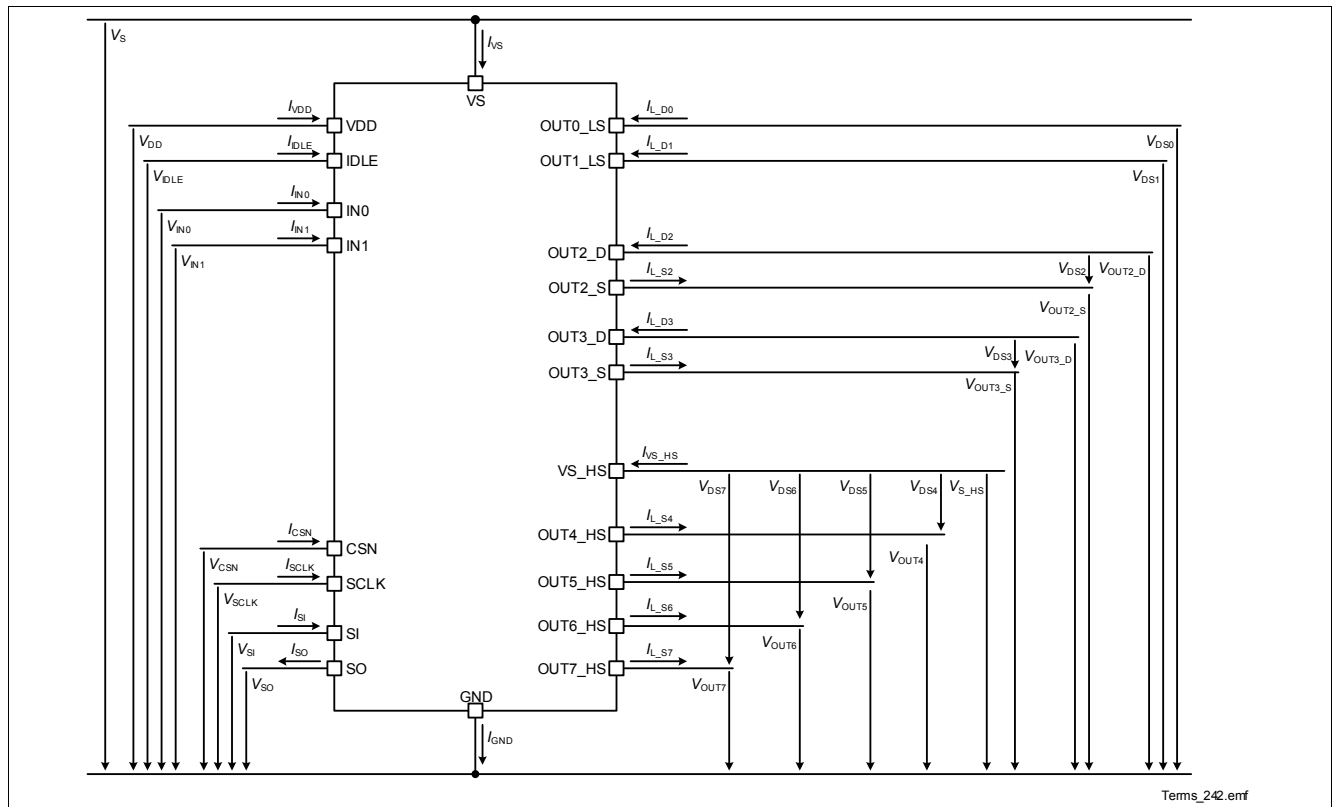


Figure 2 Voltage and Current definition

In all tables of electrical characteristics the channel related symbols without channel numbers are valid for each channel separately (e.g.  $V_{DS}$  specification is valid for  $V_{DS0} \dots V_{DS7}$ ).

Furthermore, parameters relative to output current can be indicated without specifying whether the current is going into the Drain pin or going out of the Source pin, unless otherwise specified. For instance, nominal output current can be indicated in the following ways:  $I_{L(NOM)}$   $I_{L\_LS(NOM)}$   $I_{L\_HS(NOM)}$   $I_{L\_D(NOM)}$   $I_{L\_S(NOM)}$

All SPI registers bits are marked as follows: ADDR.PARAMETER (e.g. HWCR.RST) with the exception of the bits in the Diagnosis frames which are marked only with PARAMETER (e.g. UVRVS).

### 3 Pin Configuration

#### 3.1 Pin Assignment

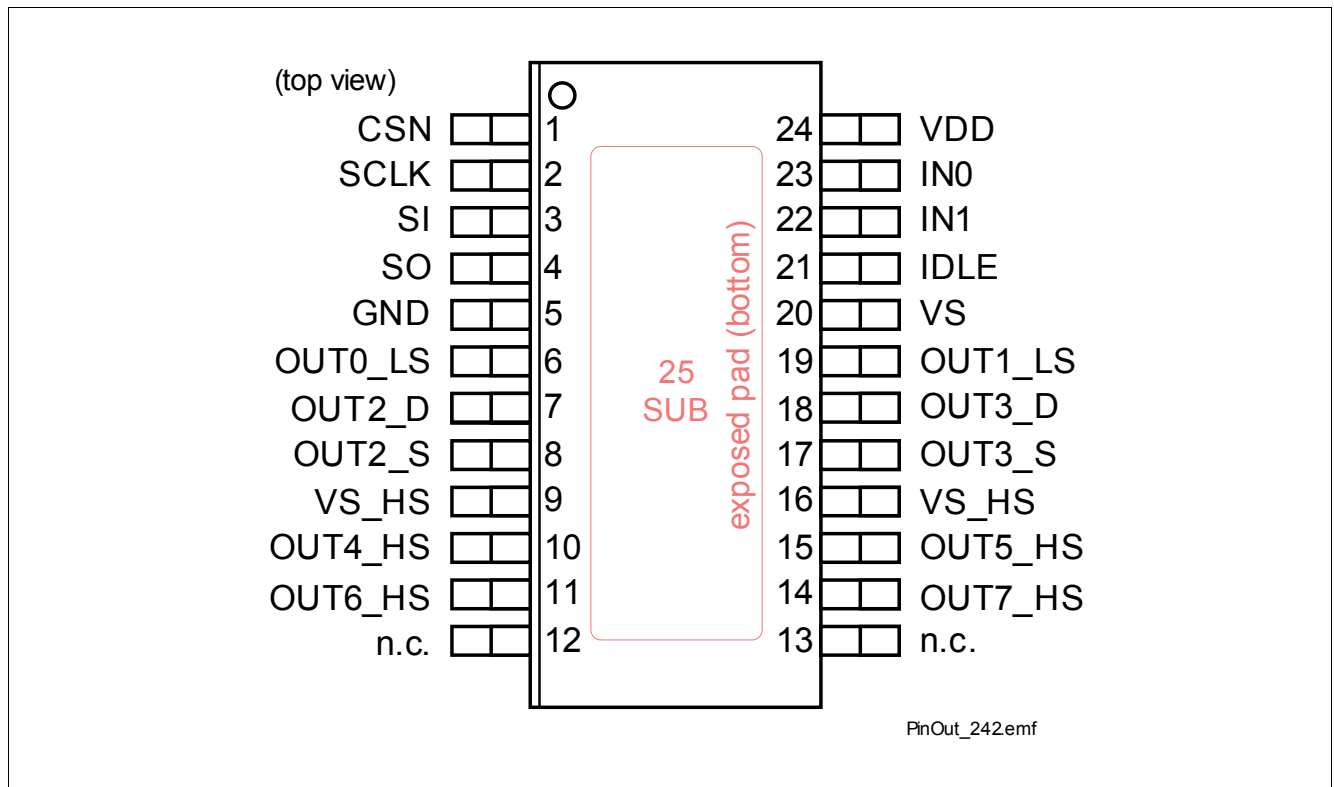


Figure 3 Pin Configuration TLE75242-EMH in PG-SSOP-24-9

### 3.2 Pin Definitions and Functions

Pin	Symbol	I/O	Function
<b>Power Supply Pins</b>			
20	VS	–	<b>Analog supply <math>V_S</math></b> Positive supply voltage for power switches gate control (incl. protections)
9, 16	VS_HS	–	<b>Analog supply <math>V_{S\_HS}</math></b> Positive supply voltage for power switches drain current
24	VDD	–	<b>Digital supply <math>V_{DD}</math></b> Supply voltage for SPI with support function to $V_S$
5	GND	–	<b>Ground</b> Ground connection (also for the low-side switches)
<b>SPI Pins</b>			
1	CSN	I	<b>Chip Select</b> “low” active, integrated pull-up to $V_{DD}$
2	SCLK	I	<b>Serial Clock</b> “high” active, integrated pull-down to ground
3	SI	I	<b>Serial Input</b> “high” active, integrated pull-down to ground
4	SO	O	<b>Serial Output</b> “Z” (tri-state) when CSN is “high”
<b>Input and Stand-by Pins</b>			
21	IDLE	I	<b>Idle mode</b> power mode control, “high” activates Idle mode, integrated pull-down to ground
23	IN0	I	<b>Input pin 0</b> connected to channel 2 by default and in Limp Home mode, “high” active, integrated pull-down to ground
22	IN1	I	<b>Input pin 1</b> connected to channel 3 by default and in Limp Home mode, “high” active, integrated pull-down to ground
<b>Power Output Pins</b>			
6	OUT0_LS	O	Drain of low-side power transistor (channel 0)
7	OUT2_D	O	Drain of auto configurable power transistor (channel 2)
8	OUT2_S	O	Source of auto configurable power transistor (channel 2)
17	OUT3_S	O	Source of auto configurable power transistor (channel 3)
18	OUT3_D	O	Drain of auto configurable power transistor (channel 3)
19	OUT1_LS	O	Drain of low-side power transistor (channel 1)
10	OUT4_HS	O	Source of high-side power transistor (channel 4)
11	OUT6_HS	O	Source of high-side power transistor (channel 6)
14	OUT7_HS	O	Source of high-side power transistor (channel 7)
15	OUT5_HS	O	Source of high-side power transistor (channel 5)

## Pin Configuration

Pin	Symbol	I/O	Function
<b>Not Connected pins / Cooling Tab</b>			
12, 13	n.c.	–	Not Connected, internally not bonded
25	GND	–	<b>Exposed pad</b> It is recommended to connect it to PCB ground for cooling and EMC - not usable as electrical GND pin. Electrical ground must be provided by pin 5.

## 4 General Product Characteristics

### 4.1 Absolute Maximum Ratings

**Table 2 Absolute Maximum Ratings <sup>1)</sup>**

$T_J = -40\text{ °C to }+150\text{ °C}$

all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Voltage ranges specified for  $V_S$  apply also to  $V_{S\_HS}$  (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Supply Voltages							
Analog Supply voltage	$V_S$	-0.3	–	28	V	–	P_4.1.1
Digital Supply voltage	$V_{DD}$	-0.3	–	5.5	V	–	P_4.1.2
Supply voltage for load dump protection	$V_{S(LD)}$	–	–	42	V	<sup>2)</sup>	P_4.1.3
Supply voltage for short circuit protection (single pulse)	$V_{S(SC)}$	0	–	28	V	–	P_4.1.4
Reverse polarity voltage	$-V_{S(REV)}$	–	–	16	V	<sup>3)</sup> $T_{J(0)} = 25\text{ °C}$ $t \leq 2\text{ min}$ See <a href="#">Chapter 11</a> for general setup. $R_L = 70\text{ }\Omega$ on all channels	P_4.1.5
Current through VS pin	$I_{VS}$	-10	–	10	mA	$t \leq 2\text{ min}$	P_4.1.7
Current through VDD pin	$I_{VDD}$	-50	–	10	mA	$t \leq 2\text{ min}$	P_4.1.8
Power Stages							
Load current	$ I_L $	–	–	$I_{L(OVL0)}$	A	single channel	P_4.1.9
Voltage at power transistor	$V_{DS}$	-0.3	–	42	V	–	P_4.1.10
Power transistor source voltage	$V_{OUT\_S}$	-16	–	$V_{OUT\_D} + 0.3$	V	–	P_4.1.11
Power transistor drain voltage ( $V_{OUT\_S} \geq 0\text{ V}$ )	$V_{OUT\_D}$	$V_{OUT\_S} - 0.3$	–	42	V	–	P_4.1.12
Power transistor drain voltage ( $V_{OUT\_S} < 0\text{ V}$ )	$V_{OUT\_D}$	-0.3	–	42	V	–	P_4.1.59
Maximum energy dissipation single pulse	$E_{AS}$	–	–	50	mJ	<sup>4)</sup> $T_{J(0)} = 25\text{ °C}$ $I_{L(0)} = 2 \cdot I_{L(EAR)}$	P_4.1.13
Maximum energy dissipation single pulse	$E_{AS}$	–	–	25	mJ	<sup>4)</sup> $T_{J(0)} = 150\text{ °C}$ $I_{L(0)} = 400\text{ mA}$	P_4.1.14

## General Product Characteristics

**Table 2 Absolute Maximum Ratings (cont'd)<sup>1)</sup>**
 $T_J = -40\text{ °C to }+150\text{ °C}$ 

all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Voltage ranges specified for  $V_S$  apply also to  $V_{S\_HS}$  (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Maximum energy dissipation repetitive pulses - $I_{L(EAR)}$	$E_{AR}$	–	–	10	mJ	<sup>4)</sup> $T_{J(0)} = 85\text{ °C}$ $I_{L(0)} = I_{L(EAR)}$ $2 \cdot 10^6$ cycles	P_4.1.15

**IDLE pin**

Voltage at IDLE pin	$V_{IDLE}$	-0.3		5.5	V	–	P_4.1.23
Current through IDLE pin	$I_{IDLE}$	-0.75		0.75	mA	–	P_4.1.25
Current through IDLE pin	$I_{IDLE}$	-10.0		2.0	mA	$t \leq 2\text{ min.}$	P_4.1.26

**Input Pins**

Voltage at input pins	$V_{IN}$	-0.3		5.5	V	–	P_4.1.28
Current through input pins	$I_{IN}$	-0.75		0.75	mA	–	P_4.1.30
Current through input pins	$I_{IN}$	-10.0		2.0	mA	$t \leq 2\text{ min.}$	P_4.1.31

**SPI Pins**

Voltage at chip select pin	$V_{CSN}$	-0.3		5.5	V	–	P_4.1.33
Current through chip select pin	$I_{CSN}$	-0.75		0.75	mA	–	P_4.1.34
Current through chip select pin	$I_{CSN}$	-10.0		2.0	mA	$t \leq 2\text{ min.}$	P_4.1.35
Voltage at serial clock pin	$V_{SCLK}$	-0.3		5.5	V		P_4.1.37
Current through serial clock pin	$I_{SCLK}$	-0.75		0.75	mA	–	P_4.1.38
Current through serial clock pin	$I_{SCLK}$	-10.0		2.0	mA	$t \leq 2\text{ min.}$	P_4.1.39
Voltage at serial input pin	$V_{SI}$	-0.3		5.5	V		P_4.1.41
Current through serial input pin	$I_{SI}$	-0.75		0.75	mA	–	P_4.1.42
Current through serial input pin	$I_{SI}$	-10.0		2.0	mA	$t \leq 2\text{ min.}$	P_4.1.43
Voltage at serial output pin SO	$V_{SO}$	-0.3		$V_{DD}+0.3$	V		P_4.1.58
Current through serial output pin SO	$I_{SO}$	-0.75		0.75	mA		P_4.1.45
Current through serial output pin SO	$I_{SO}$	-2.0		10.0	mA	$t \leq 2\text{ min.}$	P_4.1.46

**Temperatures**

Junction Temperature	$T_J$	-40	–	150	°C	–	P_4.1.48
Storage Temperature	$T_{stg}$	-55	–	150	°C	–	P_4.1.49

**ESD Susceptibility**

ESD Susceptibility HBM OUT pins vs. $V_S$ or GND	$V_{ESD}$	-4	–	4	kV	<sup>5)</sup> HBM	P_4.1.50
ESD Susceptibility HBM other pins	$V_{ESD}$	-2	–	2	kV	<sup>5)</sup> HBM	P_4.1.51

**Table 2 Absolute Maximum Ratings (cont'd)<sup>1)</sup>**
 $T_J = -40\text{ °C to }+150\text{ °C}$ 

all voltages with respect to ground, positive current flowing into pin (unless otherwise specified)

Voltage ranges specified for  $V_S$  apply also to  $V_{S\_HS}$  (unless otherwise specified)

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
ESD Susceptibility CDM Pin 1, 12, 13, 24 (corner pins)	$V_{ESD}$	-750	–	750	V	<sup>6)</sup> CDM	P_4.1.52
ESD Susceptibility CDM	$V_{ESD}$	-500	–	500	V	<sup>6)</sup> CDM	P_4.1.54

1) Not subject to production test, specified by design.

2) For a duration of  $t_{on} = 400\text{ ms}$ ;  $t_{on}/t_{off} = 10\%$ ; limited to 100 pulses

3) Device is mounted on a FR4 2s2p board according to Jedec JESD51-2,-5,-7 at natural convection; the Product (Chip+Package) was simulated on a 76.2 \* 114.3 \* 1.5 mm board with 2 inner copper layers (2 \* 70  $\mu\text{m}$  Cu, 2 \* 35  $\mu\text{m}$  Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.

4) Pulse shape represents inductive switch off:  $I_L(t) = I_L(0) \times (1 - t / t_{pulse})$ ;  $0 < t < t_{pulse}$ 

5) ESD susceptibility, HBM according to ANSI/ESDA/JEDEC JS001 (1.5k  $\Omega$ , 100 pF)

6) ESD susceptibility, Charged Device Model "CDM" ESDA STM5.3.1 or ANSI/ESD S.5.3.1

## Notes

- Stresses above the ones listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.
- Integrated protection functions are designed to prevent IC destruction under fault conditions described in the data sheet. Fault conditions are considered as "outside" normal operating range. Protection functions are not designed for continuous repetitive operation.

## 4.2 Functional Range

**Table 3 Functional range**

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Supply Voltage Range for Normal Operation	$V_{S(NOR)}$	7	–	18	V	–	P_4.2.1
Upper Supply Voltage Range for Extended Operation	$V_{S(EXT,UP)}$	18	–	28	V	Parameter deviation possible	P_4.2.2
Lower Supply Voltage Range for Extended Operation	$V_{S(EXT,LOW)}$	3	–	7	V	Parameter deviation possible	P_4.2.3
Junction Temperature	$T_J$	-40	–	150	°C	–	P_4.2.4
Logic supply voltage	$V_{DD}$	3	–	5.5	V	–	P_4.2.5

Note: Within the functional or operating range, the IC operates as described in the circuit description. The electrical characteristics are specified within the conditions given in the Electrical Characteristics table.

### 4.3 Thermal Resistance

Note: This thermal data was generated in accordance with JEDEC JESD51 standards. For more information, go to [www.jedec.org](http://www.jedec.org).

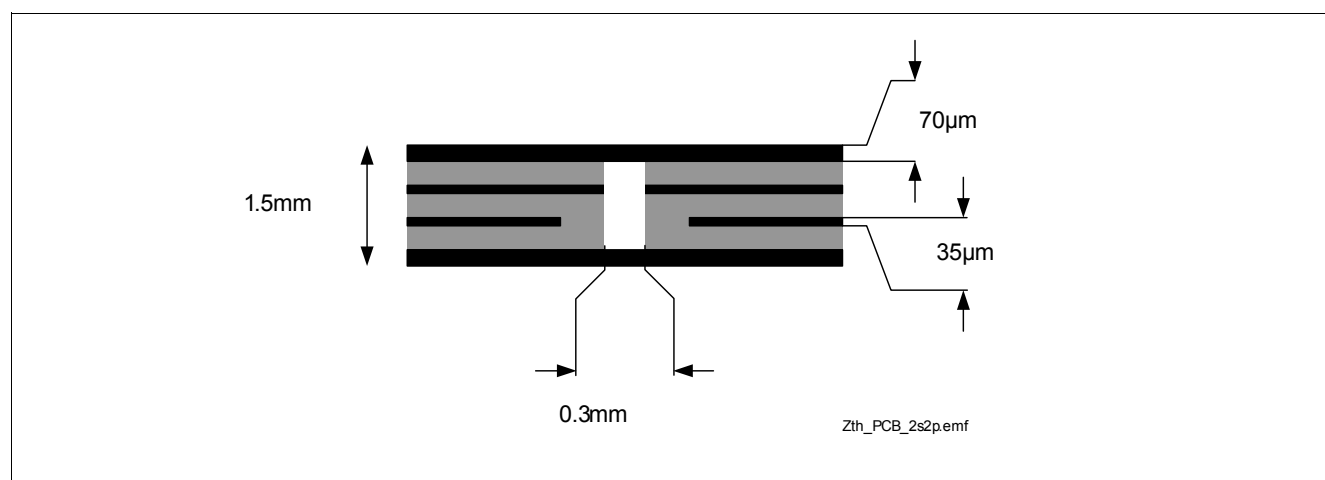
**Table 4 Thermal Resistance**

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Junction to Soldering Point	$R_{thJSP}$	–	5	7	K/W	<sup>1)</sup> measured to exposed pad (pin 25)	P_4.3.4
Junction to Ambient	$R_{thJA}$	–	32	–	K/W	<sup>1)2)</sup>	P_4.3.5

1) not subject to production test, specified by design

2) Specified  $R_{thJA}$  value is according to Jedec JESD51-2,-5,-7 at natural convection on FR4 2s2p board; the Product (Chip+Package) was simulated on a 76.2 \* 114.3 \* 1.5 mm board with 2 inner copper layers (2 \* 70  $\mu$ m Cu, 2 \* 35  $\mu$ m Cu). Where applicable a thermal via array under the exposed pad contacted the first inner copper layer.

#### 4.3.1 PCB set up



**Figure 4 2s2p PCB Cross Section**

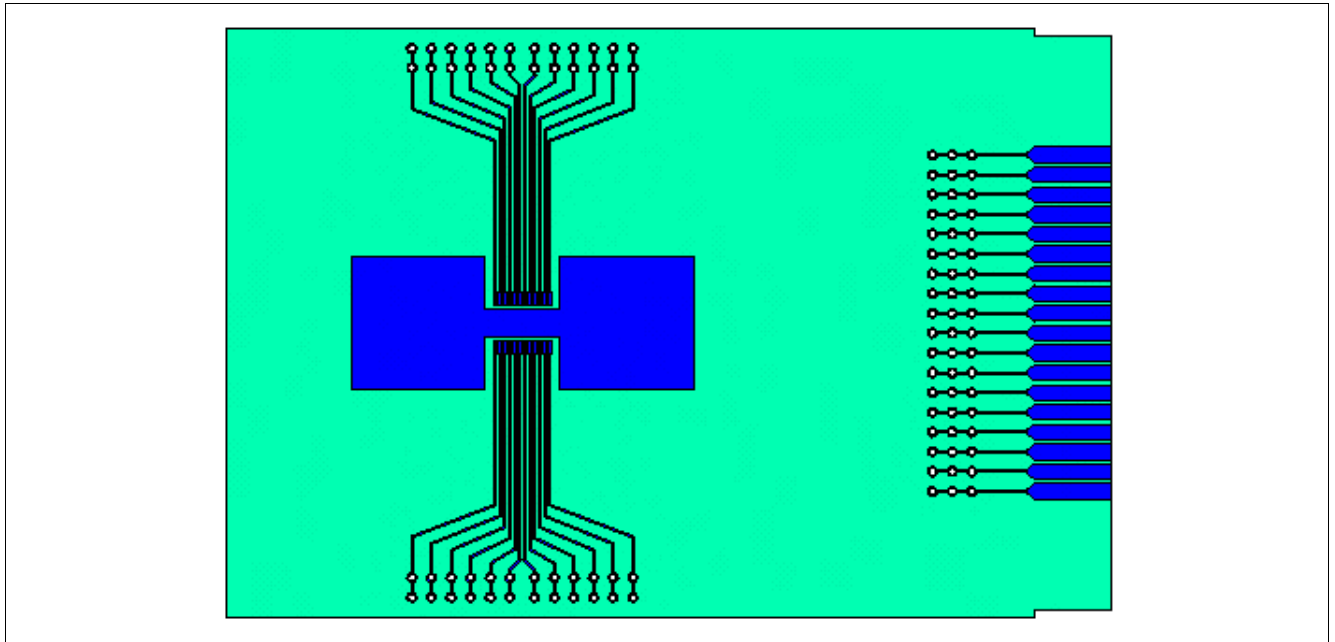


Figure 5 PC Board for Thermal Simulation with 600 mm<sup>2</sup> Cooling Area

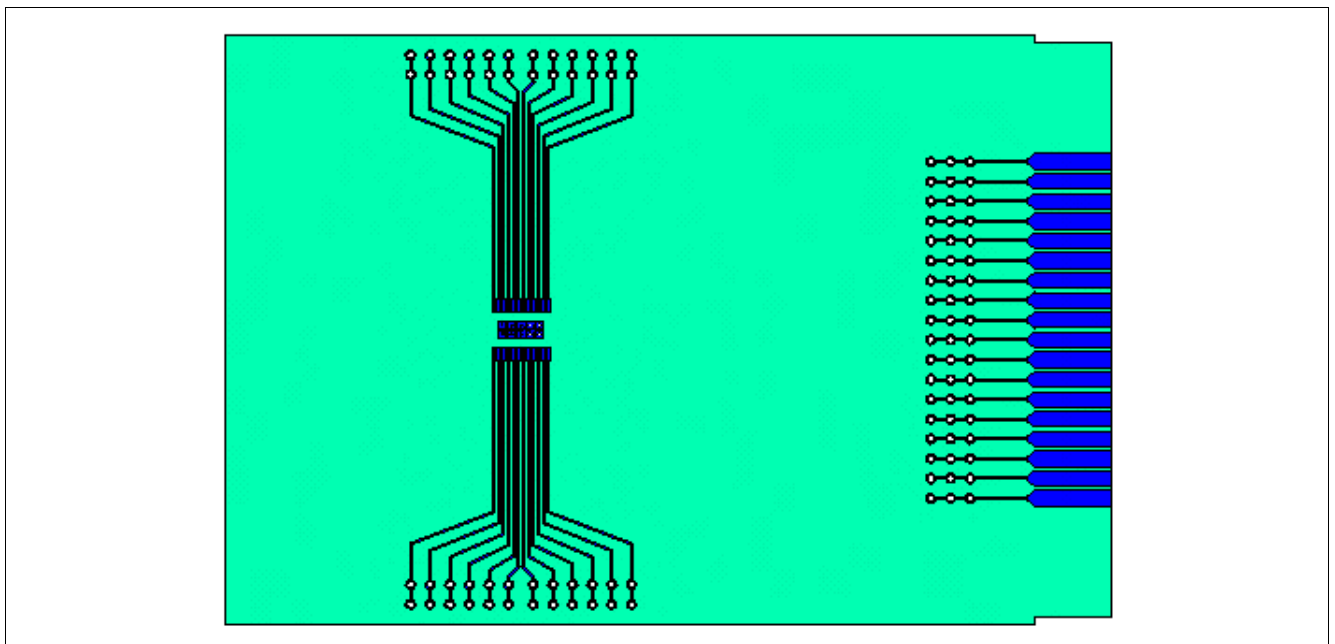


Figure 6 PC Board for Thermal Simulation with 2s2p Cooling Area

## 4.3.2 Thermal Impedance

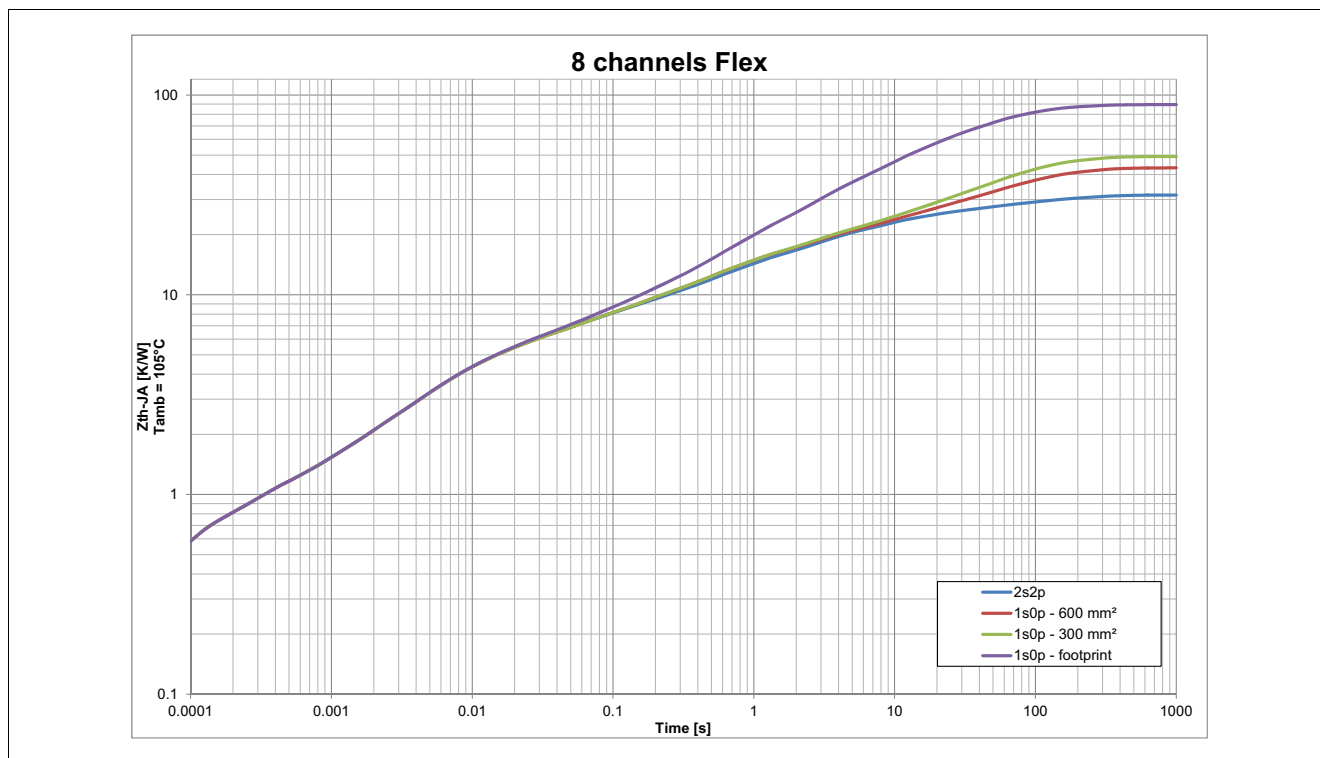


Figure 7 Typical Thermal Impedance. PCB setup according Chapter 4.3.1

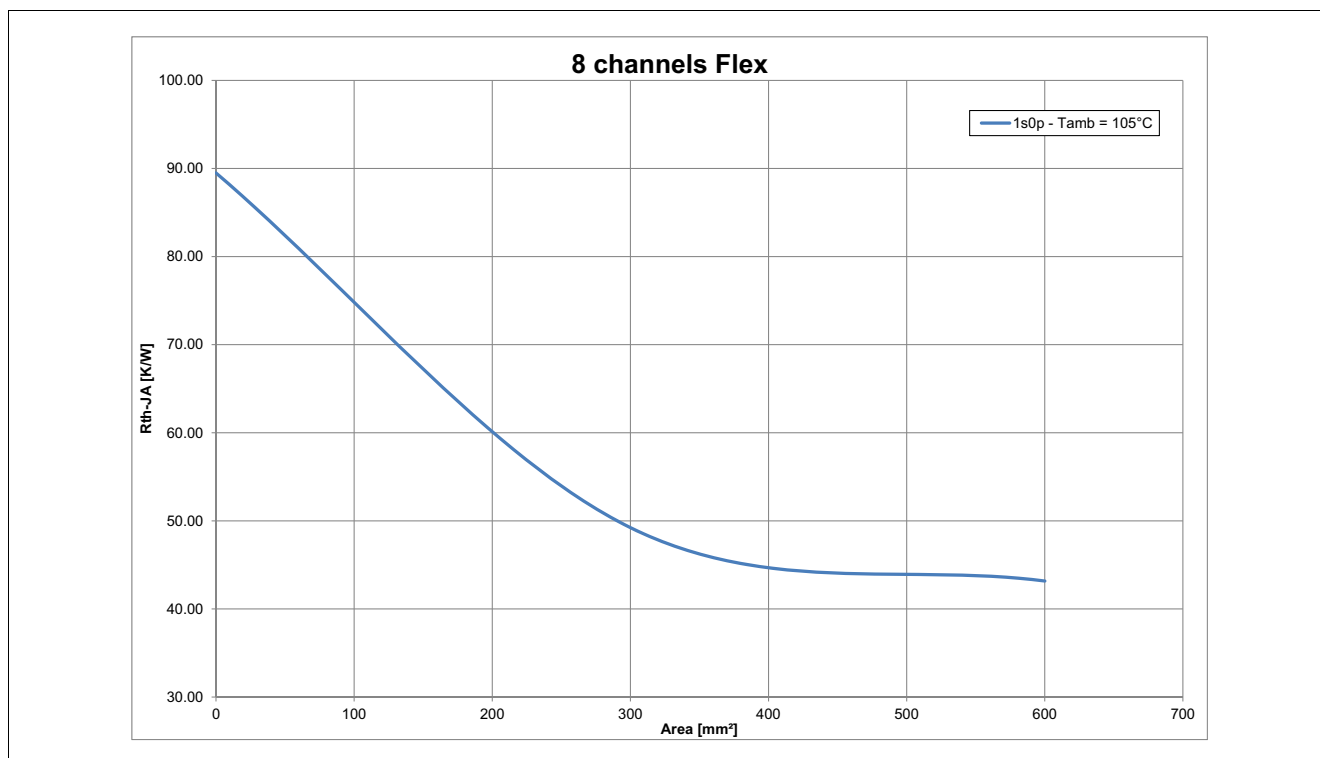


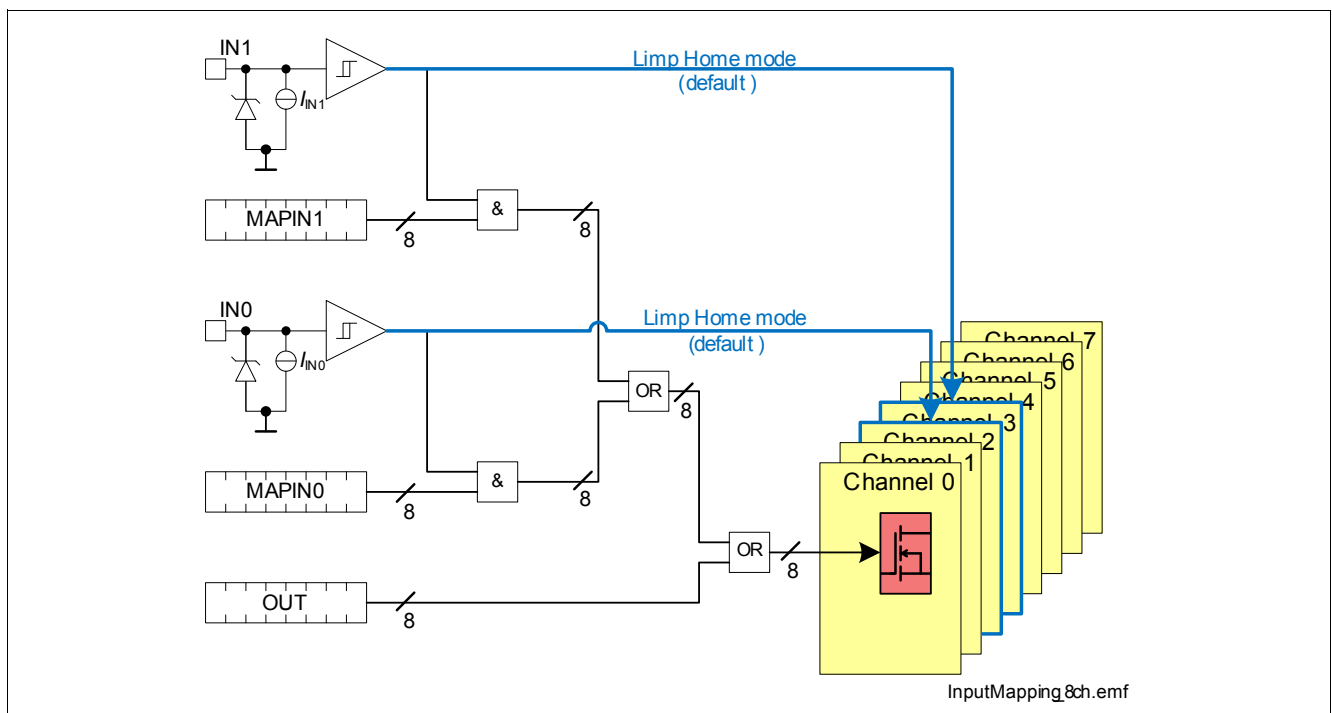
Figure 8 Typical Thermal Resistance. PCB setup 1s0p

## 5 Control Pins

The device has three pins (IN0, IN1 and IDLE) to control directly the device without using SPI.

### 5.1 Input pins

TLE75242-EMH has two input pins available. Each input pin is connected by default to one channel (IN0 to channel 2, IN1 to channel 3). Input Mapping Registers **MAPIN0** and **MAPIN1** can be programmed to connect additional or different channels to each input pin, as shown in **Figure 9**. The signals driving the channels are an OR combination between **OUT** register status, PWM Generators (according to PWM Generator Output Mapping status), IN0 and IN1 (according to Input Mapping registers status). See **Chapter 7.5** for further details.



**Figure 9 Input Mapping**

The logic level of the input pins can be monitored via the Input Status Monitor Register (**INST**). The Input Status Monitor is operative also when TLE75242-EMH is in Limp Home mode. If one of the Input pins is set to “high” and the IDLE pin is set to “low”, the device switches into Limp Home mode and activates the channel mapped by default to the input pins. See **Chapter 6.1.5** for further details.

### 5.2 IDLE pin

The IDLE pin is used to bring the device into Sleep mode operation when is set to “low” and all input pins are set to “low”. When IDLE pin is set to “low” while one of the input pins is set to “high” the device enters Limp Home mode. To ensure a proper mode transition, IDLE pin must be set for at least  $t_{IDLE2SLEEP}$  (P\_6.3.54, transition from “high” to “low”) or  $t_{SLEEP2IDLE}$  (P\_6.3.53, transition from “low” to “high”).

Setting the IDLE pin to “low” has the following consequences:

- All registers in the SPI are reset to default values
- $V_{DD}$  and  $V_S$  Undervoltage detection circuits are disabled to decrease current consumption (if both inputs are set to “low”)

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**Control Pins**

- No SPI communication is allowed (SO pin remains in high impedance state also when CSN pin is set to “low”) if both input pins are set to “low”

### 5.3 Electrical Characteristics Control Pins

**Table 5 Electrical Characteristics: Control Pins**

$V_{DD} = 3\text{ V to }5.5\text{ V}$ ,  $V_S = 7\text{ V to }18\text{ V}$ ,  $T_J = -40\text{ °C to }+150\text{ °C}$  (unless otherwise specified)

Typical values:  $V_{DD} = 5\text{ V}$ ,  $V_S = 13.5\text{ V}$ ,  $T_J = 25\text{ °C}$

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
IDLE pin							
L-input level	$V_{\text{IDLE(L)}}$	0		0.8	V	—	P_5.3.1
H-input level	$V_{\text{IDLE(H)}}$	2.0		5.5	V	—	P_5.3.2
L-input current	$I_{\text{IDLE(L)}}$	5	12	20	μA	$V_{\text{IDLE}} = 0.8\text{ V}$	P_5.3.3
H-input current	$I_{\text{IDLE(H)}}$	14	28	45	μA	$V_{\text{IDLE}} = 2.0\text{ V}$	P_5.3.4
Input Pins							
L-input level	$V_{\text{IN(L)}}$	0		0.8	V	—	P_5.3.5
H-input level	$V_{\text{IN(H)}}$	2.0		5.5	V	—	P_5.3.6
L-input current	$I_{\text{IN(L)}}$	5	12	20	μA	$V_{\text{IN}} = 0.8\text{ V}$	P_5.3.7
H-input current	$I_{\text{IN(H)}}$	14	28	45	μA	$V_{\text{IN}} = 2.0\text{ V}$	P_5.3.8

## 6 Power Supply

The TLE75242-EMH is supplied by three supply voltages:

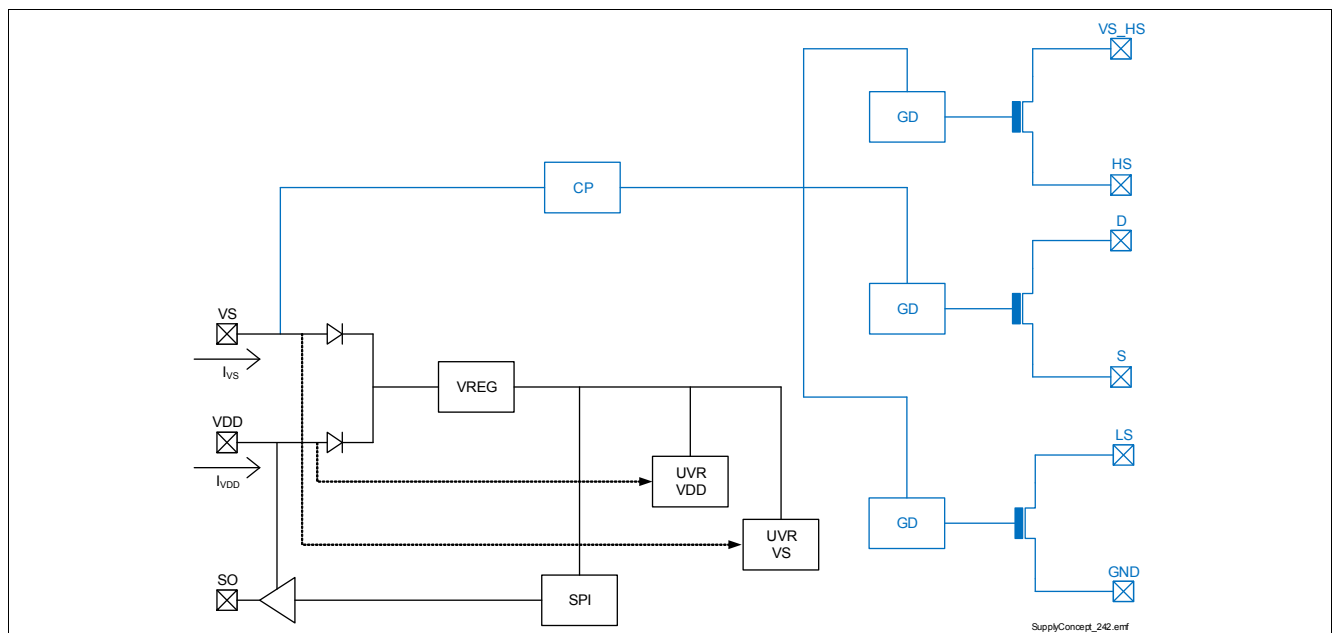
- $V_S$  (analog supply voltage used also for the logic)
- $V_{S\_HS}$  (analog supply voltage used as drain for channels 4, 5, 6 and 7)
- $V_{DD}$  (digital supply voltage)

The  $V_S$  supply line is connected to a battery feed and used, in combination with  $V_{DD}$  supply, for the driving circuitry of the power stages. In situations where  $V_S$  voltage drops below  $V_{DD}$  voltage (for instance during cranking events down to 3.0 V), an increased current consumption may be observed at VDD pin.

$V_S$  and  $V_{DD}$  supply voltages have an undervoltage detection circuit, which prevents the activation of the associated function in case the measured voltage is below the undervoltage threshold. More in detail:

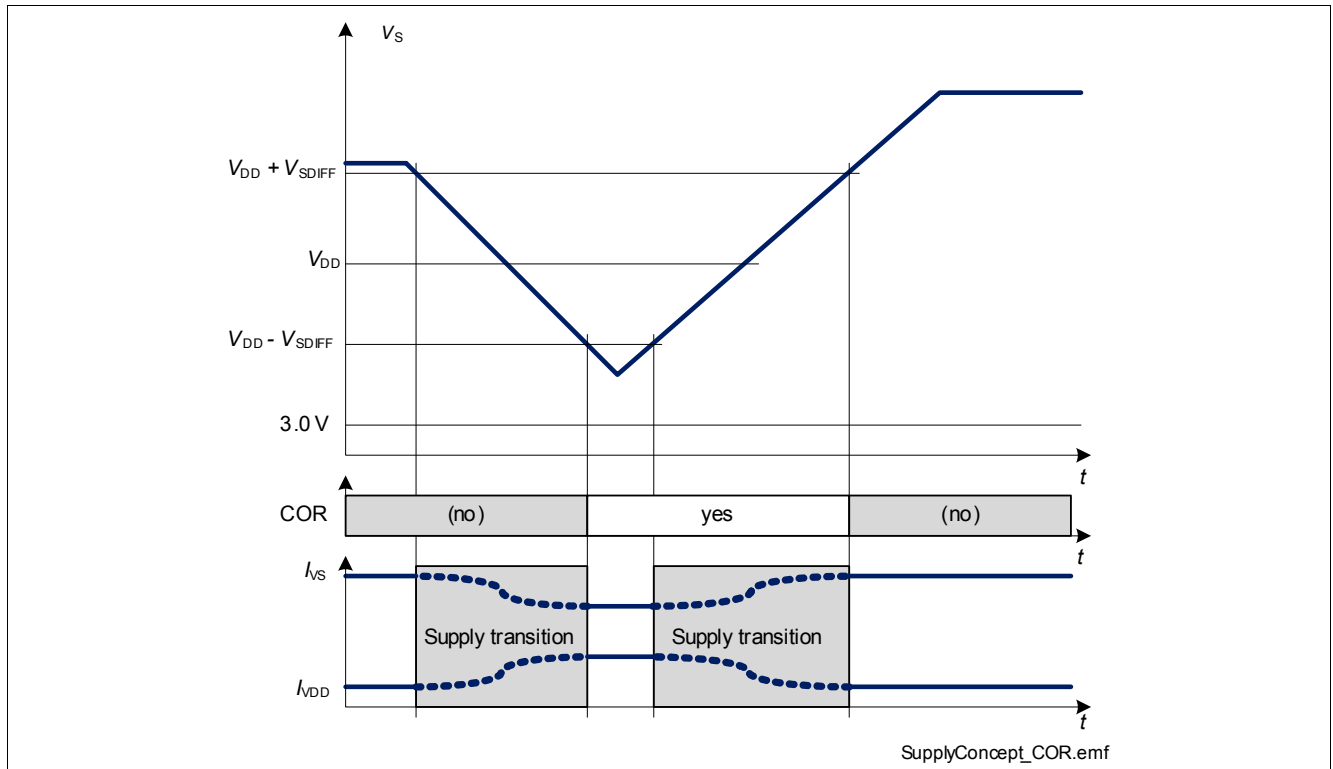
- An undervoltage on both  $V_S$  and  $V_{DD}$  supply voltages prevents the activation of the power stages and any SPI communication (the SPI registers are reset)
- An undervoltage on  $V_{DD}$  supply prevents any SPI communication. SPI read/write registers are reset to default values.
- An undervoltage on  $V_S$  supply forces the TLE75242-EMH to drain all needed current for the logic from  $V_{DD}$  supply. All channels are disabled, and are enabled again as soon as  $V_S \geq V_{S(OP)}$ .

**Figure 10** shows a basic concept drawing of the interaction between supply pins VS and VDD, the output stage drivers and SO supply line.



**Figure 10 TLE75242-EMH Internal Power Supply concept**

When  $3.0\text{ V} \leq V_S \leq V_{DD} - V_{SDIFF}$  TLE75242-EMH operates in “Cranking Operative Range” (COR). In this condition the current consumption from VDD pin increases while it decreases from VS pin where the total current consumption remains within the specified limits. **Figure 11** shows the voltage levels at VS pin where the device goes in and out of COR. During the transition to and from COR operative region,  $I_{VS}$  and  $I_{VDD}$  change between values defined for normal operation and for COR operation. The sum of both current remains within limits specified in “Overall current consumption” section (see **Table 8**).



**Figure 11 “Cranking Operative Range”**

Furthermore, when  $V_{S(UV)} \leq V_S \leq V_{S(OP)}$  it may be not possible to switch ON a channel that was previously OFF. All channels that are already ON keep their state unless they are switched OFF via SPI or via INn pins. An overview of channel behavior according to different  $V_S$  and  $V_{DD}$  supply voltages is shown in [Table 6](#) (the table is valid after a successful power-up, see [Chapter 6.1.1](#) for more details).

**Table 6** Device capability as function of  $V_S$  and  $V_{DD}$ 

	$V_{DD} \leq V_{DD(UV)}$ ( $V_{DD(UV)} = P\_6.3.25$ )	$V_{DD} = V_{DD(LOP)}$ ( $V_{DD(LOP)} = P\_6.3.24$ )	$V_{DD} > V_{DD(LOP)}$
$V_S \leq 3.0 \text{ V}$	channels cannot be controlled	channels cannot be controlled	channels cannot be controlled
$3.0 \text{ V} = V_{S(UV),max}$ ( $P\_6.3.1$ )	SPI registers reset	SPI registers available	SPI registers available
	SPI communication not available ( $f_{SCLK} = 0 \text{ MHz}$ )	SPI communication possible ( $f_{SCLK} = 1 \text{ MHz}$ ) (P_10.4.34)	SPI communication possible ( $f_{SCLK} = 5 \text{ MHz}$ ) (P_10.4.22)
	Limp Home mode not available	Limp Home mode available (channels are OFF)	Limp Home mode available (channels are OFF)
$3.0 \text{ V} < V_S \leq V_{S(OP)}$ ( $V_{S(OP)} = P\_6.3.2$ )	channels cannot be controlled by SPI	channels can be switched ON and OFF (SPI control) <sup>1)</sup> ( $R_{DS(ON)}$ deviations possible)	channels can be switched ON and OFF (SPI control) <sup>1)</sup> ( $R_{DS(ON)}$ deviations possible)
	SPI registers reset	SPI registers available	SPI registers available
	SPI communication not available ( $f_{SCLK} = 0 \text{ MHz}$ )	SPI communication possible ( $f_{SCLK} = 1 \text{ MHz}$ ) (P_10.4.34)	SPI communication possible ( $f_{SCLK} = 5 \text{ MHz}$ ) (P_10.4.22)
	Limp Home mode available <sup>1)</sup> ( $R_{DS(ON)}$ deviations possible)	Limp Home mode available <sup>1)</sup> ( $R_{DS(ON)}$ deviations possible)	Limp Home mode available <sup>1)</sup> ( $R_{DS(ON)}$ deviations possible)
$V_S \geq V_{S(OP)}$	channels cannot be controlled by SPI	channels can be switched ON and OFF (small $R_{DS(ON)}$ dev. possible when $V_S = V_{S(EXT,LOW)}$ )	channels can be switched ON and OFF (small $R_{DS(ON)}$ dev. possible when $V_S = V_{S(EXT,LOW)}$ )
	SPI registers reset	SPI registers available	SPI registers available
	SPI communication not available ( $f_{SCLK} = 0 \text{ MHz}$ )	SPI communication possible ( $f_{SCLK} = 5 \text{ MHz}$ ) (P_10.4.22)	SPI communication possible ( $f_{SCLK} = 5 \text{ MHz}$ ) (P_10.4.22)
	Limp Home mode available (small $R_{DS(ON)}$ dev. possible when $V_S = V_{S(EXT,LOW)}$ )	Limp Home mode available (small $R_{DS(ON)}$ dev. possible when $V_S = V_{S(EXT,LOW)}$ )	Limp Home mode available (small $R_{DS(ON)}$ dev. possible when $V_S = V_{S(EXT,LOW)}$ )

1) undervoltage condition on  $V_S$  must be considered - see [Chapter 6.2.1](#) for more details

## 6.1 Operation Modes

TLE75242-EMH has the following operation modes:

- Sleep mode
- Idle mode
- Active mode
- Limp Home mode

The transition between operation modes is determined according to following levels and states:

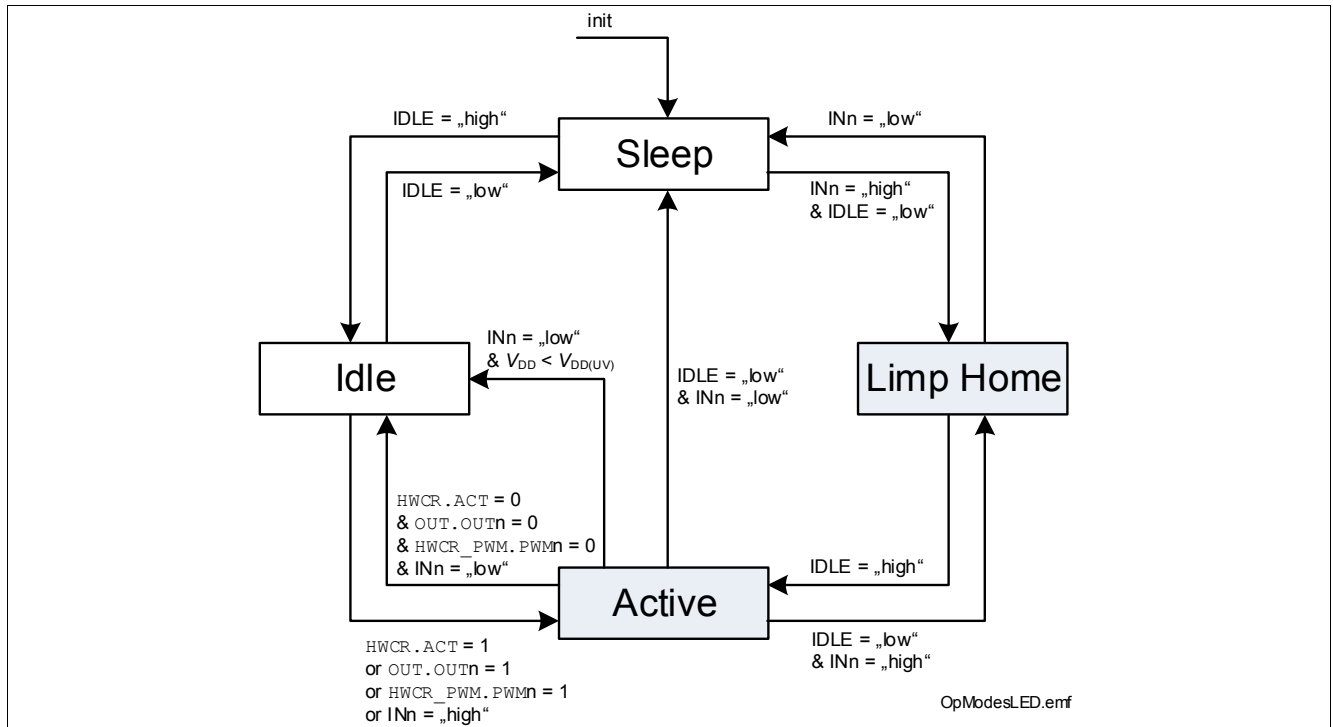
- logic level at IDLE pin
- logic level at INn pins
- `OUT.OUTn` bits state
- `HWCR.ACT` bit state
- `HWCR_PWM.PWM0` and `HWCR_PWM.PWM1` bits state

The state diagram including the possible transitions is shown in [Figure 12](#). The behaviour of TLE75242-EMH as well as some parameters may change in dependence from the operation mode of the device. Furthermore, due to the undervoltage detection circuitry which monitors  $V_S$  and  $V_{DD}$  supply voltages, some changes within the same operation mode can be seen accordingly.

The operation mode of the TLE75242-EMH can be observed by:

- status of output channels
- status of SPI registers
- current consumption at VDD pin ( $I_{VDD}$ )
- current consumption at VS pin ( $I_{VS}$ )

The default operation mode to switch ON the loads is Active mode. If the device is not in Active mode and a request to switch ON one or more outputs comes (via SPI or via Input pins), it will switch into Active or Limp Home mode, according to IDLE pin status. Due to the time needed for such transitions, output turn-on time  $t_{ON}$  will be extended due to the mode transition latency.



**Figure 12** Operation Mode state diagram

**Table 7** shows the correlation between device operation modes,  $V_S$  and  $V_{DD}$  supply voltages, and state of the most important functions (channels operativity, SPI communication and SPI registers).

**Table 7** Device function in relation to operation modes,  $V_S$  and  $V_{DD}$  voltages

Operation Mode	Function	Undervoltage condition on $V_S$ <sup>1)</sup> $V_{DD} \leq V_{DD(UV)}$	Undervoltage condition on $V_S$ $V_{DD} > V_{DD(UV)}$	$V_S$ not in undervoltage $V_{DD} \leq V_{DD(UV)}$	$V_S$ not in undervoltage $V_{DD} > V_{DD(UV)}$
Sleep	Channels	not available	not available	not available	not available
	SPI comm.	not available	not available	not available	not available
	SPI registers	reset	reset	reset	reset
Idle	Channels	not available	not available	not available	not available
	SPI comm.	not available	✓	not available	✓
	SPI registers	reset	✓	reset	✓
Active	Channels	not available	not available	✓ (IN pins only)	✓
	SPI comm.	not available	✓	not available	✓
	SPI registers	reset	✓	reset	✓
Limp Home	Channels	not available	not available	✓ (IN pins only)	✓ (IN pins only)
	SPI comm.	not available	✓ (read-only)	not available	✓ (read-only)
	SPI registers	reset	✓ (read-only) <sup>2)</sup>	reset	✓ (read-only) <sup>2)</sup>

1) see [Chapter 6.2.1](#) for more details

2) see [Chapter 6.1.5](#) for a detailed overview

### 6.1.1 Power-up

The Power-up condition is satisfied when one of the supply voltages ( $V_S$  or  $V_{DD}$ ) is applied to the device and the INn or IDLE pins are set to “high”. If  $V_S$  is above the threshold  $V_{S(OP)}$  or if  $V_{DD}$  is above the threshold  $V_{DD(LOP)}$  the internal power-on signal is set.

### 6.1.2 Sleep mode

When TLE75242-EMH is in Sleep mode, all outputs are OFF and the SPI registers are reset, independently from the supply voltages. The current consumption is minimum. See parameters  $I_{VDD(SLEEP)}$  and  $I_{VS(SLEEP)}$ , or parameter  $I_{SLEEP}$  for the whole device.

### 6.1.3 Idle mode

In Idle mode, the current consumption of the device can reach the limits given by parameters  $I_{VDD(IDLE)}$  and  $I_{VS(IDLE)}$ , or by parameter  $I_{IDLE}$  for the whole device. The internal voltage regulator is working. Diagnosis functions are not available. The output channels are switched OFF, independently from the supply voltages. When  $V_{DD}$  is available, the SPI registers are working and SPI communication is possible. In Idle mode the **ERRn** bits are not cleared for functional safety reasons.

### 6.1.4 Active mode

Active mode is the normal operation mode of TLE75242-EMH when no Limp Home condition is set and it is necessary to drive some or all loads. Voltage levels of  $V_{DD}$  and  $V_S$  influence the behavior as described at the beginning of [Chapter 6](#). Device current consumption is specified with  $I_{VDD(ACTIVE)}$  and  $I_{VS(ACTIVE)}$  ( $I_{ACTIVE}$  for the whole device). The device enters Active mode when IDLE pin is set to “high” and one of the input pins is set to “high” or one **OUT.OUTn** bit is set to “1”. If **HWCR.ACT** is set to “0”, the device returns to Idle mode as soon as all inputs pins are set to “low” and **OUT.OUTn** bits are set to “0”. If **HWCR.ACT** is set to “1”, the device remains in Active mode independently of the status of input pins and **OUT.OUTn** bits. An undervoltage condition on  $V_{DD}$  supply brings the device into Idle mode, if all input pins are set to “low”. Even if the registers **MAPIN0** and **MAPIN1** are both set to “00<sub>H</sub>” but one of the input pins INn is set to “high”, the device goes into Active mode.

### 6.1.5 Limp Home mode

TLE75242-EMH enters Limp Home mode when IDLE pin is “low” and one of the input pins is set to “high”, switching ON the channel connected to it. SPI communication is possible but only in read-only mode (SPI registers can be read but cannot be written). More in detail:

- **UVRVS** and **LOPVDD** are set to “1”
- **MODE** bits are set to “01<sub>B</sub>” (Limp Home mode)
- **TER** bit is set to “1” on the first SPI command after entering Limp Home mode. Afterwards it works normally
- **OLON** and **OLOFF** bits is set to “0”
- **ERRn** bits work normally
- **DIAG\_OSM.OUTn** bits can be read and work normally
- All other registers are set to their default value and cannot be programmed as long as the device is in Limp Home mode

See [Table 6](#) for a detailed overview of supply voltage conditions required to switch ON channels 2 and 3 during Limp Home. All other channels are OFF.

A transmission of SPI commands during transition from Active to Limp Home mode or Limp Home to Active mode may result in undefined SPI responses.

### 6.1.6 Definition of Power Supply modes transition times

The channel turn-ON time is as defined by parameter  $t_{ON}$  when TLE75242-EMH is in Active mode or in Limp Home mode. In all other cases, it is necessary to add the transition time required to reach one of the two aforementioned Power Supply modes (as shown in Figure 13).

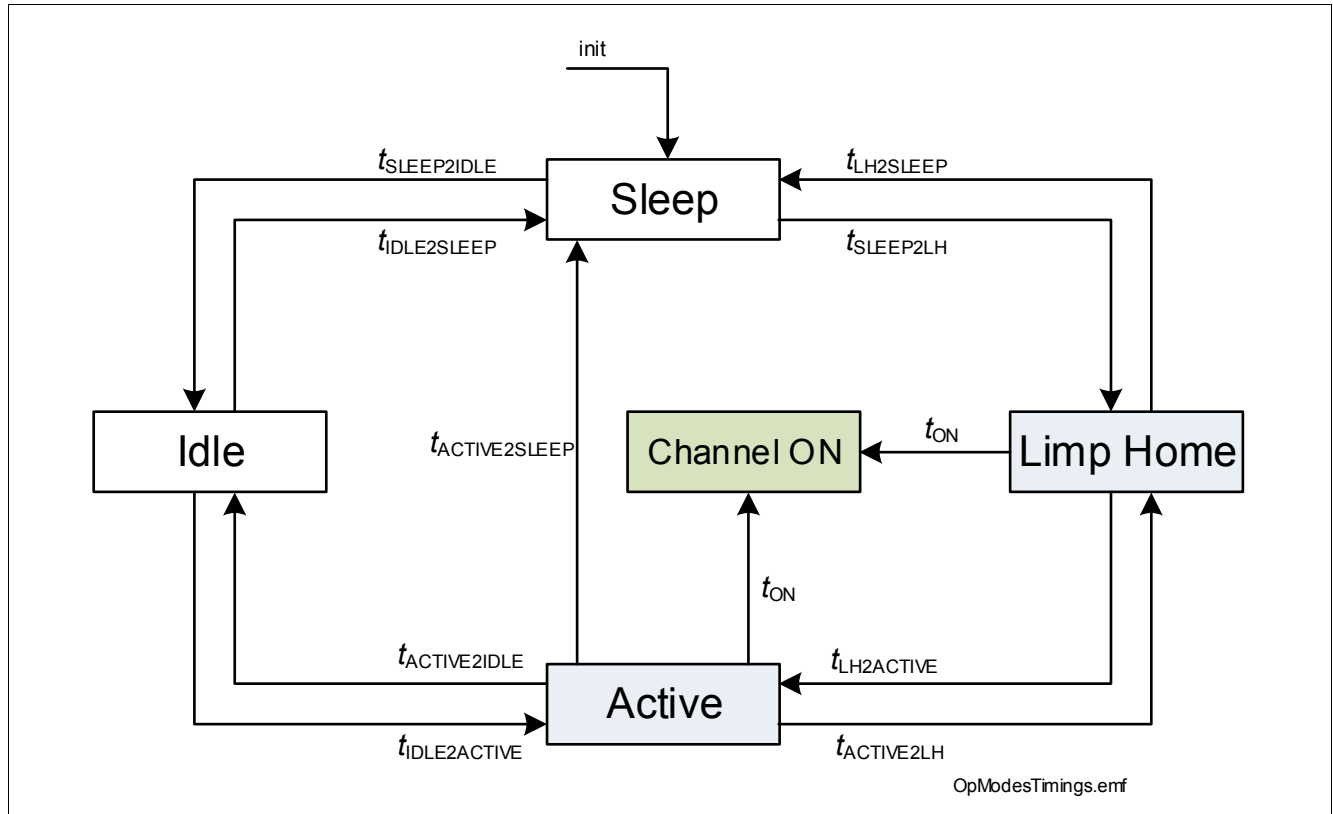


Figure 13 Transition Time diagram

## 6.2 Reset condition

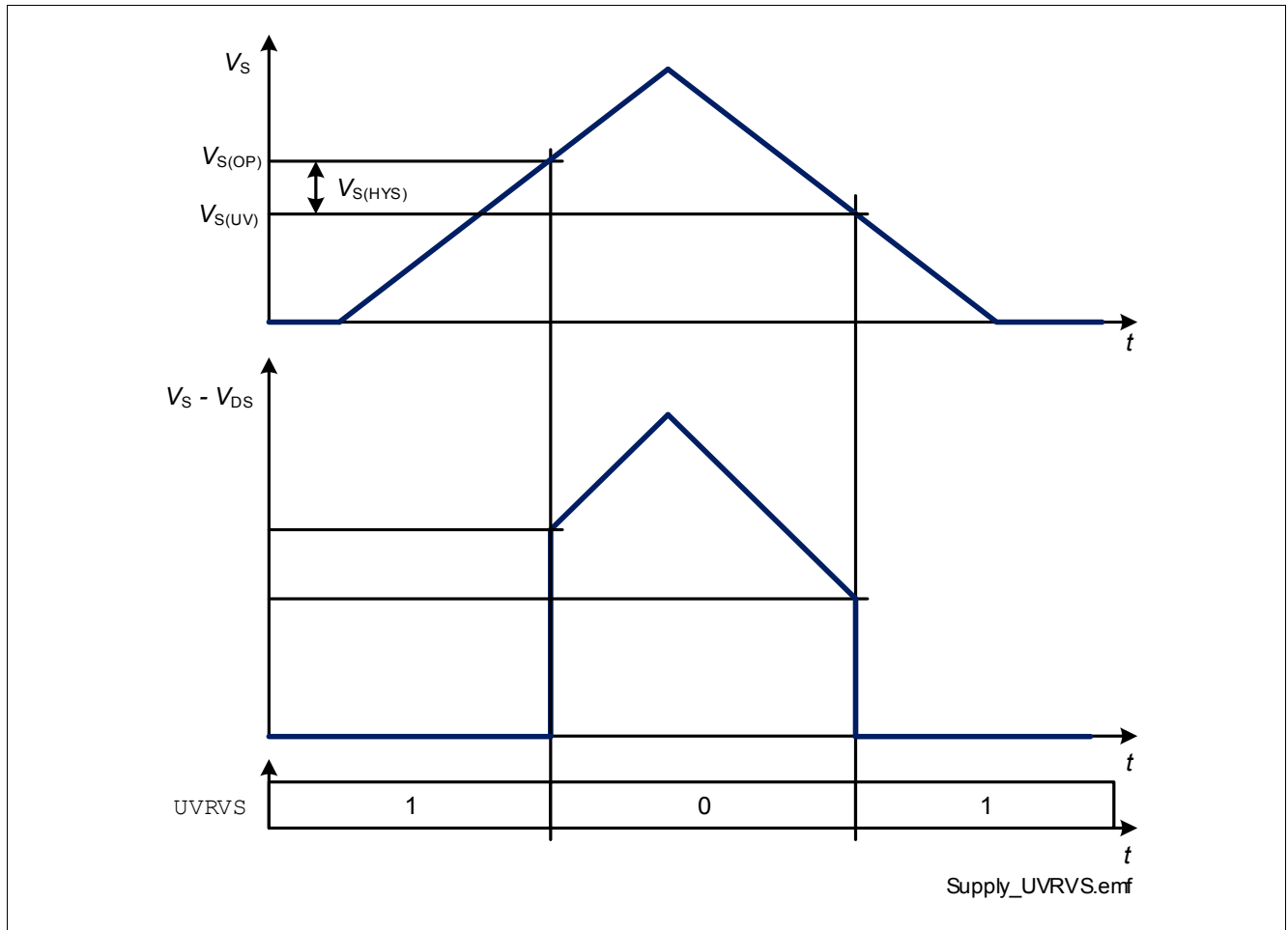
One of the following 3 conditions resets the SPI registers to the default value:

- $V_{DD}$  is not present or below the undervoltage threshold  $V_{DD(UV)}$
- IDLE pin is set to "low"
- a reset command (**HWCR.RST** set to "1") is executed
  - ERRn** bits are not cleared by a reset command (for functional safety)
  - UVRVS** and **LOPVDD** bits are cleared by a reset command

In particular, all channels are switched OFF (if there are no input pin set to "high") and the Input Mapping configuration is reset.

### 6.2.1 Undervoltage on $V_S$

Between  $V_{S(UV)}$  and  $V_{S(OP)}$  the undervoltage mechanism is triggered. If the device is operative and the supply voltage drops below the undervoltage threshold  $V_{S(UV)}$ , the logic set the bit **UVRVS** to "1". As soon as the supply voltage  $V_S$  is above the minimum voltage operative threshold  $V_{S(OP)}$ , the bit **UVRVS** is set to "0" after the first Standard Diagnosis readout. Undervoltage condition on  $V_S$  influences the status of the channels, as described in Table 6. Figure 14 sketches the undervoltage behavior (the " $V_S - V_{DS}$ " line refers to a channel which is programmed to be ON).



**Figure 14**  $V_S$  Undervoltage Behavior

### 6.2.2 Low Operating Power on $V_{DD}$

When  $V_{DD}$  supply voltage is in the range indicated by  $V_{DD(LOP)}$ , the bit **LOPVDD** is set to “1”. As soon as  $V_{DD} > V_{DD(LOP)}$  the bit **LOPVDD** is set to “0” after the first Standard Diagnosis readout.

If  $V_{DD}$  supply voltage is not present, a voltage applied to pins CSN or SO can supply the internal logic (not recommended in normal operation due to internal design limitations).

### 6.3 Electrical Characteristics Power Supply

**Table 8 Electrical Characteristics Power Supply**

$V_{DD} = 3 \text{ V to } 5.5 \text{ V}$ ,  $V_S = 7 \text{ V to } 18 \text{ V}$ ,  $T_J = -40 \text{ }^\circ\text{C to } +150 \text{ }^\circ\text{C}$ , all voltages with respect to ground, positive currents flowing as described in [Figure 2](#) (unless otherwise specified)

Typical values:  $V_{DD} = 5 \text{ V}$ ,  $V_S = 13.5 \text{ V}$ ,  $T_J = 25 \text{ }^\circ\text{C}$

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
VS pin							
Analog supply undervoltage shutdown	$V_{S(UV)}$	1.5	–	3.0	V	OUTn = ON from $V_{DS} \leq 1\text{ V}$ to $\text{UVRVS} = 1_B$ $R_L = 50\ \Omega$	P_6.3.1
Analog supply minimum operative voltage	$V_{S(OP)}$	–	–	4.0	V	$\text{OUT} . \text{OUTn} = 1_B$ from $\text{UVRVS} = 1_B$ to $V_{DS} \leq 1\text{ V}$ $R_L = 50\ \Omega$	P_6.3.2
Undervoltage shutdown hysteresis	$V_{S(HYS)}$	–	1	–	V	<sup>1)</sup>	P_6.3.3
Analog supply current consumption in Sleep mode with loads	$I_{VS(SLEEP)}$	–	0.1	3	$\mu\text{A}$	<sup>1)</sup> $V_{IDLE}$ floating $V_{INn}$ floating $V_{CSN} = V_{DD}$ $T_J \leq 85\text{ }^\circ\text{C}$	P_6.3.4
Analog supply current consumption in Sleep mode with loads	$I_{VS(SLEEP)}$	–	0.1	–	$\mu\text{A}$	<sup>1)</sup> $V_{IDLE}$ floating $V_{INn}$ floating $V_{CSN} = V_{DD}$ $T_J \leq 85\text{ }^\circ\text{C}$ $VS = 13.5\text{ V}$	P_6.3.63
Analog supply current consumption in Sleep mode with loads	$I_{VS(SLEEP)}$	–	0.1	20	$\mu\text{A}$	$V_{IDLE}$ floating $V_{INn}$ floating $V_{CSN} = V_{DD}$ $T_J = 150\text{ }^\circ\text{C}$	P_6.3.5
Analog supply current consumption in Idle mode with loads	$I_{VS(IDLE)}$	–	–	2.2	mA	IDLE = “high” $V_{INn}$ floating $f_{SCLK} = 0\text{ MHz}$ $\text{HWCR} . \text{ACT} = 0_B$ $\text{OUT} . \text{OUTn} = 0_B$ $\text{DIAG\_IOL} . \text{OUTn} = 0_B$ $V_{CSN} = V_{DD}$	P_6.3.6

**Table 8 Electrical Characteristics Power Supply (cont'd)**

$V_{DD} = 3 \text{ V to } 5.5 \text{ V}$ ,  $V_S = 7 \text{ V to } 18 \text{ V}$ ,  $T_J = -40 \text{ }^\circ\text{C to } +150 \text{ }^\circ\text{C}$ , all voltages with respect to ground, positive currents flowing as described in [Figure 2](#) (unless otherwise specified)

Typical values:  $V_{DD} = 5 \text{ V}$ ,  $V_S = 13.5 \text{ V}$ ,  $T_J = 25 \text{ }^\circ\text{C}$

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Analog supply current consumption in Idle mode with loads (COR)	$I_{VS(IDLE)}$	–	–	0.3	mA	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0 \text{ MHz}$ $HWCR.ACT = 0_B$ $OUT.OUTn = 0_B$ $DIAG_IOL.OUTn = 0_B$ $V_{CSN} = V_{DD}$ $V_S \leq V_{DD} - 1 \text{ V}$	P_6.3.7
Analog supply current consumption in Active mode with loads - channels OFF	$I_{VS(ACTIVE)}$	–	–	7.7	mA	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0 \text{ MHz}$ $HWCR.ACT = 1_B$ $OUT.OUTn = 0_B$ $DIAG_IOL.OUTn = 0_B$ $V_{CSN} = V_{DD}$	P_6.3.10
Analog supply current consumption in Active mode with loads - channels OFF (COR)	$I_{VS(ACTIVE)}$	–	–	5.0	mA	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0 \text{ MHz}$ $HWCR.ACT = 1_B$ $OUT.OUTn = 0_B$ $DIAG_IOL.OUTn = 0_B$ $V_{CSN} = V_{DD}$ $V_S \leq V_{DD} - 1 \text{ V}$	P_6.3.14
Analog supply current consumption in Active mode with loads - channels ON	$I_{VS(ACTIVE)}$	–	–	8.7	mA	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0 \text{ MHz}$ $HWCR.ACT = 1_B$ $OUT.OUTn = 1_B$ $DIAG_IOL.OUTn = 0_B$ $DIAG_OLONEN.MUX = 0100_B$ $V_{CSN} = V_{DD}$	P_6.3.18

**Table 8 Electrical Characteristics Power Supply (cont'd)**

$V_{DD} = 3 \text{ V to } 5.5 \text{ V}$ ,  $V_S = 7 \text{ V to } 18 \text{ V}$ ,  $T_J = -40 \text{ }^\circ\text{C to } +150 \text{ }^\circ\text{C}$ , all voltages with respect to ground, positive currents flowing as described in [Figure 2](#) (unless otherwise specified)

Typical values:  $V_{DD} = 5 \text{ V}$ ,  $V_S = 13.5 \text{ V}$ ,  $T_J = 25 \text{ }^\circ\text{C}$

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Analog supply current consumption in Active mode with loads - channels ON (COR)	$I_{VS(ACTIVE)}$	–	2.3	5.0	mA	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0 \text{ MHz}$ <a href="#">HWCR.ACT</a> = 1 <sub>B</sub> <a href="#">OUT.OUTn</a> = 1 <sub>B</sub> <a href="#">DIAG_IOL.OUTn</a> = 0 <sub>B</sub> $V_{CSN} = V_{DD}$ $V_S \leq V_{DD} - 1 \text{ V}$	<a href="#">P_6.3.22</a>
<b>VDD pin</b>							
Logic Supply Operating voltage	$V_{DD(OP)}$	3.0	–	5.5	V	$f_{SCLK} = 5 \text{ MHz}$	<a href="#">P_6.3.23</a>
Logic Supply Lower Operating Voltage	$V_{DD(LOP)}$	3.0	–	4.5	V	–	<a href="#">P_6.3.24</a>
Undervoltage shutdown	$V_{DD(UV)}$	1	–	3.0	V	$V_{SI} = 0 \text{ V}$ $V_{SCLK} = 0 \text{ V}$ $V_{CSN} = 0 \text{ V}$ SO from "low" to high impedance	<a href="#">P_6.3.25</a>
Logic supply current in Sleep mode	$I_{VDD(SLEEP)}$	–	0.1	2.5	μA	<sup>1)</sup> $V_{IDLE}$ floating $V_{INn}$ floating $V_{CSN} = V_{DD}$ $T_J \leq 85 \text{ }^\circ\text{C}$	<a href="#">P_6.3.26</a>
Logic supply current in Sleep mode	$I_{VDD(SLEEP)}$	–	–	10	μA	$V_{IDLE}$ floating $V_{INn}$ floating $V_{CSN} = V_{DD}$ $T_J = 150 \text{ }^\circ\text{C}$	<a href="#">P_6.3.27</a>
Logic supply current in Idle mode	$I_{VDD(IDLE)}$	–	–	0.3	mA	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0 \text{ MHz}$ <a href="#">HWCR.ACT</a> = 0 <sub>B</sub> <a href="#">OUT.OUTn</a> = 0 <sub>B</sub> $V_{CSN} = V_{DD}$	<a href="#">P_6.3.28</a>
Logic supply current in Idle mode (COR)	$I_{VDD(IDLE)}$	–	–	2.2	mA	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0 \text{ MHz}$ <a href="#">HWCR.ACT</a> = 0 <sub>B</sub> <a href="#">OUT.OUTn</a> = 0 <sub>B</sub> $V_{CSN} = V_{DD}$ $V_S \leq V_{DD} - 1 \text{ V}$	<a href="#">P_6.3.29</a>

**Table 8 Electrical Characteristics Power Supply (cont'd)**

$V_{DD} = 3\text{ V to } 5.5\text{ V}$ ,  $V_S = 7\text{ V to } 18\text{ V}$ ,  $T_J = -40\text{ °C to } +150\text{ °C}$ , all voltages with respect to ground, positive currents flowing as described in [Figure 2](#) (unless otherwise specified)

Typical values:  $V_{DD} = 5\text{ V}$ ,  $V_S = 13.5\text{ V}$ ,  $T_J = 25\text{ °C}$

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Logic supply current in Active mode - channels OFF	$I_{VDD(ACTIVE)}$	–	–	0.3	mA	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0\text{ MHz}$ <b>HWCR.ACT</b> = 1 <sub>B</sub> <b>OUT.OUTn</b> = 0 <sub>B</sub> $V_{CSN} = V_{DD}$	P_6.3.30
Logic supply current in Active mode - channels OFF (COR)	$I_{VDD(ACTIVE)}$	–	–	2.7	mA	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0\text{ MHz}$ <b>HWCR.ACT</b> = 1 <sub>B</sub> <b>OUT.OUTn</b> = 0 <sub>B</sub> $V_{CSN} = V_{DD}$ $V_S \leq V_{DD} - 1\text{ V}$	P_6.3.33
Logic supply current in Active mode - channels ON	$I_{VDD(ACTIVE)}$	–	–	0.3	mA	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0\text{ MHz}$ <b>HWCR.ACT</b> = 1 <sub>B</sub> <b>OUT.OUTn</b> = 1 $V_{CSN} = V_{DD}$	P_6.3.35
Logic supply current in Active mode - channels ON (COR)	$I_{VDD(ACTIVE)}$	–	–	3.5	mA	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0\text{ MHz}$ <b>HWCR.ACT</b> = 1 <sub>B</sub> <b>OUT.OUTn</b> = 1 <sub>B</sub> <b>DIAG_IOL.OUTn</b> = 0 <sub>B</sub> <b>DIAG_OLONEN.MUX</b> = 0100 <sub>B</sub> $V_{CSN} = V_{DD}$ $V_S \leq V_{DD} - 1\text{ V}$	P_6.3.66

**Overall current consumption**

Overall current consumption in Sleep mode $I_{VS(SLEEP)} + I_{VDD(SLEEP)}$	$I_{SLEEP}$	–	–	5	μA	<sup>1)</sup> $V_{IDLE}$ floating $V_{INn}$ floating $V_{CSN} = V_{DD}$ $T_J \leq 85\text{ °C}$	P_6.3.40
Overall current consumption in Sleep mode $I_{VS(SLEEP)} + I_{VDD(SLEEP)}$	$I_{SLEEP}$	–	–	5	μA	<sup>1)</sup> $V_{IDLE}$ floating $V_{INn}$ floating $V_{CSN} = V_{DD}$ $T_J \leq 85\text{ °C}$ $V_S = 13.5\text{ V}$	P_6.3.64

**Table 8 Electrical Characteristics Power Supply (cont'd)**

$V_{DD} = 3 \text{ V to } 5.5 \text{ V}$ ,  $V_S = 7 \text{ V to } 18 \text{ V}$ ,  $T_J = -40 \text{ }^\circ\text{C to } +150 \text{ }^\circ\text{C}$ , all voltages with respect to ground, positive currents flowing as described in [Figure 2](#) (unless otherwise specified)

Typical values:  $V_{DD} = 5 \text{ V}$ ,  $V_S = 13.5 \text{ V}$ ,  $T_J = 25 \text{ }^\circ\text{C}$

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Overall current consumption in Sleep mode $I_{VS(SLEEP)} + I_{VDD(SLEEP)}$	$I_{SLEEP}$	–	–	30	$\mu\text{A}$	$V_{IDLE}$ floating $V_{INn}$ floating $V_{CSN} = V_{DD}$ $T_J = 150 \text{ }^\circ\text{C}$	P_6.3.41
Overall current consumption in Idle mode $I_{VS(IDLE)} + I_{VDD(IDLE)}$	$I_{IDLE}$	–	–	2.5	$\text{mA}$	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0 \text{ MHz}$ $HWCR.ACT = 0_B$ $OUT.OUTn = 0_B$ $DIAG_IOL.OUTn = 0_B$ $V_{CSN} = V_{DD}$	P_6.3.42
Overall current consumption in Active mode - channels OFF $I_{VS(ACTIVE)} + I_{VDD(ACTIVE)}$	$I_{ACTIVE}$	–	–	8	$\text{mA}$	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0 \text{ MHz}$ $HWCR.ACT = 1_B$ $OUT.OUTn = 0_B$ $DIAG_IOL.OUTn = 0_B$ $V_{CSN} = V_{DD}$	P_6.3.45
Overall current consumption in Active mode - channels ON $I_{VS(ACTIVE)} + I_{VDD(ACTIVE)}$	$I_{ACTIVE}$	–	–	9	$\text{mA}$	IDLE = "high" $V_{INn}$ floating $f_{SCLK} = 0 \text{ MHz}$ $HWCR.ACT = 1_B$ $OUT.OUTn = 1_B$ $DIAG_IOL.OUTn = 0_B$ $V_{CSN} = V_{DD}$	P_6.3.62
Voltage difference between $V_S$ and $V_{DD}$ supply lines	$V_{SDIFF}$	–	200	–	$\text{mV}$	<sup>1)</sup>	P_6.3.52

**Timings**

Sleep to Idle delay	$t_{SLEEP2IDLE}$	–	200	400	$\mu\text{s}$	<sup>1)</sup> from IDLE pin to <b>TER + INST</b> register = 8680 <sub>H</sub> (see <a href="#">Chapter 10.6.1</a> for details)	P_6.3.53
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**Table 8 Electrical Characteristics Power Supply (cont'd)**

$V_{DD} = 3\text{ V to } 5.5\text{ V}$ ,  $V_S = 7\text{ V to } 18\text{ V}$ ,  $T_J = -40\text{ °C to } +150\text{ °C}$ , all voltages with respect to ground, positive currents flowing as described in [Figure 2](#) (unless otherwise specified)

Typical values:  $V_{DD} = 5\text{ V}$ ,  $V_S = 13.5\text{ V}$ ,  $T_J = 25\text{ °C}$

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Idle to Sleep delay	$t_{IDLE2SLEEP}$	—	100	200	$\mu\text{s}$	<sup>1)</sup> from IDLE pin to Standard Diagnosis = 0000 <sub>H</sub> (see <a href="#">Chapter 10.5</a> for details) external pull-down SO to GND required	P_6.3.54
Idle to Active delay	$t_{IDLE2ACTIVE}$	—	100	200	$\mu\text{s}$	<sup>1)</sup> from INn or CSN pins to <a href="#">MODE</a> = 10 <sub>B</sub>	P_6.3.55
Active to Idle delay	$t_{ACTIVE2IDLE}$	—	100	200	$\mu\text{s}$	<sup>1)</sup> from INn or CSN pins to <a href="#">MODE</a> = 11 <sub>B</sub>	P_6.3.56
Sleep to Limp Home delay	$t_{SLEEP2LH}$	—	300 + $t_{ON}$	600 + $t_{ON}$	$\mu\text{s}$	<sup>1)</sup> from INn pins to $V_{DS} = 10\% V_S$	P_6.3.57
Limp Home to Sleep delay	$t_{LH2SLEEP}$	—	200 + $t_{OFF}$	400 + $t_{OFF}$	$\mu\text{s}$	<sup>1)</sup> from INn pins to Standard Diagnosis = 0000 <sub>H</sub> (see <a href="#">Chapter 10.6.1</a> for details). External pull-down SO to GND required	P_6.3.58
Limp Home to Active delay	$t_{LH2ACTIVE}$	—	50	100	$\mu\text{s}$	<sup>1)</sup> from IDLE pin to <a href="#">MODE</a> = 10 <sub>B</sub>	P_6.3.59

**Table 8 Electrical Characteristics Power Supply (cont'd)**

$V_{DD} = 3\text{ V to }5.5\text{ V}$ ,  $V_S = 7\text{ V to }18\text{ V}$ ,  $T_J = -40\text{ °C to }+150\text{ °C}$ , all voltages with respect to ground, positive currents flowing as described in [Figure 2](#) (unless otherwise specified)

Typical values:  $V_{DD} = 5\text{ V}$ ,  $V_S = 13.5\text{ V}$ ,  $T_J = 25\text{ °C}$

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Active to Limp Home delay	$t_{\text{ACTIVE2LH}}$	—	50	100	μs	1) from IDLE pin to <a href="#">TER</a> + <a href="#">INST</a> register = 8683 <sub>H</sub> (IN0 = IN1 = “high”) or 8682 <sub>H</sub> (IN1 = “high”, IN0 = “low”) or 8681 <sub>H</sub> (IN1 = “low”, IN0 = “high”) (see <a href="#">Chapter 10.5</a> for details)	<a href="#">P_6.3.60</a>
Active to Sleep delay	$t_{\text{ACTIVE2SLEEP}}$	—	50	100	μs	1) from IDLE pin to Standard Diagnosis = 0000 <sub>H</sub> (see <a href="#">Chapter 10.6.1</a> for details). External pull-down SO to GND required.	<a href="#">P_6.3.61</a>

1) Not subject to production test - specified by design

## 7 Power Stages

The TLE75242-EMH is an eight channels low-side and high-side relay switch. The power stages are built by N-channel lateral power MOSFET transistors.

There are two auto-configurable channels which can be used either as low-side or as high-side switches. They adjust the diagnostic and protective functions according their potential at drain and source automatically. For these channels a charge pump is connected to the output MOSFET gate.

In high-side configuration, the load is connected between ground and source of the power transistor (pins OUTn\_S, n = 2, 3). The drains of the power transistors (OUTn\_D, with “n” equal to the configurable channel number) can be connected to any potential between ground and  $V_S$ . When the drain is connected to  $V_S$ , the channel behave like an high-side switch.

In low-side configuration, the source of the power transistors must be connected to GND pin potential (either directly or through a reverse current blocking diode).

The configuration can be chosen for each of these channels individually, therefore it is feasible to connect one or more channels in low-side configuration, while the remaining auto-configurable are used as high-side switches.

The supply voltage  $V_{S\_HS}$  can be connected to any potential between ground and  $V_S$ . A charge pump is connected to the output MOSFET gate.

### 7.1 Output ON-state resistance

The ON-state resistance  $R_{DS(ON)}$  depends on the supply voltage as well as the junction temperature  $T_J$ .

#### 7.1.1 Switching Resistive Loads

When switching resistive loads the following switching times and slew rates can be considered.

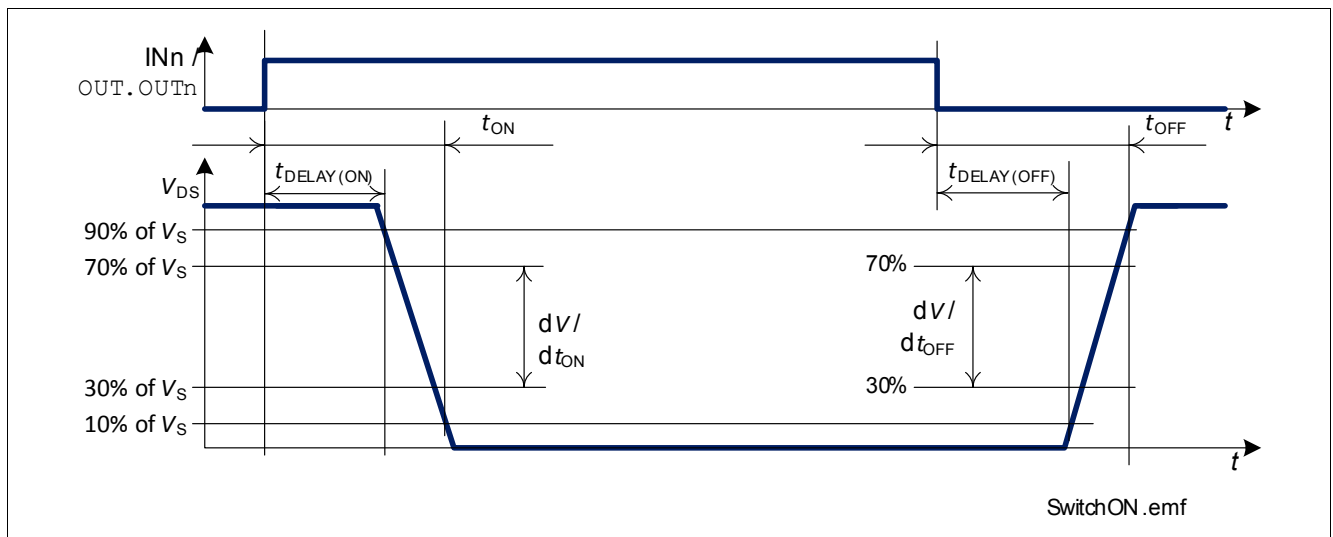


Figure 15 Switching a Resistive Load

#### 7.1.2 Inductive Output Clamp

When switching off inductive loads, the voltage across the power switch rises to  $V_{DS(CL)}$  potential, because the inductance intends to continue driving the current. The potential at Output pin is not allowed to go below  $V_{OUT\_S(CL)}$  or  $V_{OUT(CL)}$ . The voltage clamping is necessary to prevent device destruction.

Figure 16, Figure 17, Figure 18 show a concept drawing of the implementation. Nevertheless, the maximum allowed load inductance is limited. The clamping structure protects the device in all operative modes (Sleep, Idle, Active, Limp Home).

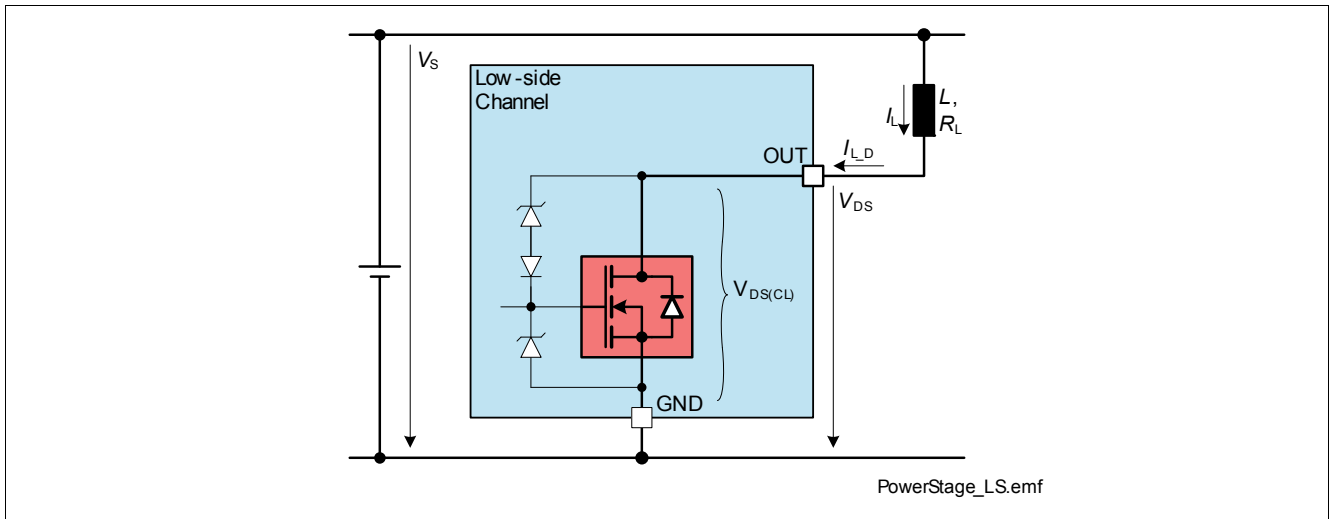


Figure 16 Output Clamp concept

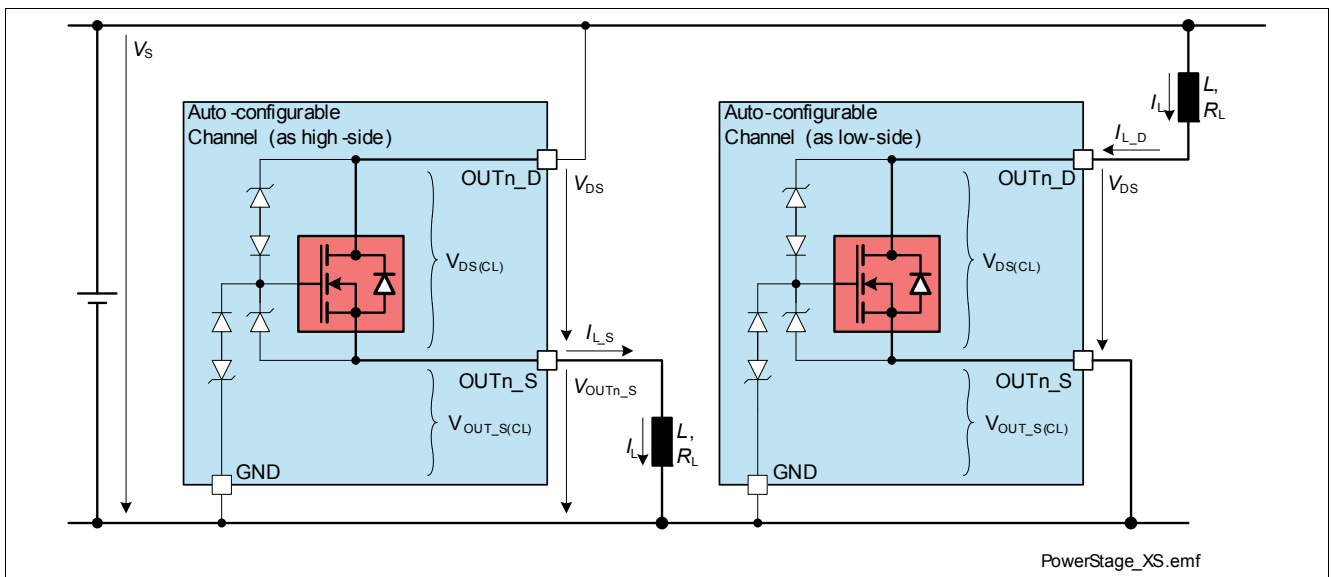


Figure 17 Output Clamp concept



- Diagnostic:  $V_{DS(OL)}$ ,  $V_{OUT(OL)}$ ,  $V_{OUT\_S(OL)}$ ,  $I_{L(OL)}$

Reliability in Limp Home condition for the unaffected channels is unchanged.

*Note: No protection mechanism like temperature protection or over load protection is active during applied inverse currents. Inverse currents cause power losses inside the DMOS, which increase the overall device temperature. This could lead to a switch OFF of unaffected channels due to Over Temperature*

### 7.3 Switching Channels in parallel

In case of appearance of a short circuit with channels in parallel, it may happen that the two channels switch OFF asynchronously, therefore bringing an additional thermal stress to the channel that switches OFF last. In order to avoid this condition, it is possible to parametrize in the SPI registers the parallel operation of two neighbour channels (bits **HWCR.PAR**). When operating in this mode, the fastest channel to react to an Over Load or Over Temperature condition will deactivate also the other. The inductive energy that two channels can handle once set in parallel is lower than twice the single channel energy (see P\_7.6.11). It is possible to synchronize the following couples of channels:

- channel 0 and channel 2 → **HWCR.PAR** (0) set to "1"
- channel 1 and channel 3 → **HWCR.PAR** (1) set to "1"
- channel 4 and channel 6 → **HWCR.PAR** (2) set to "1"
- channel 5 and channel 7 → **HWCR.PAR** (3) set to "1"

The synchronization bits influence only how the channels react to Over Load or Over Temperature conditions. Synchronized channels have to be switched ON and OFF individually by the micro-controller.

### 7.4 "Bulb Inrush Mode" (BIM)

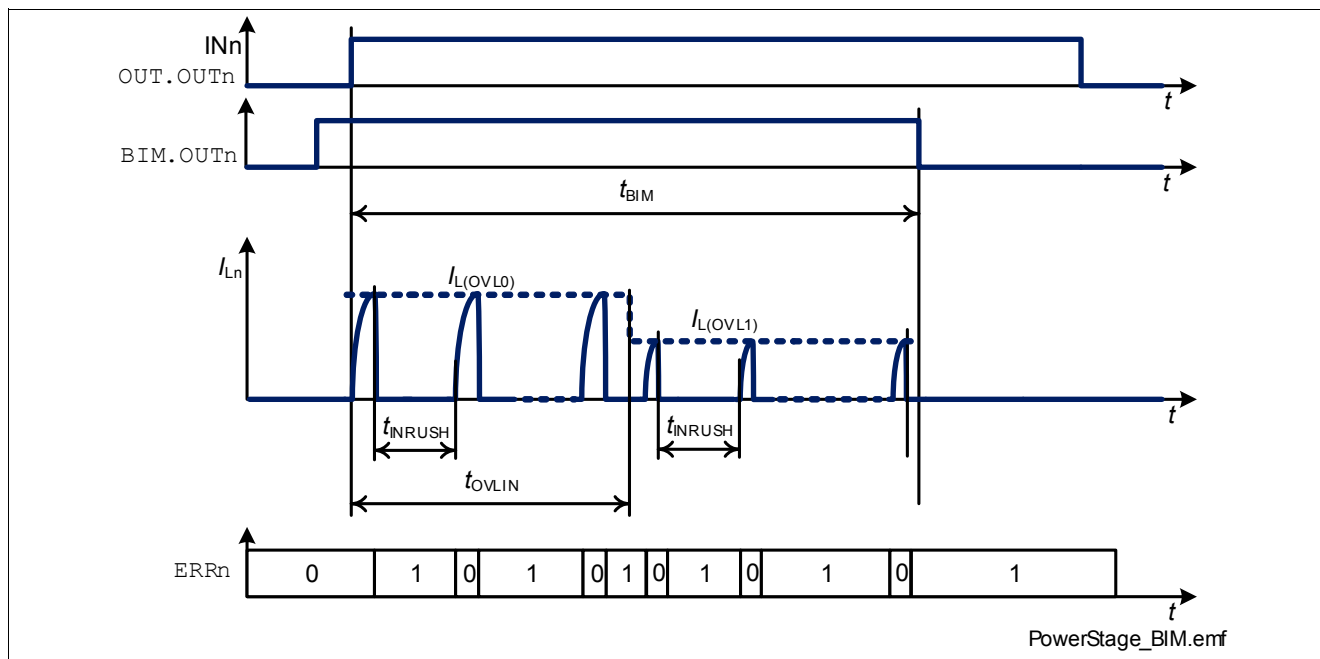
Although TLE75242-EMH is optimized for relays and LED, it may be necessary to use one or more of the outputs as high-side switches to drive small lamps (typically 2 W) or electronic loads with a big input capacitor. In such operative conditions, at the switch ON an inrush current may appear, reaching the overload current threshold which latches the channel OFF (see [Chapter 8.1](#) for further details). In normal operation the device waits until the microcontroller sends an SPI command to clear the latches (register **HWCR\_OCL**) allowing the channel to turn ON again. Usually this delay is too long to transfer enough energy to the load.

If the corresponding bit **BIM.OUTn** is set to "1", in case the channel reaches the overload current threshold or the overtemperature threshold and latches OFF, it restarts automatically after a time  $t_{INRUSH}$ , allowing the load to go out of the inrush phase. A time diagram is shown in [Figure 19](#). As shown, the counter starts when the channel is switched ON. Every channel switch OFF (independently from the entity controlling the channel - see [Figure 20](#) for further details) resets the bit **BIM.OUTn** to "0".

While **BIM.OUTn** bits are set to "1", **ERRn** bits may be also set to "1" but this doesn't latch the channel OFF.

An internal timer set the bit **BIM.OUTn** back to "0" after 40 ms (parameter  $t_{BIM}$ ) to prevent an excessive thermal stress to the channel, especially in case of short circuit at the output.

TLE75242-EMH allows a per-channel selection of Bulb Inrush Mode (BIM) in order to be fully flexible without any additional reliability risk.



**Figure 19** Bulb Inrush Mode (BIM) operation

## 7.5 Automatic PWM Generator

The TLE75242-EMH has two independent automatic PWM generator implemented. Each PWM generator can be assigned to one or more channels, and can be programmed with a different duty cycle and frequency.

Both PWM generator refer to a base frequency  $f_{INT}$  generated by an internal oscillator. This base frequency can be adjusted using `HWCR_PWM.ADJ` bits as described in [Table 9](#).

**Table 9** `HWCR_PWM.ADJ` coefficients overview

bit content	absolute delta to $f_{INT}$	relative delta between steps
0000 <sub>B</sub>	(reserved)	(reserved)
0001 <sub>B</sub>	-37.2%	-5.2%
0010 <sub>B</sub>	-31.9%	-5.1%
0011 <sub>B</sub>	-26.9%	-5.9%
0100 <sub>B</sub>	-21.0%	-5.5%
0101 <sub>B</sub>	-15.5%	-4.6%
0110 <sub>B</sub>	-10.9%	-5.1%
0111 <sub>B</sub>	-5.8%	-5.8%
1000 <sub>B</sub>	—	—
1001 <sub>B</sub>	+4.3%	+4.3%
1010 <sub>B</sub>	+8.9%	+4.6%
1011 <sub>B</sub>	+14.0%	+5.1%
1100 <sub>B</sub>	+19.5%	+5.6%
1101 <sub>B</sub>	+25.6%	+6.1%
1110 <sub>B</sub>	+32.4%	+6.8%
1111 <sub>B</sub>	+40.0%	+7.6%

For each PWM generator 4 parameters can be set:

- duty cycle (bits `PWM_CR0.DC` for PWM Generator 0)
  - 8 bits are available to achieve 0.39% duty cycle resolution
  - when the micro-controller programs a new duty cycle, the PWM generator waits until the previous cycle is completed before using the new duty cycle (this happens also when the duty cycle is either 0% or 100% - the new duty cycle is taken with the next PWM cycle)
  - the maximum duty cycle achievable is 99.61% (`PWM_CR0.DC` set to "11111111<sub>B</sub>"). It is possible to achieve 100% by setting `PWM_CR0.FREQ` to "11<sub>B</sub>"
- frequency (bits `PWM_CR0.FREQ` for PWM Generator 0)
  - with 2 bits is possible to select the divider for  $f_{INT}$  to achieve the needed duty cycle
  - $00_B = f_{INT} / 1024$  (when  $f_{INT} = 102.4$  kHz the corresponding PWM frequency is 100 Hz)
  - $01_B = f_{INT} / 512$  (corresponding to 200 Hz)
  - $10_B = f_{INT} / 256$  (corresponding to 400 Hz)
- channel output control and mapping registers `PWM_OUT` and `PWM_MAP`
  - any channel can be mapped to each PWM Generator
  - together with 2 parallel input it is possible to have 4 independent PWM groups of channels with low effort from the point of view of micro-controller resources and SPI data traffic

**Figure 20** expands the concept shown in **Figure 9** adding the PWM Generators.

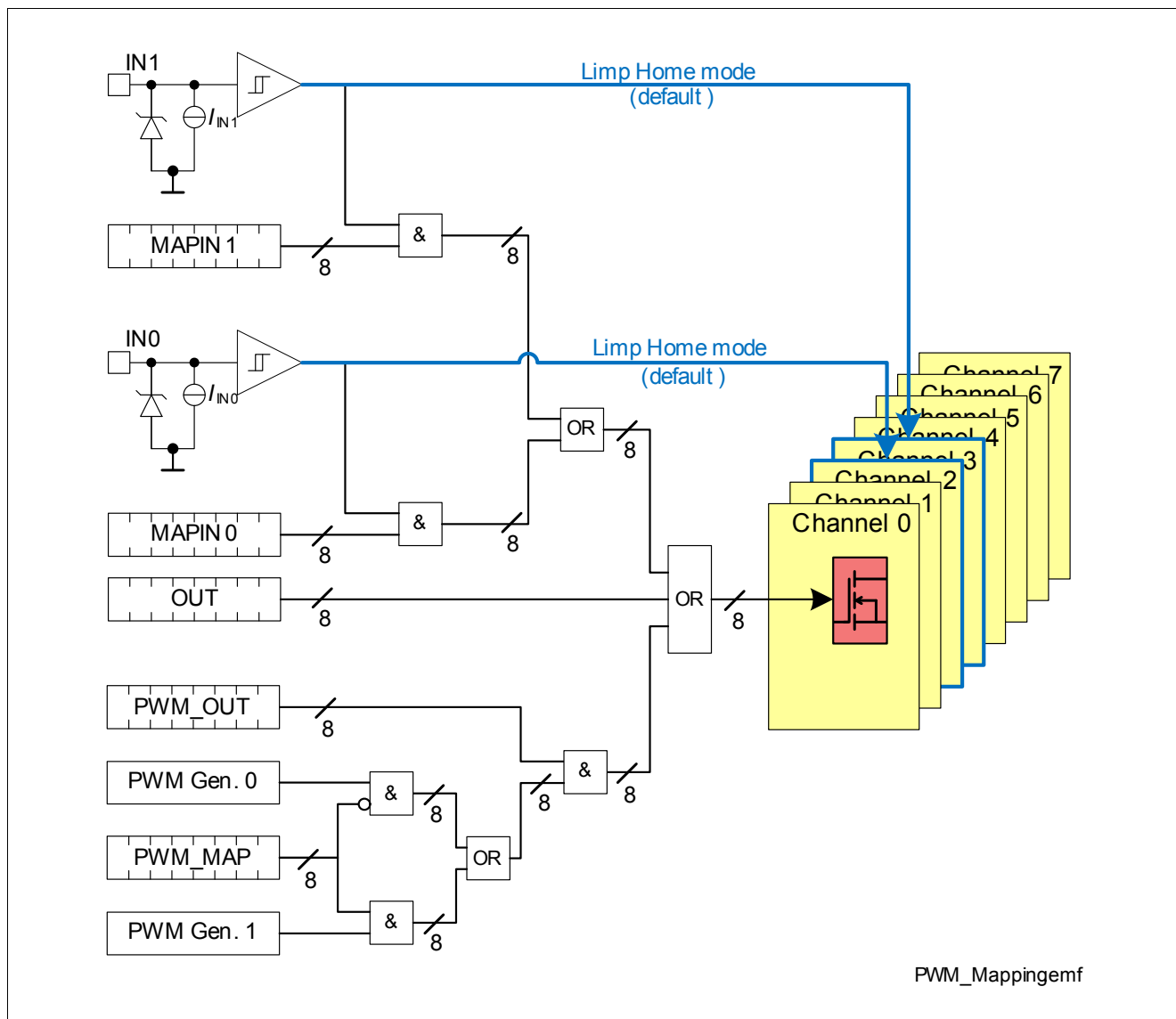


Figure 20 PWM Generator Mappings

## 7.6 Electrical Characteristics Power Stages

**Table 10 Electrical Characteristics: Power Stage**
 $V_{DD} = 3 \text{ V to } 5.5 \text{ V}$ ,  $V_S = 7 \text{ V to } 18 \text{ V}$ ,  $T_J = -40 \text{ °C to } +150 \text{ °C}$  (unless otherwise specified)

Typical values:  $V_{DD} = 5 \text{ V}$ ,  $V_S = 13.5 \text{ V}$ ,  $T_J = 25 \text{ °C}$ 

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Output Characteristics							
On-State Resistance	$R_{DS(ON)}$	–	1.0	–	$\Omega$	<sup>1)</sup> $T_J = 25\text{ °C}$	P_7.6.1
On-State Resistance	$R_{DS(ON)}$	–	1.8	2.2	$\Omega$	$T_J = 150\text{ °C}$ $I_L = I_{L(EAR)} = 220\text{ mA}$	P_7.6.2
Nominal load current (all channels active)	$I_{L(NOM)}$	–	330	500 <sup>2)3)</sup>	mA	<sup>1)</sup> $T_A = 85\text{ °C}$ $T_J \leq 150\text{ °C}$	P_7.6.3
Nominal load current (all channels active)	$I_{L(NOM)}$	–	260	500 <sup>2)3)</sup>	mA	<sup>1)</sup> $T_A = 105\text{ °C}$ $T_J \leq 150\text{ °C}$	P_7.6.4
Nominal load current (half of channels active)	$I_{L(NOM)}$	–	470	500 <sup>2)3)</sup>	mA	<sup>1)</sup> $T_A = 85\text{ °C}$ $T_J \leq 150\text{ °C}$	P_7.6.5
Load current for maximum energy dissipation - repetitive (all channels active)	$I_{L(EAR)}$	–	220	–	mA	<sup>1)</sup> $T_A = 85\text{ °C}$ $T_J \leq 150\text{ °C}$	P_7.6.8
Inverse current capability per channel (in High-Side operation)	$-I_{L(IC)}$	–	–	$I_{L(EAR)}$	mA	<sup>1)</sup> No influences on switching functionality of unaffected channels - parameter deviations possible	P_7.6.9
Maximum energy dissipation repetitive pulses - $2 \cdot I_{L(EAR)}$ (two channels in parallel)	$E_{AR}$	–	–	15	mJ	<sup>1)</sup> $T_{J(0)} = 85\text{ °C}$ $I_{L(0)} = 2 \cdot I_{L(EAR)}$ $2 \cdot 10^6$ cycles HWCR . PAR = “1” for affected channels	P_7.6.11
Power stage voltage drop at low battery Auto-configurable channels	$V_{DS(OP)}$	–	–	1	V	$R_L = 50\text{ }\Omega$ connected to $V_S$ or ground $V_S = V_{S(OP),max}$ $V_{Dn} = V_{S(OP),max}$ refer to <b>Figure 17</b>	P_7.6.13

**Table 10 Electrical Characteristics: Power Stage (cont'd)**
 $V_{DD} = 3 \text{ V to } 5.5 \text{ V}$ ,  $V_S = 7 \text{ V to } 18 \text{ V}$ ,  $T_J = -40 \text{ }^\circ\text{C to } +150 \text{ }^\circ\text{C}$  (unless otherwise specified)

Typical values:  $V_{DD} = 5 \text{ V}$ ,  $V_S = 13.5 \text{ V}$ ,  $T_J = 25 \text{ }^\circ\text{C}$ 

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Power stage voltage drop at low battery Low-side channels	$V_{DS(OP)}$	–	–	1	V	$R_L = 50 \text{ } \Omega$ supplied by $V_S = 4 \text{ V}$ $V_S = V_{S(OP),max}$ refer to <a href="#">Figure 16</a>	<a href="#">P_7.6.14</a>
Power stage voltage drop at low battery High-side channels	$V_{DS(OP)}$	–	–	1	V	$R_L = 50 \text{ } \Omega$ $V_S = V_{S(OP),max}$ $V_{S\_HS} = V_{S(OP),max}$ refer to <a href="#">Figure 18</a>	<a href="#">P_7.6.15</a>
Drain to Source Output clamping voltage	$V_{DS(CL)}$	42	46	55	V	$I_L = 20 \text{ mA}$ for High-Side Configuration $V_S = V_{OUT\_Dn} = 36 \text{ V}$ for High-Side Configuration $V_S = V_{S\_H} = 36 \text{ V}$	<a href="#">P_7.6.16</a>
Source to Ground Output clamping voltage Auto-configurable channels	$V_{OUT\_S(CL)}$	-25	–	-16	V	$I_L = 20 \text{ mA}$ $V_S = V_{OUT\_Dn} = 7 \text{ V}$	<a href="#">P_7.6.17</a>
Source to Ground Output clamping voltage High-side channels	$V_{OUT(CL)}$	-25	–	-16	V	$I_L = 20 \text{ mA}$ $V_S = V_{OUT\_Dn} = 7 \text{ V}$	<a href="#">P_7.6.18</a>
Output leakage current (each channel) $T_J \leq 85 \text{ }^\circ\text{C}$ (Low-Side channels)	$I_{L(OFF)}$	–	0.01	0.5	$\mu\text{A}$	<sup>1)</sup> $V_{IN} = 0 \text{ V}$ or floating $V_{DS} = 28 \text{ V}$ <a href="#">OUT.OUTn</a> = 0 $T_J \leq 85 \text{ }^\circ\text{C}$	<a href="#">P_7.6.19</a>
Output leakage current (each channel) $T_J \leq 85 \text{ }^\circ\text{C}$ (Auto-configurable and High-Side channels)	$I_{L(OFF)}$	–	0.01	0.5	$\mu\text{A}$	<sup>1)</sup> $V_{IN} = 0 \text{ V}$ or floating $V_{DS} = 28 \text{ V}$ $V_{OUT\_S} = 1.5\text{V}$ <a href="#">OUT.OUTn</a> = 0 $T_J \leq 85 \text{ }^\circ\text{C}$	<a href="#">P_7.6.47</a>
Output leakage current (each channel) $T_J = 150 \text{ }^\circ\text{C}$ (Low-Side channels)	$I_{L(OFF)}$	–	0.1	5	$\mu\text{A}$	<sup>1)</sup> $V_{IN} = 0 \text{ V}$ or floating $V_{DS} = 28 \text{ V}$ <a href="#">OUT.OUTn</a> = 0 $T_J = 150 \text{ }^\circ\text{C}$	<a href="#">P_7.6.20</a>

**Table 10 Electrical Characteristics: Power Stage (cont'd)**
 $V_{DD} = 3\text{ V to } 5.5\text{ V}$ ,  $V_S = 7\text{ V to } 18\text{ V}$ ,  $T_J = -40\text{ °C to } +150\text{ °C}$  (unless otherwise specified)

Typical values:  $V_{DD} = 5\text{ V}$ ,  $V_S = 13.5\text{ V}$ ,  $T_J = 25\text{ °C}$ 

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Output leakage current (each channel) $T_J = 150\text{ °C}$ (Auto-configurable and High-Side channels)	$I_{L(OFF)}$	–	0.1	5	$\mu\text{A}$	1) $V_{IN} = 0\text{ V or floating}$ $V_{DS} = 28\text{ V}$ $V_{OUT\_S} = 1.5\text{ V}$ <b>OUT.OUTn</b> = 0 $T_J = 150\text{ °C}$	P_7.6.49

**Timings**

Turn-ON delay (from INn pin or bit to $V_{OUT} = 90\% V_S$ ) (Low-Side channels and auto-configurable channels used as Low-Side switches)	$t_{DELAY(ON)}$	1	4	8	$\mu\text{s}$	$R_L = 50\text{ }\Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.28
Turn-OFF delay (from INn pin or bit to $V_{OUT} = 10\% V_S$ ) (Low-Side channels and auto-configurable channels used as Low-Side switches)	$t_{DELAY(OFF)}$	1	6	12	$\mu\text{s}$	$R_L = 50\text{ }\Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.29
Turn-ON time (from INn pin or bit to $V_{OUT} = 10\% V_S$ ) (Low-Side channels and auto-configurable channel used as Low-Side switches)	$t_{ON}$	6	15	35	$\mu\text{s}$	$R_L = 50\text{ }\Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.30
Turn-OFF time (from INn pin or bit to $V_{OUT} = 90\% V_S$ ) (Low-Side channels and auto-configurable channel used as Low-Side switches)	$t_{OFF}$	6	15	35	$\mu\text{s}$	$R_L = 50\text{ }\Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.31
Turn-ON/OFF matching (Low-Side channels and auto-configurable channel used as Low-Side switches)	$t_{ON} - t_{OFF}$	-10	0	10	$\mu\text{s}$	$R_L = 50\text{ }\Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.32
Turn-ON slew rate $V_{DS} = 70\% \text{ to } 30\% V_S$ (Low-Side channels and auto-configurable channel used as Low-Side switches)	$dV/dt_{ON}$	0.7	1.3	1.9	$\text{V}/\mu\text{s}$	$R_L = 50\text{ }\Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.33

**Table 10 Electrical Characteristics: Power Stage (cont'd)**
 $V_{DD} = 3\text{ V to } 5.5\text{ V}$ ,  $V_S = 7\text{ V to } 18\text{ V}$ ,  $T_J = -40\text{ °C to } +150\text{ °C}$  (unless otherwise specified)

Typical values:  $V_{DD} = 5\text{ V}$ ,  $V_S = 13.5\text{ V}$ ,  $T_J = 25\text{ °C}$ 

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Turn-OFF slew rate $V_{DS} = 30\% \text{ to } 70\% V_S$ (Low-Side channels and auto-configurable channels used as Low-Side switches)	$-dV/dt_{OFF}$	0.7	1.3	1.9	V/ $\mu$ s	$R_L = 50\ \Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.34
Turn-ON delay (from INn pin or bit to $V_{OUT} = 10\% V_S$ ) (Auto-configurable channels used as High-Side and High-Side switches)	$t_{DELAY(ON)}$	1	4	8	$\mu$ s	$R_L = 50\ \Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.35
Turn-OFF delay (from INn pin or bit to $V_{OUT} = 90\% V_S$ ) (Auto-configurable channels used as High-Side and High-Side switches)	$t_{DELAY(OFF)}$	1	6	12	$\mu$ s	$R_L = 50\ \Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.36
Turn-ON time (from INn pin or bit to $V_{OUT} = 90\% V_S$ ) (Auto-configurable channels used as High-Side and High-Side switches)	$t_{ON}$	6	15	35	$\mu$ s	$R_L = 50\ \Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.37
Turn-OFF time (from INn pin or bit to $V_{OUT} = 10\% V_S$ ) (Auto-configurable channels used as High-Side and High-Side switches)	$t_{OFF}$	6	15	35	$\mu$ s	$R_L = 50\ \Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.38
Turn-ON/OFF matching (Auto-configurable used as High-Side and High-Side switches)	$t_{ON} - t_{OFF}$	-10	0	10	$\mu$ s	$R_L = 50\ \Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.39
Turn-ON slew rate $V_{DS} = 30\% \text{ to } 70\% V_S$ (Auto-configurable used as High-Side and High-Side switches)	$dV/dt_{ON}$	0.7	1.3	1.9	V/ $\mu$ s	$R_L = 50\ \Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.40
Turn-OFF slew rate $V_{DS} = 70\% \text{ to } 30\% V_S$ (Auto-configurable used as High-Side and High-Side switches)	$-dV/dt_{OFF}$	0.7	1.3	1.9	V/ $\mu$ s	$R_L = 50\ \Omega$ $V_S = 13.5\text{ V}$ Active mode or Limp Home mode	P_7.6.41

**Table 10 Electrical Characteristics: Power Stage (cont'd)**
 $V_{DD} = 3\text{ V to } 5.5\text{ V}$ ,  $V_S = 7\text{ V to } 18\text{ V}$ ,  $T_J = -40\text{ °C to } +150\text{ °C}$  (unless otherwise specified)

Typical values:  $V_{DD} = 5\text{ V}$ ,  $V_S = 13.5\text{ V}$ ,  $T_J = 25\text{ °C}$ 

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Bulb Inrush Mode restart time	$t_{INRUSH}$	–	–	40	μs	<sup>1)</sup> Active mode	P_7.6.42
Bulb Inrush Mode reset time	$t_{BIM}$	–	40	–	ms	<sup>1)</sup> Active mode	P_7.6.43

**PWM Generator**

Internal reference frequency	$f_{INT}$	80	102	125	kHz	HWCR_PWM.ADJ = 1000 <sub>B</sub>	P_7.6.44
Internal reference frequency variation	$f_{INT(VAR)}$	-15	–	15	%	<sup>1)</sup>	P_7.6.56
Internal reference frequency synchronization time	$t_{SYNC}$	–	5	10	μs	<sup>1)</sup> HWCR_PWM.ADJ = 1000 <sub>B</sub>	P_7.6.45

1) Not subject to production test - specified by design

2) If one channel has  $I_{L(NOM),max}$  applied, the remaining channels must be underloaded accordingly so that  $T_J < 150\text{ °C}$ 

3)  $I_{L(NOM),max}$  can reach  $I_{L(OVL1),min}$

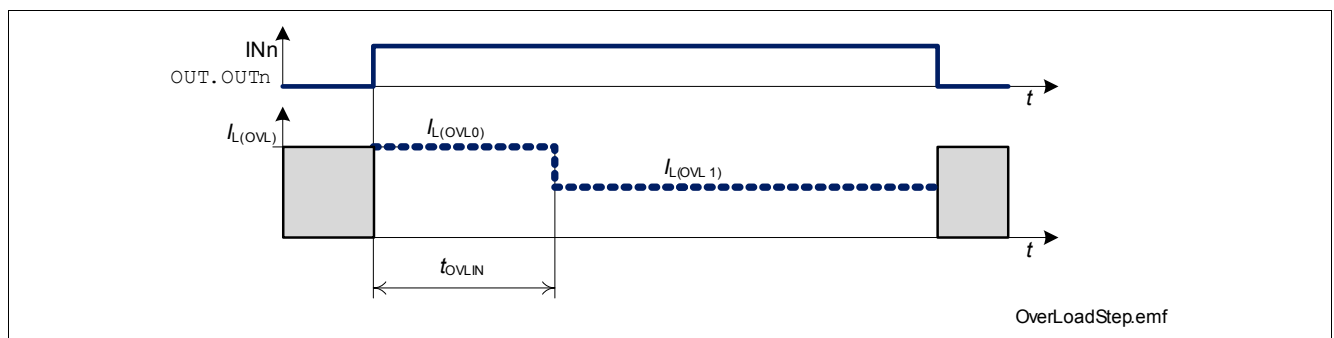
## 8 Protection Functions

### 8.1 Over Load Protection

The TLE75242-EMH is protected in case of over load or short circuit of the load. There are two over load current thresholds (see [Figure 21](#)):

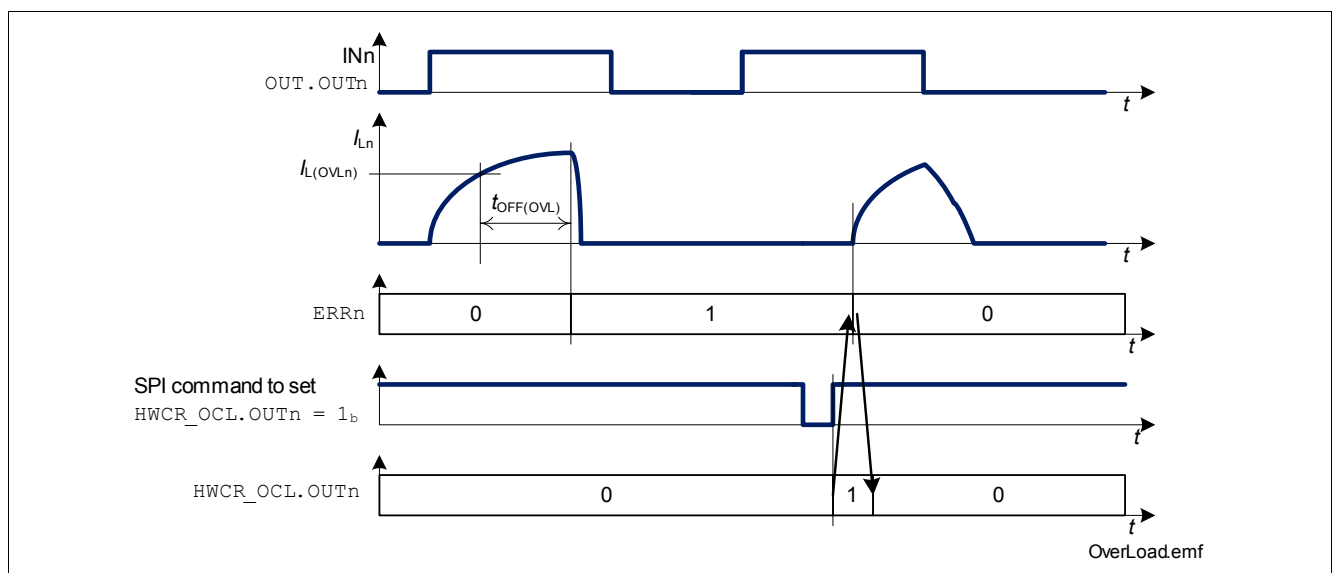
- $I_{L(OVL0)}$  between channel switch ON and  $t_{OVLIN}$
- $I_{L(OVL1)}$  after  $t_{OVLIN}$

Every time the channel is switched OFF for a time longer than  $2 \cdot t_{SYNC}$  the over load current threshold is set back to  $I_{L(OVL0)}$ .



**Figure 21 Over Load current thresholds**

In case the load current is higher than  $I_{L(OVL0)}$  or  $I_{L(OVL1)}$ , after time  $t_{OFF(OVL)}$  the over loaded channel is switched OFF and the according diagnosis bit **ERRn** is set. The channel can be switched ON after clearing the protection latch by setting the corresponding **HWCR\_OCL.OUTn** bit to "1". This bit is set back to "0" internally after de-latching the channel. Please refer to [Figure 22](#) for details.



**Figure 22 Latch OFF at Over Load**

### 8.2 Over Temperature Protection

A temperature sensor is integrated for each channel, causing an overheated channel to switch OFF to prevent destruction. The according diagnosis bit **ERRn** is set (combined with Over Load protection). The channel can be

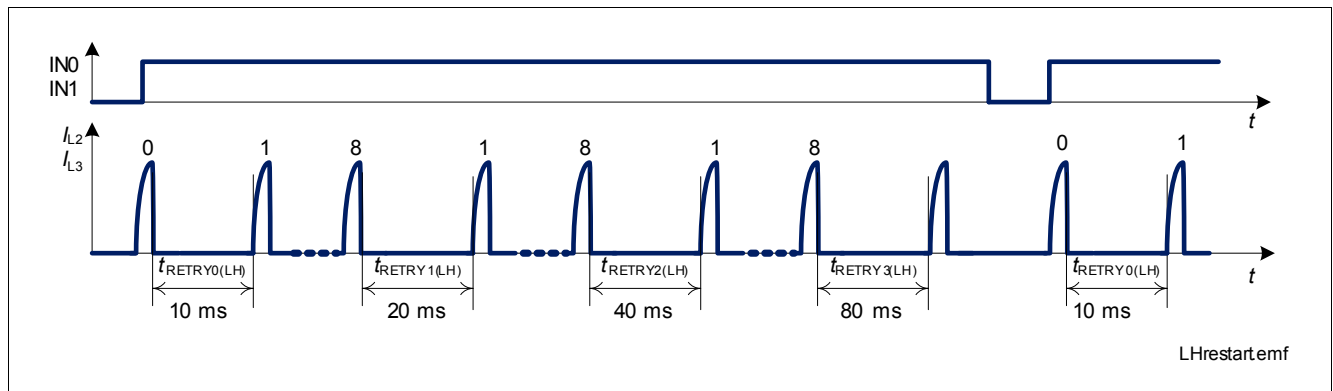
switched ON after clearing the protection latch by setting the corresponding **HWCR\_OCL.OUTn** bit to “1”. This bit is set back to “0” internally after de-latching the channel.

### 8.3 Over Temperature and Over Load Protection in Limp Home mode

When TLE75242-EMH is in Limp Home mode, channels 2 and 3 can be switched ON using the input pins. In case of Over Load, Short Circuit or Over Temperature the channels switch OFF. If the input pins remain “high”, the channels restart with the following timings:

- 10 ms (first 8 retries)
- 20 ms (following 8 retries)
- 40 ms (following 8 retries)
- 80 ms (as long as the input pin remains “high” and the error is still present)

If at any time the input pin is set to “low” for longer than  $2 \cdot t_{\text{SYNC}}$ , the restart timer is reset. At the next channel activation while in Limp Home mode the timer starts from 10 ms again. See **Figure 23** for details. Over Load current thresholds behave as described in **Chapter 8.1**.



**Figure 23** Restart timer in Limp Home mode

### 8.4 Reverse Polarity Protection

In Reverse Polarity (also known as Reverse Battery) condition, power dissipation is caused by the intrinsic body diode of each DMOS channel (for Low-Side channels and for auto-configurable channels used as Low-Side switches), while High-Side channels and auto-configurable channels used as High-Side switches have Reversave™ functionality. Each ESD diode of the logic and supply pins contributes to total power dissipation. Channels with Reversave™ functionality are switched ON almost with the same  $R_{\text{DS(ON)}}$  (see parameter  $R_{\text{DS(REV)}}$ ). The reverse current through the channels has to be limited by the connected loads. The current through digital power supply  $V_{\text{DD}}$  and input pins has to be limited as well (please refer to the Absolute Maximum Ratings listed on **Chapter 4.1**).

*Note: No protection mechanism like temperature protection or current limitation is active during reverse polarity.*

### 8.5 Over Voltage Protection

In the case of supply voltages between  $V_{\text{S(SC)}}$  and  $V_{\text{S(LD)}}$  the output transistors are still operational and follow the input pins or the **OUT** register.

In addition to the output clamp for inductive loads as described in **Chapter 7.1.2**, there is a clamp mechanism available for over voltage protection for the logic and all channels, monitoring the voltage between VS and GND pins ( $V_{\text{S(AZ)}}$ ).

## 8.6 Electrical Characteristics Protection

**Table 11 Electrical Characteristics Protection**
 $V_{DD} = 3\text{ V to }5.5\text{ V}$ ,  $V_S = 7\text{ V to }18\text{ V}$ ,  $T_J = -40\text{ °C to }+150\text{ °C}$  (unless otherwise specified)

Typical values:  $V_{DD} = 5\text{ V}$ ,  $V_S = 13.5\text{ V}$ ,  $T_J = 25\text{ °C}$ 

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Over Load							
Over Load detection current	$I_{L(OVL0)}$	1.3	1.7	2.3	A	$T_J = -40\text{ }^{\circ}\text{C}$	P_8.8.19
Over Load detection current	$I_{L(OVL0)}$	1.25	1.55	2.3	A	<sup>1)</sup> $T_J = 25\text{ }^{\circ}\text{C}$	P_8.8.20
Over Load detection current	$I_{L(OVL0)}$	1	1.45	2	A	$T_J = 150\text{ }^{\circ}\text{C}$	P_8.8.21
Over Load detection current	$I_{L(OVL1)}$	0.7	0.95	1.3	A	$T_J = -40\text{ }^{\circ}\text{C}$	P_8.8.22
Over Load detection current	$I_{L(OVL1)}$	0.65	0.85	1.3	A	<sup>1)</sup> $T_J = 25\text{ }^{\circ}\text{C}$	P_8.8.23
Over Load detection current	$I_{L(OVL1)}$	0.5	0.8	1.25	A	$T_J = 150\text{ }^{\circ}\text{C}$	P_8.8.24
Over Load threshold switch delay time	$t_{OVLIN}$	110	170	260	μs	<sup>1)</sup>	P_8.8.5
Over Load shut-down delay time	$t_{OFF(OVL)}$	4	7	11	μs	<sup>1)</sup> BIM.OUTn=HWCR. PAR=0 <sub>B</sub>	P_8.8.26
Over Temperature and Over Voltage							
Thermal shut-down temperature	$T_{J(SC)}$	150	175 <sup>1)</sup>	220 <sup>1)</sup>	°C		P_8.8.7
Over voltage protection	$V_{S(AZ)}$	42	50	60	V	$I_{VS} = 10\text{ mA}$ Sleep mode	P_8.8.8
Reverse Polarity							
Drain Source diode during reverse polarity (Low-Side channels and auto-configurable channels used as Low-Side switches)	$V_{DS(REV)}$	—	800	—	mV	<sup>1)</sup> $I_L = -10\text{ mA}$ $T_J = 25\text{ }^{\circ}\text{C}$ Sleep mode	P_8.8.9
Drain Source diode during reverse polarity (Low-Side channels and auto-configurable channels used as Low-Side switches)	$V_{DS(REV)}$	—	650	—	mV	$I_L = -10\text{ mA}$ $T_J = 150\text{ }^{\circ}\text{C}$ Sleep mode	P_8.8.10
On-State Resistance during Reverse Polarity (High-Side channels and auto-configurable channels used as High-Side switches)	$R_{DS(REV)}$	—	1.0	—	Ω	<sup>1)</sup> $V_S = -V_{S(REV)}$ $I_L = I_{L(EAR)}$ $T_J = 25\text{ }^{\circ}\text{C}$	P_8.8.11

**Table 11 Electrical Characteristics Protection (cont'd)**
 $V_{DD} = 3\text{ V to }5.5\text{ V}$ ,  $V_S = 7\text{ V to }18\text{ V}$ ,  $T_J = -40\text{ °C to }+150\text{ °C}$  (unless otherwise specified)

Typical values:  $V_{DD} = 5\text{ V}$ ,  $V_S = 13.5\text{ V}$ ,  $T_J = 25\text{ °C}$ 

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
On-State Resistance during Reverse Polarity (High-Side channels and auto-configurable channels used as High-Side switches)	$R_{DS(REV)}$	–	1.8	–	$\Omega$	<sup>1)</sup> $V_S = -V_{S(REV)}$ $I_L = I_{L(EAR)}$ $T_J = 150\text{ °C}$	P_8.8.12

**Timings**

Restart time in Limp Home mode	$t_{RETRY0(LH)}$	7	10	13	ms	<sup>1)</sup>	P_8.8.13
Restart time in Limp Home mode	$t_{RETRY1(LH)}$	14	20	26	ms	<sup>1)</sup>	P_8.8.14
Restart time in Limp Home mode	$t_{RETRY2(LH)}$	28	40	52	ms	<sup>1)</sup>	P_8.8.15
Restart time in Limp Home mode	$t_{RETRY3(LH)}$	56	80	104	ms	<sup>1)</sup>	P_8.8.16

<sup>1)</sup> Not subject to production test - specified by design

## 9 Diagnosis

The SPI of TLE75242-EMH provides diagnosis information about the device and the load status. Each channel diagnosis information is independent from other channels. An error condition on one channel has no influence on the diagnostic of other channels in the device (unless configured to work in parallel, see [Chapter 7.3](#) for more details).

### 9.1 Over Load and Over Temperature

When either an Over Load or an Over Temperature occurs on one channel, the diagnosis bit **ERRn** is set accordingly. As described in [Chapter 8.1](#) and [Chapter 8.2](#), the channel latches OFF and must be reactivated setting corresponding **HWCR\_OCL.OUTn** bit to "1".

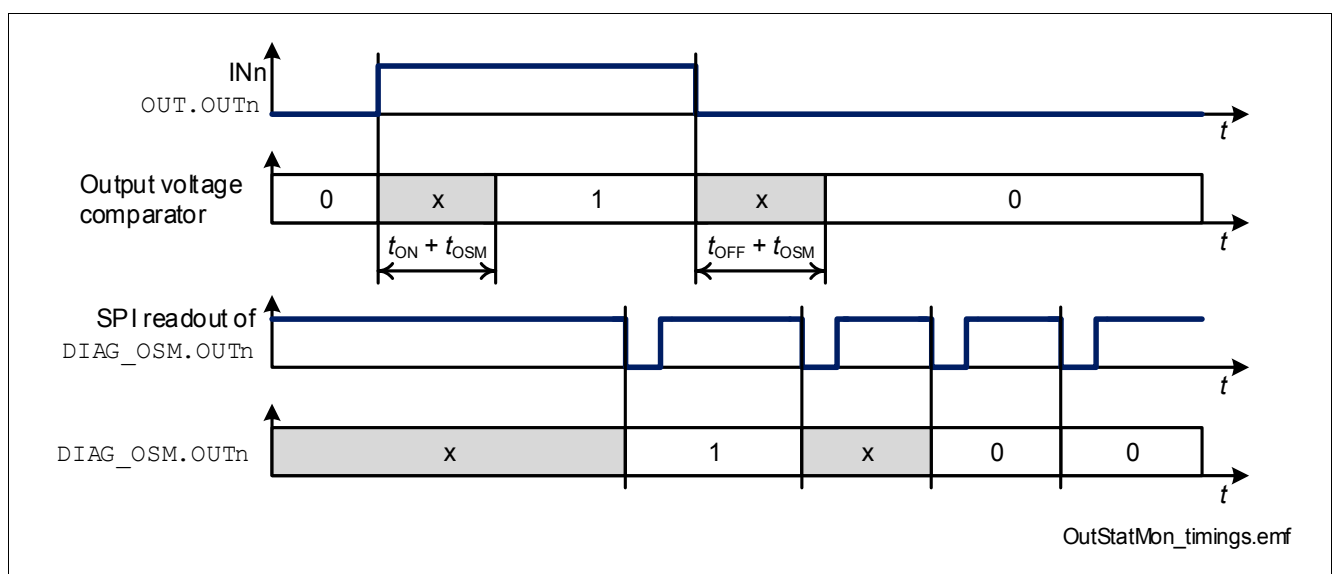
### 9.2 Output Status Monitor

The device compares each channel  $V_{DS}$  with  $V_{DS(OL)}$  (Low-Side channels and auto-configurable channels used as Low-Side switches),  $V_{OUT\_S}$  with  $V_{OUT\_S(OL)}$  (auto-configurable channels used as High-Side),  $V_{OUT}$  with  $V_{OUT(OL)}$  (High-Side channels) and sets the corresponding **DIAG\_OSM.OUTn** bits accordingly. The bits are updated every time **DIAG\_OSM** register is read.

- $V_{DS} < V_{DS(OL)} \rightarrow \text{DIAG\_OSM.OUTn} = "1"$  (Low-Side channels and auto-configurable channels as Low-Side)
- $V_{OUT\_S} > V_{OUT\_S(OL)} \rightarrow \text{DIAG\_OSM.OUTn} = "1"$  (auto-configurable channels as High-Side)
- $V_{OUT} > V_{OUT(OL)} \rightarrow \text{DIAG\_OSM.OUTn} = "1"$  (High-Side channels)

A diagnosis current  $I_{OL}$  in parallel to the power switch can be enabled by programming the **DIAG\_IOL.OUTn** bit, which can be used for Open Load at OFF detection. Each channel has its dedicated diagnosis current source. If the diagnosis current  $I_{OL}$  is enabled or if the channel changes state (ON  $\rightarrow$  OFF or OFF  $\rightarrow$  ON) it is necessary to wait a time  $t_{OSM}$  for a reliable diagnosis. Enabling  $I_{OL}$  current sources increases the current consumption of the device. Even if an Open Load is detected, the channel is not latched OFF.

See [Figure 24](#) for a timing overview (the values of **DIAG\_IOL.OUTn** refer to a channel in normal operation properly connected to the load).

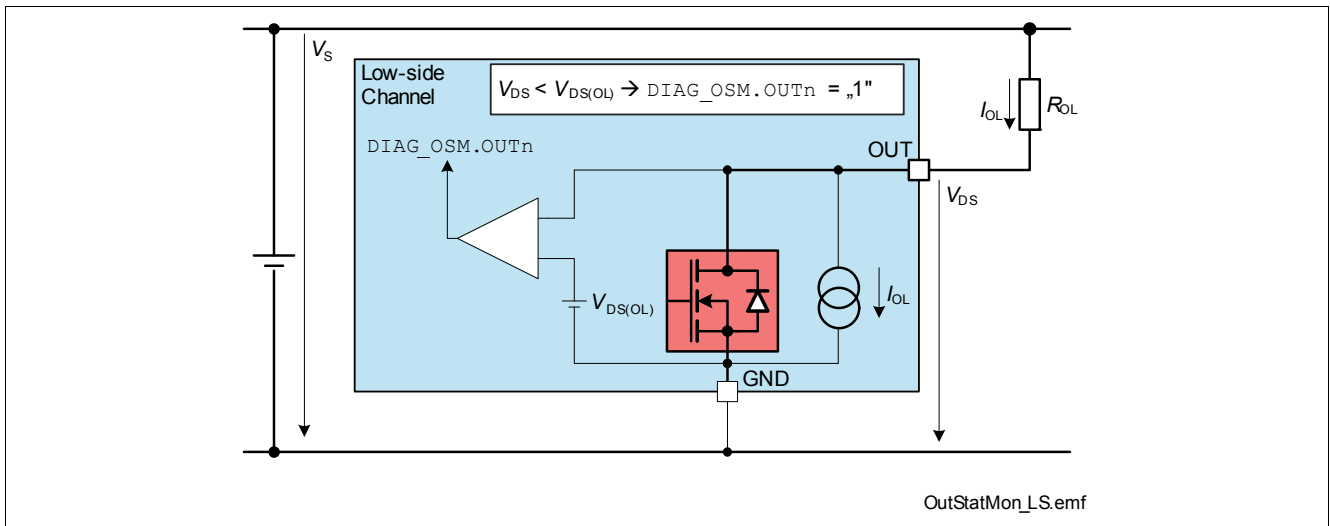


**Figure 24** Output Status Monitor timing

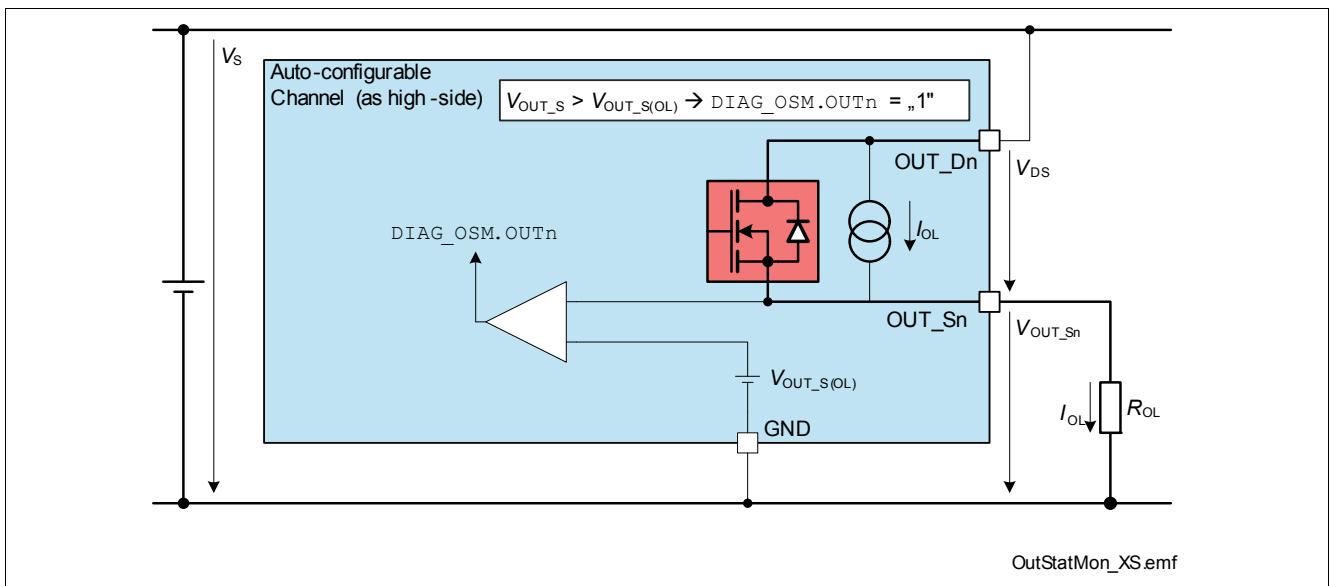
Output Status Monitor diagnostic is available when  $V_S = V_{S(NOR)}$  and  $V_{DD} \geq V_{DD(UV)}$ .

Due to the fact that Output Status Monitor checks the voltage level at the outputs in real time, for Open Load in OFF diagnostic it is necessary to synchronize the reading of **DIAG\_OSM** register with the OFF state of the channels.

**Figure 25**, **Figure 26** and **Figure 27** and **Figure 28** shows how Output Status Monitor is implemented at concept level.



**Figure 25** Output Status Monitor - concept (Low-Side channels)



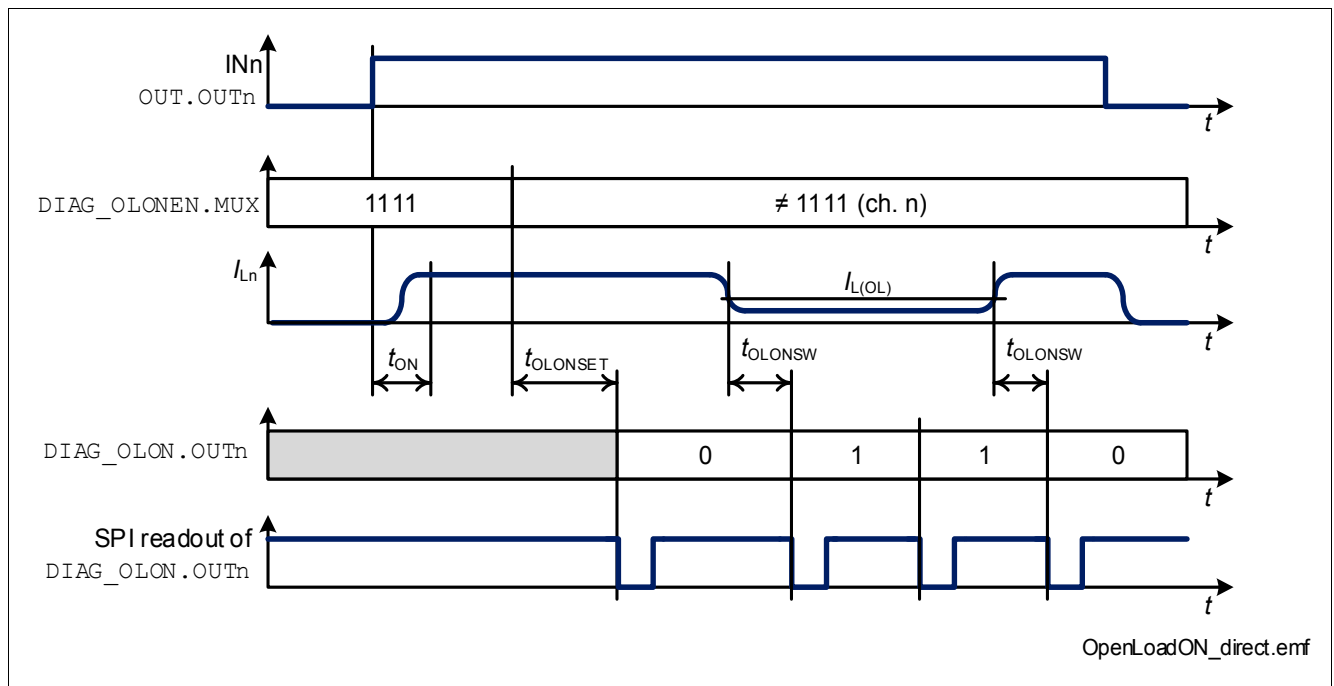
**Figure 26** Output Status Monitor - concept (auto-configurable channel as High-Side)



### 9.3.1 Open Load at ON - direct channel diagnosis

When **DIAG\_OLONEN.MUX** bits are programmed with a value corresponding to a channel ( $0010_B \rightarrow 0111_B$ ), the internal multiplexer checks for Open Load at ON condition on the selected channel. It is recommended that the channel is ON for at least  $t_{ON}$  before activating the diagnosis. After a time  $t_{OLONSET}$  the corresponding **DIAG\_OLON.OUTn** bit for the selected channel is available. All the other bits in the **DIAG\_OLON** register are set to default ( $0_B$ ). The bits are updated every time the register is read.

When a channel is selected, the corresponding **DIAG\_OLON.OUTn** bit content is mirrored also in the Standard Diagnosis (bit **OLON**). In case of several register readouts in sequence the register content is updated at every read request from micro-controller. See **Figure 29** for further details.



**Figure 29** Open Load at ON timings (direct channels diagnosis)

### 9.3.2 Open Load at ON - diagnosis loop

When **DIAG\_OLONEN.MUX** bits are programmed with the value  $1010_B$ , the device starts a diagnosis loop where all auto-configurable (when used as high-side switches) and high-side channels are checked for Open Load at ON. The internal multiplexer is controlled by the internal logic, therefore there is no need for the micro-controller to send any additional command.

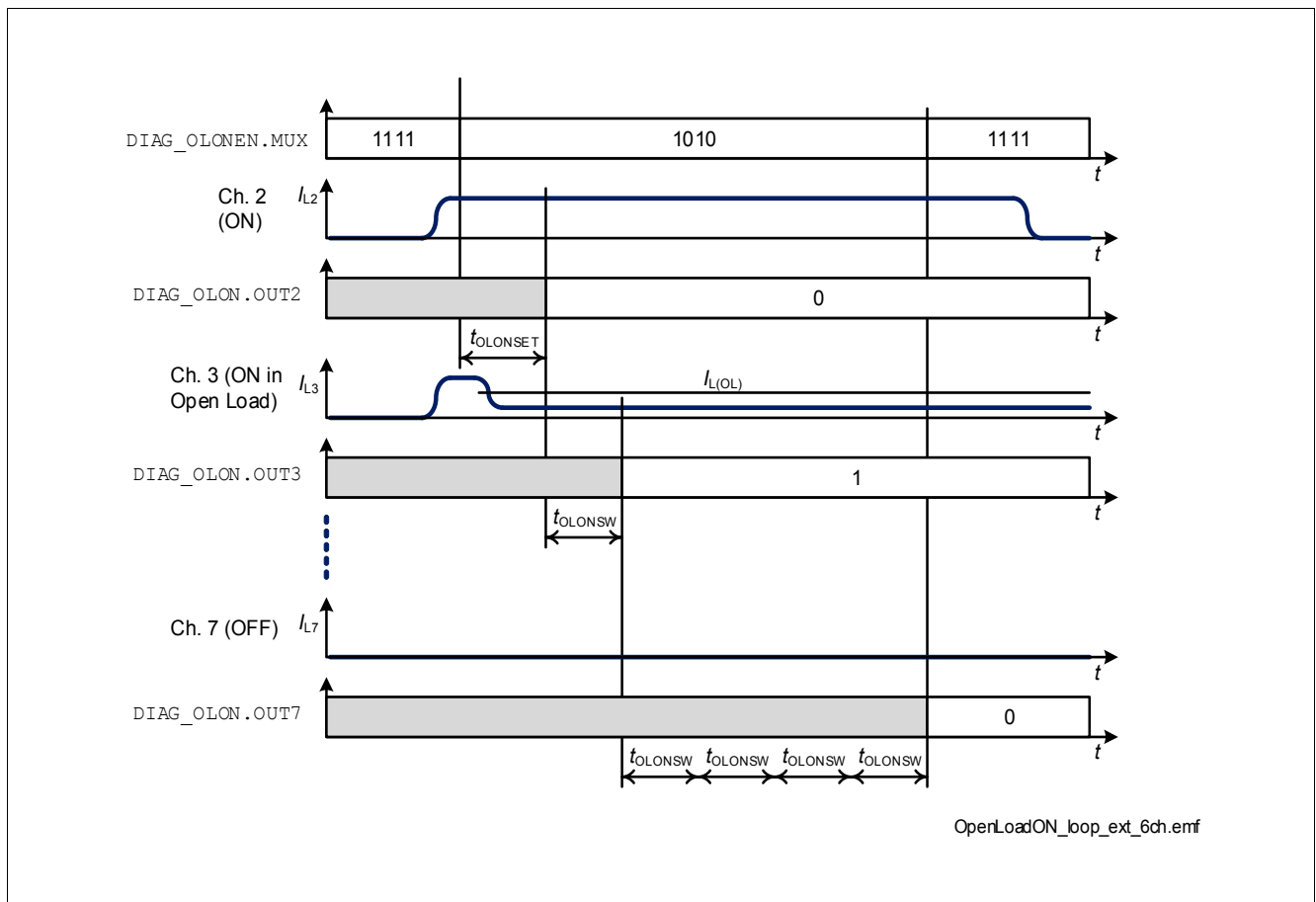
First the internal logic checks all channels which are directly driven by the micro-controller and not configured to be driven by the internal PWM generator, then the internal logic checks all channels which are configured to be driven by the internal PWM generator.

- Diagnosis sequence for channels driven directly by the micro-controller
  - First channel checked: channel 2. It is recommended that the channels are ON at least  $t_{ON}$  before activating the diagnosis loop.
  - After a time  $t_{OLONSET} + t_{SYNC}$  the diagnosis for the first channel is completed (**DIAG\_OLON.OUTn** bit is updated)
  - The internal multiplexer is set to the next channel. After a time  $t_{OLONSW} + t_{SYNC}$  the diagnosis is completed (**DIAG\_OLON.OUTn** bit is updated) for the currently selected channel. This step is repeated for all remaining directly driven channels.
  - If one channel is OFF when the diagnosis is performed, the corresponding **DIAG\_OLON.OUTn** is set to  $0_B$

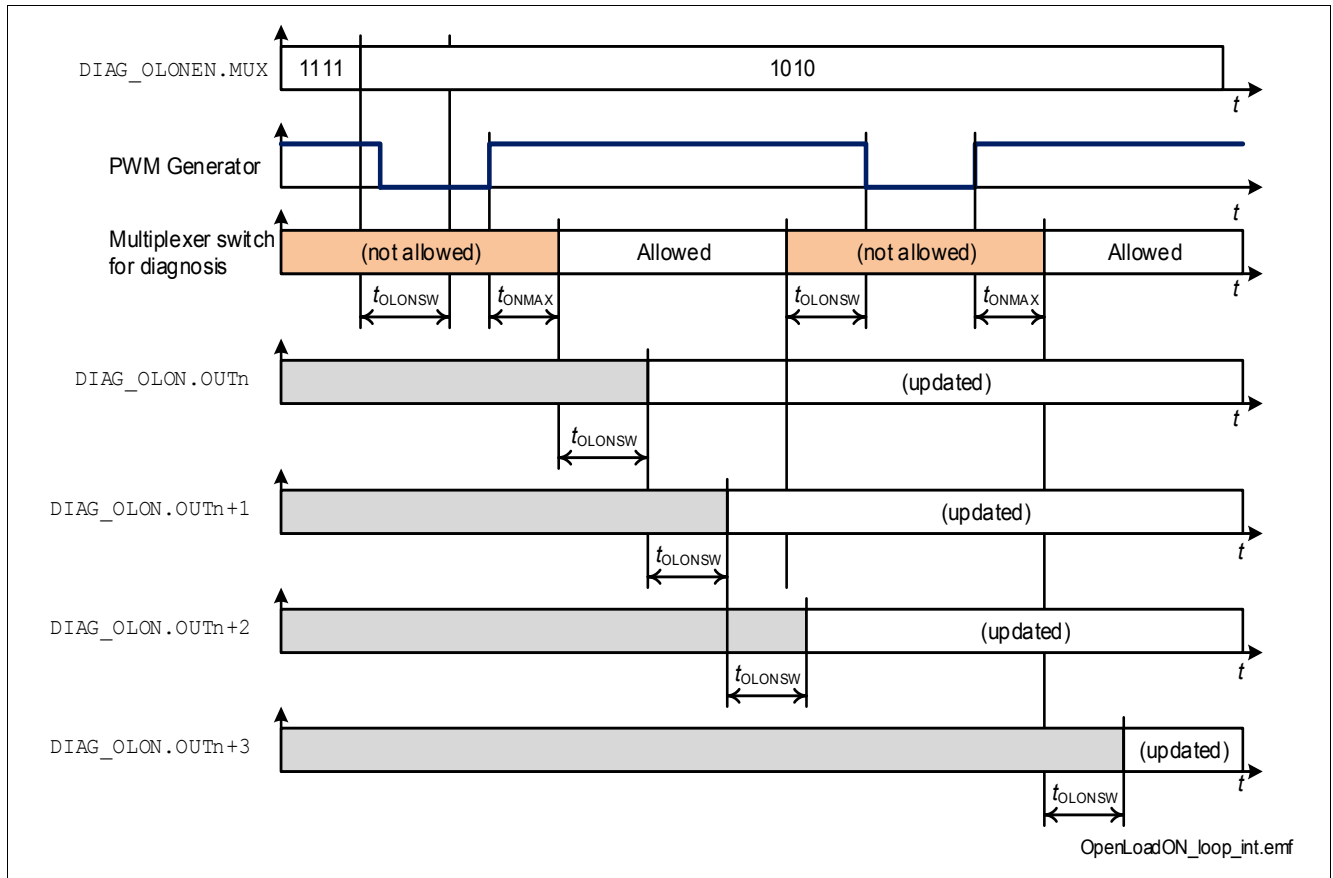
- Diagnosis sequence for channels driven by the internal PWM Generators (see [Chapter 7.5](#))
    - These channels are diagnosed only after all channels directly driven by micro-controller are checked
    - Channels mapped to PWM Generator 0 are diagnosed first
    - After a time  $t_{OLONSET}$  the channel activation (switch ON) is the trigger event to perform Open Load at ON diagnosis for the first channel
    - After a time  $t_{ONMAX} + t_{OLONSW}$  the diagnosis for the first channel is completed (**DIAG\_OLON.OUTn** bit is updated)
    - The internal multiplexer is set to the next channel. After a time  $t_{OLONSW}$  the diagnosis is completed (**DIAG\_OLON.OUTn** bit is updated) for the currently selected channel. This step is repeated for all remaining PWM generator driven channels.
- If the channel is in OFF state during the PWM period, the internal logic waits for the ON state to perform the diagnosis. After a time  $t_{ONMAX} + t_{OLONSW}$  the diagnosis for that channel is completed.
- The minimum ON time for a reliable diagnosis is  $> t_{ONMAX} + t_{OLONSW}$ . If the ON time is  $< t_{ONMAX} + t_{OLONSW}$  the corresponding **DIAG\_OLON.OUTn** is set to “0”.

When the loop finishes, **DIAG\_OLONEN.MUX** bits are set back to 1111<sub>B</sub> (default value) and **DIAG\_OLON.OUTn** bits store the last diagnosis loop result. It is necessary to start another diagnosis loop to update the register content.

[Figure 30](#) shows the timing in case of channels driven directly by micro-controller, while [Figure 31](#) represents the case with channels driven by internal PWM Generators.



**Figure 30** Open Load at ON timings (diagnosis loop - channels driven by micro-controller directly)



**Figure 31** Open Load at ON timings (diagnosis loop - channels driven by internal PWM Generators)

### 9.3.3 OLON bit

The **OLON** bit can assume the following values:

- “0” = no Open Load at ON state detected, or the channel is OFF when the diagnosis is performed
- “1” = Open Load at ON state detected

According to the setting of **DIAG\_OLONEN.MUX** different information are reported in the Standard Diagnosis.

- **DIAG\_OLONEN.MUX** set to 0010<sub>B</sub> → 0111<sub>B</sub>: The **OLON** bit shows the Open Load at ON state diagnosis performed on the selected channel. The information is updated at every Standard Diagnosis readout.
- **DIAG\_OLONEN.MUX** set to 1010<sub>B</sub>: the **OLON** bit shows the “OR” combination of all bits in **DIAG\_OLON** register. The information is updated while the diagnosis loop is running.
- **DIAG\_OLONEN.MUX** set to 1111<sub>B</sub>: the **OLON** bit shows the result of the latest diagnosis loop performed. It is necessary to start another diagnosis loop to update the information.
- **DIAG\_OLONEN.MUX** set to any other value: The **OLON** bit is set to “0”. These values of **DIAG\_OLONEN.MUX** bits are reserved and should not be used in the application.

## 9.4 Electrical Characteristics Diagnosis

**Table 12 Electrical Characteristics Diagnosis**
 $V_{DD} = 3\text{ V to } 5.5\text{ V}$ ,  $V_S = 7\text{ V to } 18\text{ V}$ ,  $T_J = -40\text{ °C to } +150\text{ °C}$  (unless otherwise specified)

Typical values:  $V_{DD} = 5\text{ V}$ ,  $V_S = 13.5\text{ V}$ ,  $T_J = 25\text{ °C}$ 

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Output Status Monitor							
Output Status Monitor comparator settling time	$t_{\text{OSM}}$	—	—	20	μs	1)	P_9.5.1
Output Status Monitor threshold voltage (Low-Side channels and auto-configurable channels used as Low-Side switches)	$V_{\text{DS(OL)}}$	3	3.3	3.6	V		P_9.5.2
Output Status Monitor threshold voltage (High-Side channels)	$V_{\text{OUT(OL)}}$	3	3.3	3.6	V	2)	P_9.5.3
Output Status Monitor threshold voltage (auto-configurable channels used as High-Side switches)	$V_{\text{OUT\_S(OL)}}$	3	3.3	3.6	V	3)	P_9.5.4
Output diagnosis current	$I_{\text{OL}}$	70	85	100	μA	$V_{\text{DS}} = 3.3\text{ V}$ (Low-Side channels and auto-configurable channels used as Low-Side switches) $V_{\text{OUT}} = 3.3\text{ V}$ (High-Side channels) $V_{\text{OUT\_S}} = 3.3\text{ V}$ (auto-configurable channels used as High-Side switches)	P_9.5.5
Open Load equivalent resistance	$R_{\text{OL}}$	30	—	300	kΩ	1)	P_9.5.6
Open Load at ON							
Open Load at ON Diagnosis waiting time before mux activation	$t_{\text{ONMAX}}$	40	58	76	μs	1)	P_9.5.7
Open Load at ON Diagnosis settling time	$t_{\text{OLONSET}}$	—	20	40	μs	1)	P_9.5.8
Open Load at ON Diagnosis channel switching time	$t_{\text{OLONSW}}$	—	10	20	μs	1)	P_9.5.9

**Table 12 Electrical Characteristics Diagnosis (cont'd)**
 $V_{DD} = 3\text{ V to } 5.5\text{ V}$ ,  $V_S = 7\text{ V to } 18\text{ V}$ ,  $T_J = -40\text{ °C to } +150\text{ °C}$  (unless otherwise specified)

Typical values:  $V_{DD} = 5\text{ V}$ ,  $V_S = 13.5\text{ V}$ ,  $T_J = 25\text{ °C}$ 

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Open Load detection threshold current	$I_{L(OL)}$	1	6	10	mA	$T_J = -40\text{ °C}$	P_9.5.10
Open Load detection threshold current	$I_{L(OL)}$	–	6	–	mA	<sup>1)</sup> $T_J = 25\text{ °C}$	P_9.5.11
Open Load detection threshold current	$I_{L(OL)}$	1	6	10	mA	$T_J = 150\text{ °C}$	P_9.5.12

1) Not subject to production test - specified by design

2) Output status detection voltages are referenced to ground (GND pin)

3) Output status detection voltages are referenced to ground (GND pin)

## 10 Serial Peripheral Interface (SPI)

The serial peripheral interface (SPI) is a full duplex synchronous serial slave interface, which uses four lines: SO, SI, SCLK and CSN. Data is transferred by the lines SI and SO at the rate given by SCLK. The falling edge of CSN indicates the beginning of an access. Data is sampled in on line SI at the falling edge of SCLK and shifted out on line SO at the rising edge of SCLK. Each access must be terminated by a rising edge of CSN. A modulo 8/16 counter ensures that data is taken only when a multiple of 8 bit has been transferred after the first 16 bits. Otherwise a TER bit is asserted. In this way the interface provides daisy chain capability with 16 bit as well as with 8 bit SPI devices.

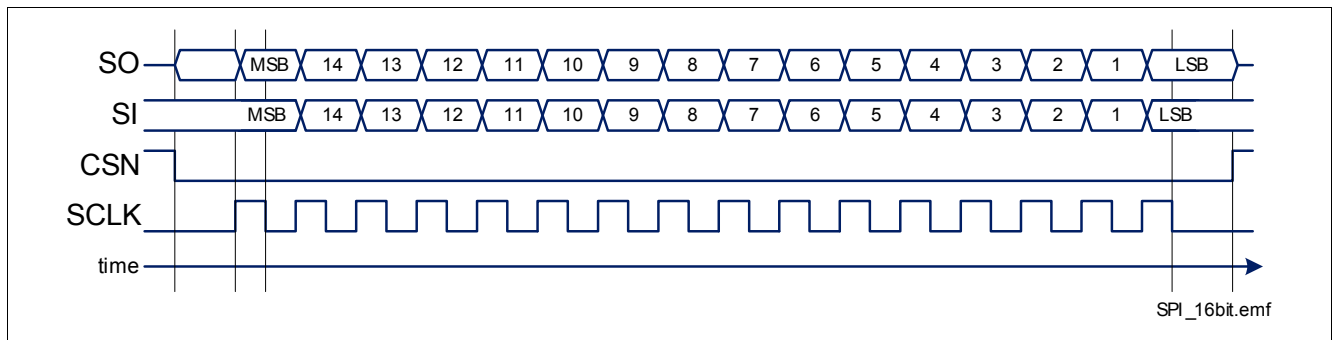


Figure 32 Serial Peripheral Interface

### 10.1 SPI Signal Description

#### CSN - Chip Select

The system microcontroller selects the TLE75242-EMH by means of the CSN pin. Whenever the pin is in "low" state, data transfer can take place. When CSN is in "high" state, any signals at the SCLK and SI pins are ignored and SO is forced into a high impedance state.

#### CSN "high" to "low" Transition

- The requested information is transferred into the shift register.
- SO changes from high impedance state to "high" or "low" state depending on the logic OR combination between the transmission error flag (TER) and the signal level at pin SI. This allows to detect a faulty transmission even in daisy chain configuration.
- If the device is in Sleep mode, SO pin remains in high impedance state and no SPI transmission occurs.

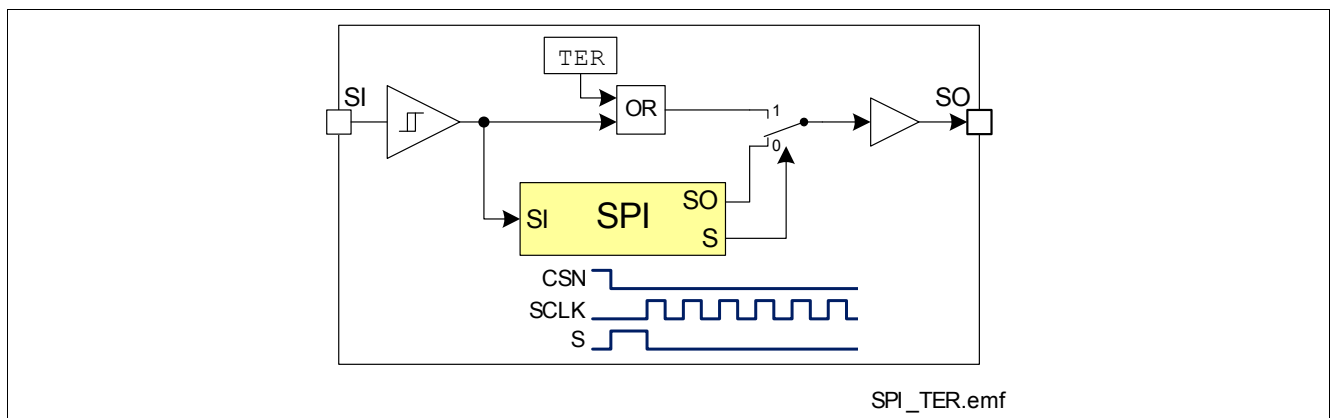


Figure 33 Combinatorial Logic for TER bit

### CSN "low" to "high" Transition

- Command decoding is only done, when after the falling edge of CSN exactly a multiple (1, 2, 3, ...) of eight SCLK signals have been detected after the first 16 SCLK pulses. In case of faulty transmission, the transmission error bit (**TER**) is set and the command is ignored.
- Data from shift register is transferred into the addressed register.

### SCLK - Serial Clock

This input pin clocks the internal shift register. The serial input (SI) transfers data into the shift register on the falling edge of SCLK while the serial output (SO) shifts diagnostic information out on the rising edge of the serial clock. It is essential that the SCLK pin is in "low" state whenever chip select CSN makes any transition, otherwise the command may be not accepted.

### SI - Serial Input

Serial input data bits are shift-in at this pin, the most significant bit first. SI information is read on the falling edge of SCLK. The input data consists of two parts, control bits followed by data bits. Please refer to [Chapter 10.5](#) for further information.

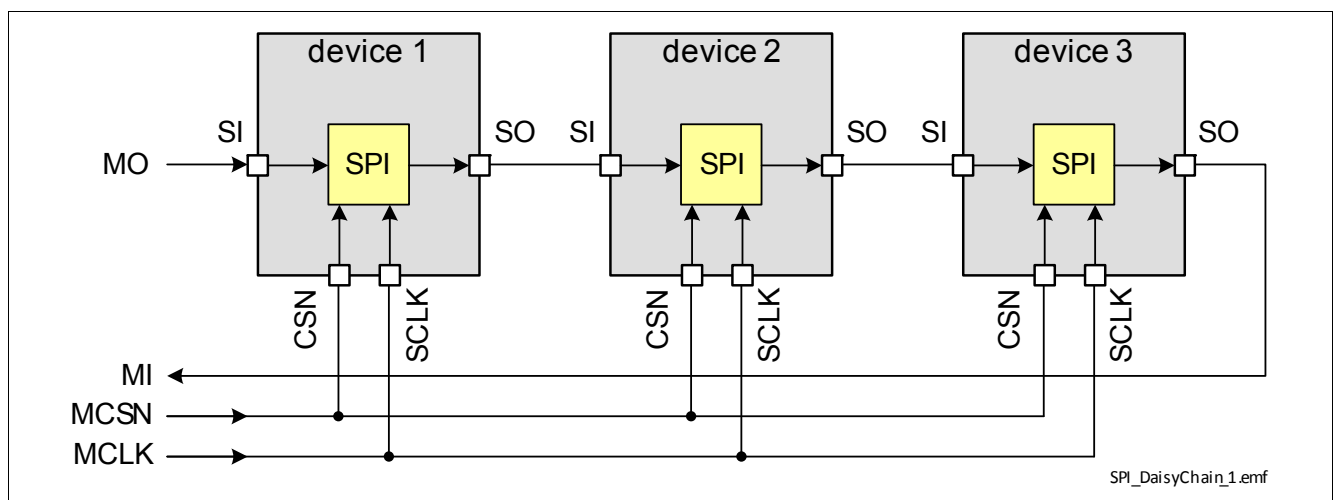
### SO Serial Output

Data is shifted out serially at this pin, the most significant bit first. SO is in high impedance state until the CSN pin goes to "low" state. New data appears at the SO pin following the rising edge of SCLK.

Please refer to [Chapter 10.5](#) for further information.

## 10.2 Daisy Chain Capability

The SPI of TLE75242-EMH provides daisy chain capability. In this configuration several devices are activated by the same CSN signal MCSN. The SI line of one device is connected with the SO line of another device (see [Figure 34](#)), in order to build a chain. The end of the chain is connected to the output and input of the master device, MO and MI respectively. The master device provides the master clock MCLK which is connected to the SCLK line of each device in the chain.

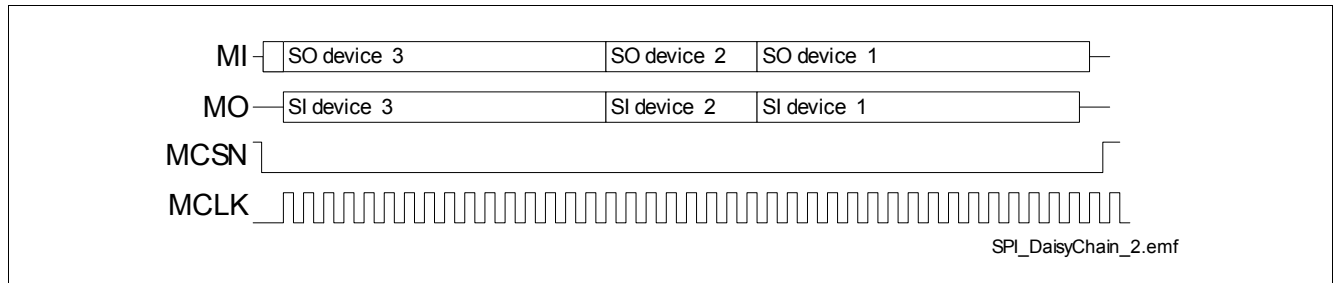


**Figure 34** Daisy Chain Configuration

In the SPI block of each device, there is one shift register where each bit from SI line is shifted in each SCLK. The bit shifted out occurs at the SO pin. After sixteen SCLK cycles, the data transfer for one device is finished. In single chip configuration, the CSN line must turn "high" to make the device acknowledge the transferred data. In daisy

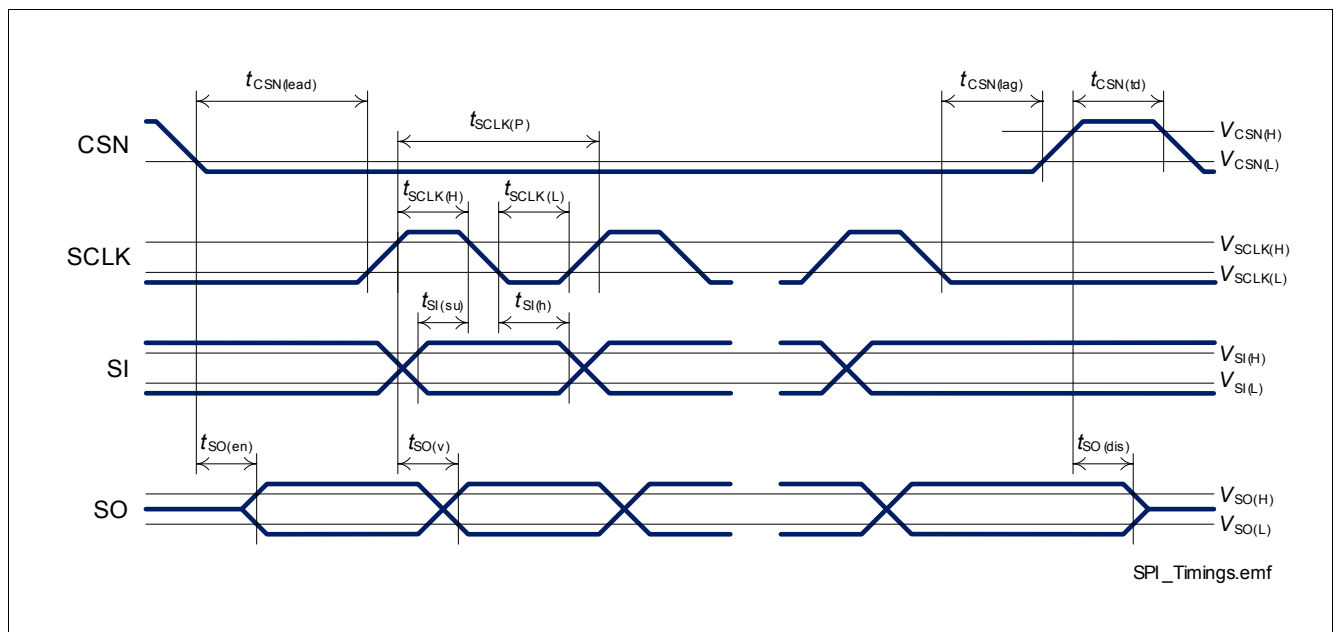
## Serial Peripheral Interface (SPI)

chain configuration, the data shifted out at device 1 has been shifted in to device 2. When using three devices in daisy chain, several multiples of 8 bits have to be shifted through the devices (depending on how many devices with 8 bit SPI and how many with 16 bit SPI). After that, the MCSN line must turn “high” (see [Figure 35](#)).



**Figure 35** Data Transfer in Daisy Chain Configuration

## 10.3 Timing Diagrams



**Figure 36** Timing Diagram SPI Access

## Serial Peripheral Interface (SPI)

## 10.4 Electrical Characteristics

 $V_{DD} = 3 \text{ V to } 5.5 \text{ V}$ ,  $V_S = 7 \text{ V to } 18 \text{ V}$ ,  $T_J = -40 \text{ }^\circ\text{C to } +150 \text{ }^\circ\text{C}$  (unless otherwise specified)

Typical values:  $V_{DD} = 5 \text{ V}$ ,  $V_S = 13.5 \text{ V}$ ,  $T_J = 25 \text{ }^\circ\text{C}$ 
**Table 13 Electrical Characteristics Serial Peripheral Interface (SPI)**

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Input Characteristics (CSN, SCLK, SI) - “low” level of pin							
CSN	$V_{\text{CSN(L)}}$	0	—	0.8	V	—	P_10.4.1
SCLK	$V_{\text{SCLK(L)}}$	0	—	0.8	V	—	P_10.4.2
SI	$V_{\text{SI(L)}}$	0	—	0.8	V	—	P_10.4.3
Input Characteristics (CSN, SCLK, SI) - “high” level of pin							
CSN	$V_{\text{CSN(H)}}$	2	—	$V_{\text{DD}}$	V	—	P_10.4.4
SCLK	$V_{\text{SCLK(H)}}$	2	—	$V_{\text{DD}}$	V	—	P_10.4.5
SI	$V_{\text{SI(H)}}$	2	—	$V_{\text{DD}}$	V	—	P_10.4.6
Input Pull-Up Current at Pin CSN							
L-input pull-up current at CSN pin	$-I_{\text{CSN(L)}}$	30	60	90	μA	$V_{\text{DD}} = 5 \text{ V}$ $V_{\text{CSN}} = 0.8 \text{ V}$	P_10.4.7
H-input pull-up current at CSN pin	$-I_{\text{CSN(H)}}$	20	40	65	μA	$V_{\text{DD}} = 5 \text{ V}$ $V_{\text{CSN}} = 2 \text{ V}$	P_10.4.8
L-Input Pull-Down Current at Pin							
SCLK	$I_{\text{SCLK(L)}}$	5	12	20	μA	$V_{\text{SCLK}} = 0.8 \text{ V}$	P_10.4.9
SI	$I_{\text{SI(L)}}$	5	12	20	μA	$V_{\text{SI}} = 0.8 \text{ V}$	P_10.4.10
H-Input Pull-Down Current at Pin							
SCLK	$I_{\text{SCLK(H)}}$	14	28	45	μA	$V_{\text{SCLK}} = 2 \text{ V}$	P_10.4.11
SI	$I_{\text{SI(H)}}$	14	28	45	μA	$V_{\text{SI}} = 2 \text{ V}$	P_10.4.12
Output Characteristics (SO)							
L level output voltage	$V_{\text{SO(L)}}$	0	—	0.4	V	$I_{\text{SO}} = -1.5 \text{ mA}$	P_10.4.13
H level output voltage	$V_{\text{SO(H)}}$	$V_{\text{DD}} - 0.4$	—	$V_{\text{DD}}$	V	$I_{\text{SO}} = 1.5 \text{ mA}$	P_10.4.14
Output tristate leakage current	$I_{\text{SO(OFF)}}$	-1	—	1	μA	$V_{\text{CSN}} = V_{\text{DD}}$ $V_{\text{SO}} = 0 \text{ V}$	P_10.4.15
Output tristate leakage current	$I_{\text{SO(OFF)}}$	-1	—	1	μA	$V_{\text{CSN}} = V_{\text{DD}}$ $V_{\text{SO}} = V_{\text{DD}}$	P_10.4.16
Timings							
Enable lead time (falling CSN to rising SCLK)	$t_{\text{CSN(lead)}}$	200	—	—	ns	<sup>1)</sup> $V_{\text{DD}} = 4.5 \text{ V}$ or $V_{\text{S}} > 7 \text{ V}$	P_10.4.17
Enable lag time (falling SCLK to rising CSN)	$t_{\text{CSN(lag)}}$	200	—	—	ns	<sup>1)</sup> $V_{\text{DD}} = 4.5 \text{ V}$ or $V_{\text{S}} > 7 \text{ V}$	P_10.4.18

## Serial Peripheral Interface (SPI)

Table 13 Electrical Characteristics Serial Peripheral Interface (SPI) (cont'd)

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Transfer delay time (rising CSN to falling CSN)	$t_{\text{CSN(td)}}$	250	–	–	ns	<sup>1)</sup> $V_{\text{DD}} = 4.5 \text{ V}$ or $V_{\text{S}} > 7 \text{ V}$	P_10.4.19
Output enable time (falling CSN to SO valid)	$t_{\text{SO(en)}}$	–	–	200	ns	<sup>1)</sup> $V_{\text{DD}} = 4.5 \text{ V}$ or $V_{\text{S}} > 7 \text{ V}$ $C_{\text{L}} = 20 \text{ pF}$ at SO pin	P_10.4.20
Output disable time (rising CSN to SO tristate)	$t_{\text{SO(dis)}}$	–	–	200	ns	<sup>1)</sup> $V_{\text{DD}} = 4.5 \text{ V}$ or $V_{\text{S}} > 7 \text{ V}$ $C_{\text{L}} = 20 \text{ pF}$ at SO pin	P_10.4.21
Serial clock frequency	$f_{\text{SCLK}}$	–	–	5	MHz	<sup>1)</sup> $V_{\text{DD}} = 4.5 \text{ V}$ or $V_{\text{S}} > 7 \text{ V}$	P_10.4.22
Serial clock period	$t_{\text{SCLK(P)}}$	200	–	–	ns	<sup>1)</sup> $V_{\text{DD}} = 4.5 \text{ V}$ or $V_{\text{S}} > 7 \text{ V}$	P_10.4.23
Serial clock “high” time	$t_{\text{SCLK(H)}}$	75	–	–	ns	<sup>1)</sup> $V_{\text{DD}} = 4.5 \text{ V}$ or $V_{\text{S}} > 7 \text{ V}$	P_10.4.24
Serial clock “low” time	$t_{\text{SCLK(L)}}$	75	–	–	ns	<sup>1)</sup> $V_{\text{DD}} = 4.5 \text{ V}$ or $V_{\text{S}} > 7 \text{ V}$	P_10.4.25
Data setup time (required time SI to falling SCLK)	$t_{\text{SI(su)}}$	20	–	–	ns	<sup>1)</sup> $V_{\text{DD}} = 4.5 \text{ V}$ or $V_{\text{S}} > 7 \text{ V}$	P_10.4.26
Data hold time (falling SCLK to SI)	$t_{\text{SI(h)}}$	20	–	–	ns	<sup>1)</sup> $V_{\text{DD}} = 4.5 \text{ V}$ or $V_{\text{S}} > 7 \text{ V}$	P_10.4.27
Output data valid time with capacitive load	$t_{\text{SO(v)}}$	–	–	100	ns	<sup>1)</sup> $V_{\text{DD}} = 4.5 \text{ V}$ or $V_{\text{S}} > 7 \text{ V}$ $C_{\text{L}} = 20 \text{ pF}$ at SO pin	P_10.4.28
Enable lead time (falling CSN to rising SCLK)	$t_{\text{CSN(lead)}}$	1	–	–	$\mu\text{s}$	<sup>1)</sup> $V_{\text{DD}} = V_{\text{S}} = 3.0 \text{ V}$	P_10.4.29
Enable lag time (falling SCLK to rising CSN)	$t_{\text{CSN(lag)}}$	1	–	–	$\mu\text{s}$	<sup>1)</sup> $V_{\text{DD}} = V_{\text{S}} = 3.0 \text{ V}$	P_10.4.30
Transfer delay time (rising CSN to falling CSN)	$t_{\text{CSN(td)}}$	1.25	–	–	$\mu\text{s}$	<sup>1)</sup> $V_{\text{DD}} = V_{\text{S}} = 3.0 \text{ V}$	P_10.4.31

## Serial Peripheral Interface (SPI)

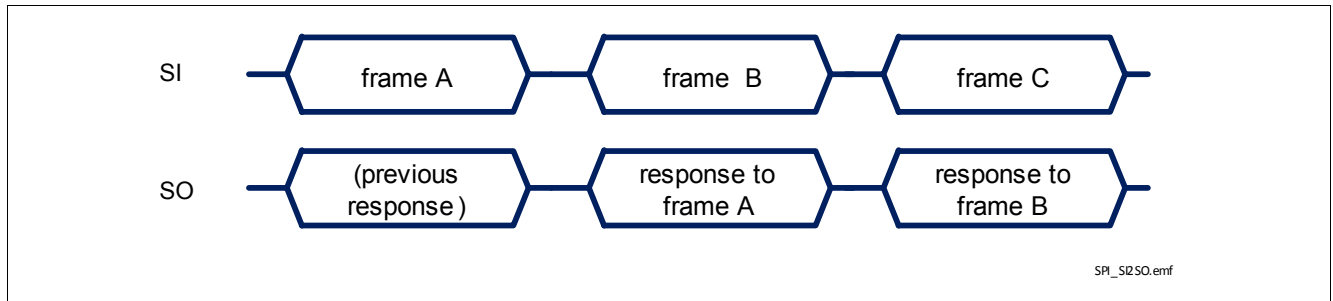
Table 13 Electrical Characteristics Serial Peripheral Interface (SPI) (cont'd)

Parameter	Symbol	Values			Unit	Note / Test Condition	Number
		Min.	Typ.	Max.			
Output enable time (falling CSN to SO valid)	$t_{SO(en)}$	–	–	1	$\mu s$	<sup>1)</sup> $V_{DD} = V_S = 3.0 V$ $C_L = 20 pF$ at SO pin	P_10.4.32
Output disable time (rising CSN to SO tristate)	$t_{SO(dis)}$	–	–	1	$\mu s$	<sup>1)</sup> $V_{DD} = V_S = 3.0 V$ $C_L = 20 pF$ at SO pin	P_10.4.33
Serial clock frequency	$f_{SCLK}$	–	–	1	MHz	<sup>1)</sup> $V_{DD} = V_S = 3.0 V$	P_10.4.34
Serial clock period	$t_{SCLK(P)}$	1	–	–	$\mu s$	<sup>1)</sup> $V_{DD} = V_S = 3.0 V$	P_10.4.35
Serial clock “high” time	$t_{SCLK(H)}$	375	–	–	ns	<sup>1)</sup> $V_{DD} = V_S = 3.0 V$	P_10.4.36
Serial clock “low” time	$t_{SCLK(L)}$	375	–	–	ns	<sup>1)</sup> $V_{DD} = V_S = 3.0 V$	P_10.4.37
Data setup time (required time SI to falling SCLK)	$t_{SI(su)}$	100	–	–	ns	<sup>1)</sup> $V_{DD} = V_S = 3.0 V$	P_10.4.38
Data hold time (falling SCLK to SI)	$t_{SI(h)}$	100	–	–	ns	<sup>1)</sup> $V_{DD} = V_S = 3.0 V$	P_10.4.39
Output data valid time with capacitive load	$t_{SO(v)}$	–	–	500	ns	<sup>1)</sup> $V_{DD} = V_S = 3.0 V$ $C_L = 20 pF$ at SO pin	P_10.4.40

1) Not subject to production test, specified by design

## 10.5 SPI Protocol

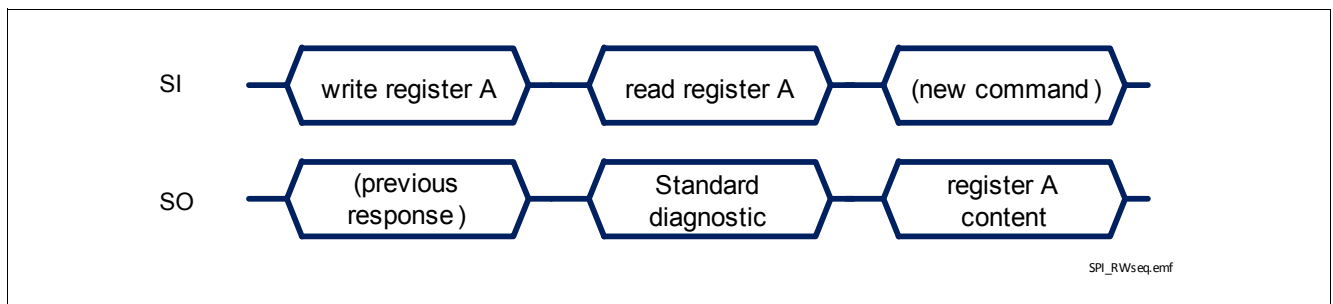
The relationship between SI and SO content during SPI communication is shown in [Figure 37](#). SI line represents the frame sent from the  $\mu$ C and SO line is the answer provided by TLE75242-EMH.



**Figure 37 Relationship between SI and SO during SPI communication**

The SPI protocol provides the answer to a command frame only with the next transmission triggered by the  $\mu$ C. Although the biggest majority of commands and frames implemented in TLE75242-EMH can be decoded without the knowledge of what happened before, it is advisable to consider what the  $\mu$ C sent in the previous transmission to decode TLE75242-EMH response frame completely.

More in detail, the sequence of commands to “read” and “write” the content of a register looks as follows:

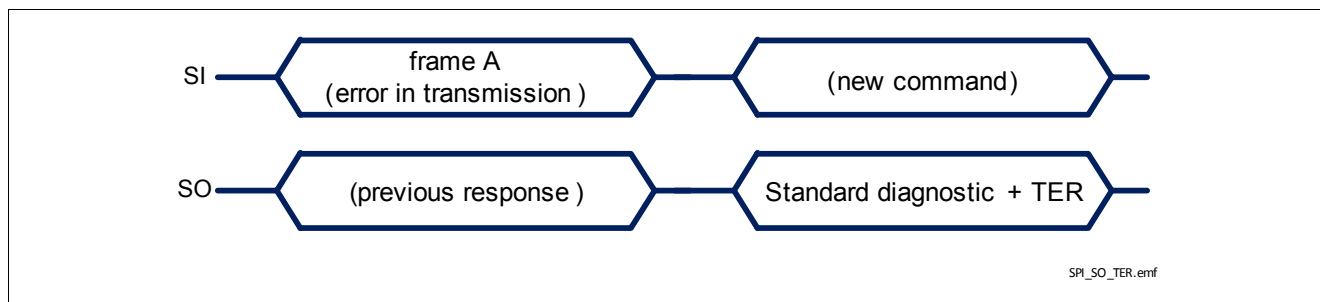


**Figure 38 Register content sent back to  $\mu$ C**

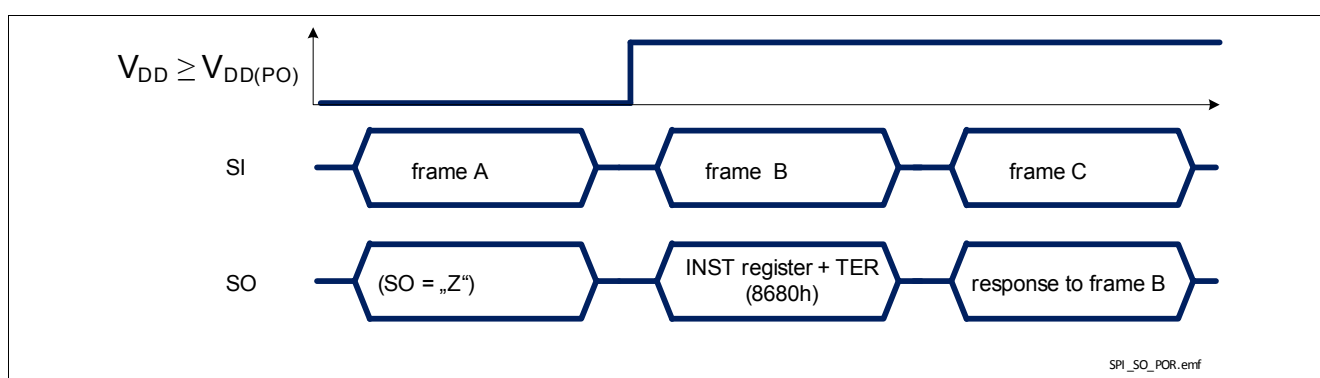
There are 3 special situations where the frame sent back to the  $\mu$ C is not related directly to the previous received frame:

- in case an error in transmission happened during the previous frame (for instance, the clock pulses were not multiple of 8 with a minimum of 16 bits), shown in [Figure 39](#)
- when TLE75242-EMH logic supply comes out of Power-On reset condition or after a Software Reset, as shown in [Figure 40](#)
- in case of command syntax errors
  - “write” command starting with “11” instead of “10”
  - “read” command starting with “00” instead of “01”
  - “read” or “write” commands on registers which are “reserved” or “not used”

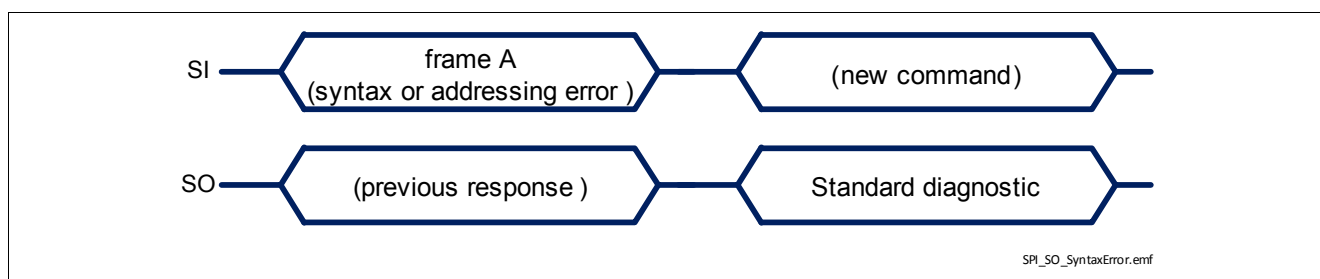
## Serial Peripheral Interface (SPI)



**Figure 39** TLE75242-EMH response after a error in transmission



**Figure 40** TLE75242-EMH response after coming out of Power-On reset at  $V_{DD}$



**Figure 41** TLE75242-EMH response after a command syntax error

A summary of all possible SPI commands is presented in [Table 14](#), including the answer that TLE75242-EMH sends back at the next transmission.

## Serial Peripheral Interface (SPI)

Table 14 SPI Command summary<sup>1)</sup>

Requested Operation	Frame sent to SPIDER+ (SI pin)	Frame received from SPIDER+ (SO pin) with the next command
Read Standard Diagnosis	0xxxxxxxxxxxxxxxxx01 <sub>B</sub> ("xxxxxxxxxxxxxxxx <sub>B</sub> " = don't care)	0ddddddddddddddd <sub>B</sub> (Standard Diagnosis)
Write 10 bit register	10aaaaccccccccccc <sub>B</sub> where: "aaa <sub>B</sub> " = register address ADDR0 "cccccccccc <sub>B</sub> " = new register content	0ddddddddddddddd <sub>B</sub> (Standard Diagnosis)
Read 10 bit registers	01aaaaxxxxxxxxxx10 <sub>B</sub> where: "aaa <sub>B</sub> " = register address ADDR0 "xxxxxxxx <sub>B</sub> " = don't care	10aaaaccccccccccc <sub>B</sub> where: "aaa <sub>B</sub> " = register address ADDR0 "cccccccccc <sub>B</sub> " = register content
Write 8 bit register	10aaaabbcccccccccc <sub>B</sub> where: "aaa <sub>B</sub> " = register address ADDR0 "bb <sub>B</sub> " = register address ADDR1 "cccccccccc <sub>B</sub> " = new register content	0ddddddddddddddd <sub>B</sub> (Standard Diagnosis)
Read 8 bit registers	01aaaabbxxxxxxxx10 <sub>B</sub> where: "aaa <sub>B</sub> " = register address ADDR0 "bb <sub>B</sub> " = register address ADDR1 "xxxxxxxx <sub>B</sub> " = don't care	10aaaabbcccccccccc <sub>B</sub> where: "aaa <sub>B</sub> " = register address ADDR0 "bb <sub>B</sub> " = register address ADDR1 "cccccccccc <sub>B</sub> " = register content

1) "a" = address bits for ADDR0 field, "b" = address bit for ADDR1 field, "c" = register content, "d" = diagnostic bit

## 10.6 SPI Registers Overview

### 10.6.1 Standard Diagnosis

**Table 15** Standard Diagnosis

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	Default
----	----	----	----	----	----	---	---	---	---	---	---	---	---	---	---	---------

0	UVR VS	LOP VDD	MODE	TER	OL ON	OL OFF	ERR									7800 <sub>H</sub>
---	-----------	------------	------	-----	----------	-----------	-----	--	--	--	--	--	--	--	--	-------------------

Field	Bits	Type	Description
UVRVS	14	r	<b><math>V_S</math> Undervoltage Monitor</b> 0 <sub>B</sub> No undervoltage condition on $V_S$ detected (see <a href="#">Chapter 6.2.1</a> for more details) 1 <sub>B</sub> (default) There was at least one $V_S$ Undervoltage condition since last Standard Diagnosis readout
LOPVDD	13	r	<b><math>V_{DD}</math> Lower Operating Range Monitor</b> 0 <sub>B</sub> $V_{DD}$ is above $V_{DD(LOP)}$ 1 <sub>B</sub> (default) There was at least one " $V_{DD} = V_{DD(LOP)}$ " condition since last Standard Diagnosis readout
MODE	12:11	r	<b>Operative Mode Monitor</b> 00 <sub>B</sub> (reserved) 01 <sub>B</sub> Limp Home Mode 10 <sub>B</sub> Active Mode 11 <sub>B</sub> (default) Idle Mode
TER	10	r	<b>Transmission Error</b> 0 <sub>B</sub> Previous transmission was successful (modulo 16 + n*8 clocks received, where n = 0, 1, 2...) 1 <sub>B</sub> (default) Previous transmission failed The first frame after a reset is <b>TER</b> set to "high" and the <b>INST</b> register. The second frame is the Standard Diagnosis with <b>TER</b> set to "low" (if there was no fail in the previous transmission).
OLON	9	r	<b>Open Load at ON state Diagnosis</b> 0 <sub>B</sub> (default) No Open Load at ON detected 1 <sub>B</sub> Open Load at ON detected See <a href="#">Chapter 9.3.3</a> for a detailed explanation

## Serial Peripheral Interface (SPI)

Field	Bits	Type	Description
OLOFF	8	r	<b>Open Load in OFF Diagnosis</b> $0_B$ (default) All channels in OFF state (which have <b>DIAG_IOL.OUTn</b> bit set to "1") have $V_{DS} > V_{DS(OL)}$ (Low-Side channels and Auto-configurable used as Low-Side switches) or $V_{OUT\_S} < V_{OUT\_S(OL)}$ (High-Side channels and Auto-configurable used as High-Side switches) $1_B$ At least one channel in OFF state (with <b>DIAG_IOL.OUTn</b> bit set to "1") has $V_{DS} < V_{DS(OL)}$ (Low-Side channels and Auto-configurable used as Low-Side switches) or $V_{OUT\_S} > V_{OUT\_S(OL)}$ (High-Side channels and Auto-configurable used as High-Side switches) Channels in ON state are not considered
ERRn n = 7 to 0	n:0	r	<b>Over Load / Over Temperature Diagnosis of channel n</b> $0_B$ (default) No failure detected $1_B$ Over Temperature or Over Load

## 10.6.2 Register structure

The register banks the digital part have following structure:

**Table 16** Register structure - all registers (with the exclusion of **PWM\_CR0** and **PWM\_CR1**)

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	Default
----	----	----	----	----	----	---	---	---	---	---	---	---	---	---	---	---------

r = 0 w = 1	r = 1 w = 0	ADDR0				ADDR1		DATA								XXXX <sub>H</sub>
----------------	----------------	-------	--	--	--	-------	--	------	--	--	--	--	--	--	--	-------------------

**Table 17** Register structure - **PWM\_CR0** and **PWM\_CR1**

15	14	13	12	11	10	9	8	7	6	5	4	3	2	1	0	Default
----	----	----	----	----	----	---	---	---	---	---	---	---	---	---	---	---------

r = 0 w = 1	r = 1 w = 0	ADDR0				DATA										XXXX <sub>H</sub>
----------------	----------------	-------	--	--	--	------	--	--	--	--	--	--	--	--	--	-------------------

**Table 18** summarizes the available registers with their addressing space and size

**Table 18** Register addressing space

Register name	ADDR0	ADDR1	Size	Type	Purpose
<b>OUT</b> n = 7 to 0	0000 <sub>B</sub>	00 <sub>B</sub>	n	r/w	<b>Power output control register</b> bits OUT.OUTn 0 <sub>B</sub> (default) Output is OFF 1 <sub>B</sub> Output is ON
<b>BIM</b>	0000 <sub>B</sub>	01 <sub>B</sub>	8	r/w	<b>Bulb Inrush Mode</b> bits BIM.OUTn 0 <sub>B</sub> (default) Output latches OFF in case of errors 1 <sub>B</sub> Output restarts automatically in case of errors
<b>MAPIN0</b> n = 7 to 0	0001 <sub>B</sub>	00 <sub>B</sub>	n	r/w	<b>Input Mapping (Input Pin 0)</b> bits MAPIN0.OUTn 0 <sub>B</sub> (default) The output is not connected to the input pin 1 <sub>B</sub> The output is connected to the input pin Note: Channel 2 has the corresponding bit set to "1" by default
<b>MAPIN1</b> n = 7 to 0	0001 <sub>B</sub>	01 <sub>B</sub>	n	r/w	<b>Input Mapping (Input Pin 1)</b> bits MAPIN1.OUTn 0 <sub>B</sub> (default) The output is not connected to the input pin 1 <sub>B</sub> The output is connected to the input pin Note: Channel 3 has the corresponding bit set to "1" by default

## Serial Peripheral Interface (SPI)

Table 18 Register addressing space (cont'd)

Register name	ADDR0	ADDR1	Size	Type	Purpose
<b>INST</b>	0001 <sub>B</sub>	10 <sub>B</sub>	8	r	<b>Input Status Monitor</b> bit $TER$ 0 <sub>B</sub> Previous transmission was successful (modulo 16 + n*8 clocks received, where n = 0, 1, 2...) 1 <sub>B</sub> (default) Previous transmission failed bits $INST.RES$ (6:2) - reserved bits $INST.INn$ (1:0) 0 <sub>B</sub> (default) The input pin is set to "low" 1 <sub>B</sub> The input pin is set to "high" First register transmitted after a reset of the logic
<b>DIAG_IOL</b> n = 7 to 0	0010 <sub>B</sub>	00 <sub>B</sub>	n	r/w	<b>Open Load diagnostic current control</b> bits $DIAG\_IOL.OUTn$ 0 <sub>B</sub> (default) Diagnosis current not enabled 1 <sub>B</sub> Diagnosis current enabled
<b>DIAG_OSM</b> n = 7 to 0	0010 <sub>B</sub>	01 <sub>B</sub>	n	r	<b>Output Status Monitor</b> bits $DIAG\_OSM.OUTn$ 0 <sub>B</sub> (default) $V_{DS} > V_{DS(OL)}$ (Low-Side channels and Auto-configurable used as Low-Side switches) or $V_{OUT\_S} < V_{OUT\_S(OL)}$ (High-Side channels and Auto-configurable used as High-Side switches) 1 <sub>B</sub> $V_{DS} < V_{DS(OL)}$ (Low-Side channels and Auto-configurable used as Low-Side switches) or $V_{OUT\_S} > V_{OUT\_S(OL)}$ (High-Side channels and Auto-configurable used as High-Side switches)
<b>DIAG_OLON</b>	0010 <sub>B</sub>	10 <sub>B</sub>	8	r	<b>Open Load at ON monitor</b> bits $DIAG\_OLON.OUTn$ (7:2) 0 <sub>B</sub> (default) normal operation or diagnosis performed on channel OFF 1 <sub>B</sub> Open Load at ON detected bits (1:0) - reserved (default: 0 <sub>B</sub> ) This feature is active only on High-Side channels and auto-configurable channels used as High-Side switches

## Serial Peripheral Interface (SPI)

Table 18 Register addressing space (cont'd)

Register name	ADDR0	ADDR1	Size	Type	Purpose
DIAG_OLONEN	0010 <sub>B</sub>	11 <sub>B</sub>	8	r/w	<b>Open Load at ON diagnostic control</b> bits (7:4) - reserved bits DIAG_OLONEN.MUX (3:0) 0000 <sub>B</sub> (reserved) 0001 <sub>B</sub> (reserved) 0010 <sub>B</sub> Open Load at ON diagnostic active on channel 2 0011 <sub>B</sub> Open Load at ON diagnostic active on channel 3 0100 <sub>B</sub> Open Load at ON diagnostic active on channel 4 0101 <sub>B</sub> Open Load at ON diagnostic active on channel 5 0110 <sub>B</sub> Open Load at ON diagnostic active on channel 6 0111 <sub>B</sub> Open Load at ON diagnostic active on channel 7 1000 <sub>B</sub> (reserved) 1001 <sub>B</sub> (reserved) 1010 <sub>B</sub> Open Load at ON diagnosis loop start 1011 <sub>B</sub> (reserved) 1100 <sub>B</sub> (reserved) 1101 <sub>B</sub> (reserved) 1110 <sub>B</sub> (reserved) 1111 <sub>B</sub> (default) Open Load at ON diagnostic not active
HWCR	0011 <sub>B</sub>	00 <sub>B</sub>	8	r/w	<b>Hardware Configuration Register</b> bit HWCR.ACT (7) (Active Mode) 0 <sub>B</sub> (default) Normal operation or device leaves Active Mode 1 <sub>B</sub> Device enters Active Mode (see <a href="#">Chapter 6.1</a> for a description of the possible operative mode transitions) bit HWCR.RST (6) (Reset) 0 <sub>B</sub> (default) Normal operation 1 <sub>B</sub> Execute Reset command (self clearing) bits HWCR.PAR (3:0) (channels operating in parallel) 0 <sub>B</sub> (default) Normal operation 1 <sub>B</sub> two neighbour channels have Over Load and Over Temperature synchronized (see <a href="#">Chapter 7.3</a> for more details) bits 5:4 - reserved (default: 0 <sub>B</sub> )
HWCR_OCL n = 7 to 0	0011 <sub>B</sub>	01 <sub>B</sub>	n	w	<b>Output Clear Latch</b> bits HWCR_OCL.OUTn 0 <sub>B</sub> (default) Normal operation 1 <sub>B</sub> Clear the error latch for the selected output

## Serial Peripheral Interface (SPI)

Table 18 Register addressing space (cont'd)

Register name	ADDR0	ADDR1	Size	Type	Purpose
HWCR_PWM	0011 <sub>B</sub>	10 <sub>B</sub>	8	r/w	<b>PWM Configuration Register</b> bits HWCR_PWM.ADJ (7:4) 0000 <sub>B</sub> (reserved) 0001 <sub>B</sub> base frequency $f_{INT} - 37.2\%$ 0010 <sub>B</sub> base frequency $f_{INT} - 31.9\%$ 0011 <sub>B</sub> base frequency $f_{INT} - 26.9\%$ 0100 <sub>B</sub> base frequency $f_{INT} - 21.0\%$ 0101 <sub>B</sub> base frequency $f_{INT} - 15.5\%$ 0110 <sub>B</sub> base frequency $f_{INT} - 10.9\%$ 0111 <sub>B</sub> base frequency $f_{INT} - 5.8\%$ 1000 <sub>B</sub> (default) base frequency $f_{INT}$ 1001 <sub>B</sub> base frequency $f_{INT} + 4.3\%$ 1010 <sub>B</sub> base frequency $f_{INT} + 8.9\%$ 1011 <sub>B</sub> base frequency $f_{INT} + 14.0\%$ 1100 <sub>B</sub> base frequency $f_{INT} + 19.5\%$ 1101 <sub>B</sub> base frequency $f_{INT} + 25.6\%$ 1110 <sub>B</sub> base frequency $f_{INT} + 32.4\%$ 1111 <sub>B</sub> base frequency $f_{INT} + 40.0\%$ bits HWCR_PWM.PWM1 (1) 0 <sub>B</sub> (default) PWM Generator 1 not active 1 <sub>B</sub> PWM Generator 1 active bits HWCR_PWM.PWM0 (0) 0 <sub>B</sub> (default) PWM Generator 0 not active 1 <sub>B</sub> PWM Generator 0 active bits HWCR_PWM.RES (3:2) - reserved
PWM_CR0	0100 <sub>B</sub>	—	10	r/w	<b>PMW Generator Configuration 0</b> bits PWM_CR0.FREQ (9:8) 00 <sub>B</sub> (default) internal clock divided by 1024 01 <sub>B</sub> internal clock divided by 512 10 <sub>B</sub> internal clock divided by 256 11 <sub>B</sub> 100% duty cycle bits PWM_CR0.DC (7:0) (resolution: 0.39%) 00000000 <sub>B</sub> , PWM generator is OFF 11111111 <sub>B</sub> , PWM generator is ON (99.61% duty cycle)
PWM_CR1	0101 <sub>B</sub>	—	10	r/w	<b>PMW Generator Configuration 1</b> bits PWM_CR1.FREQ (9:8) 00 <sub>B</sub> (default) internal clock divided by 1024 01 <sub>B</sub> internal clock divided by 512 10 <sub>B</sub> internal clock divided by 256 11 <sub>B</sub> 100% duty cycle bits PWM_CR1.DC (7:0) (resolution: 0.39%) 00000000 <sub>B</sub> , PWM generator is OFF 11111111 <sub>B</sub> , PWM generator is ON (99.61% duty cycle)

**Table 18 Register addressing space (cont'd)**

Register name	ADDR0	ADDR1	Size	Type	Purpose
<b>PWM_OUT</b>	1001 <sub>B</sub>	00 <sub>B</sub>	8	r/w	<b>PWM Generator Output Control</b> bits PWM_OUT.OUTn 0 <sub>B</sub> (default) The selected output is not driven by one of the two PWM Generators 1 <sub>B</sub> The selected output is connected to a PWM Generator
<b>PWM_MAP</b>	1001 <sub>B</sub>	01 <sub>B</sub>	8	r/w	<b>PWM Generator Output Mapping</b> bits PWM_MAP.OUTn 0 <sub>B</sub> (default) The selected output is connected to PWM Generator 0 1 <sub>B</sub> The selected output is connected to PWM Generator 1 It is necessary to set the <b>PWM_OUT</b> register to activate the PWM Generator control for the outputs.

### 10.6.3 Register summary

All registers with addresses not mentioned in **Table 19** and **Table 20** have to be considered as “reserved”. “Read” operations performed on those registers return the Standard Diagnosis. The column “Default” indicates the content of the register (8 or 10 bits) after a reset.

**Table 19 Addressable registers (basic functions)**

15	14	13-10	9	8	7	6	5	4	3	2	1	0	Default
r = 0 w = 1	r = 1 w = 0	0000	00	OUT.OUTn									00 <sub>H</sub>
r = 0 w = 1	r = 1 w = 0	0001	00	MAPIN0.OUTn									04 <sub>H</sub>
r = 0 w = 1	r = 1 w = 0	0001	01	MAPIN1.OUTn									08 <sub>H</sub>
0	1	0001	10	TER	(reserved)						INST.INn	00 <sub>H</sub>	
r = 0 w = 1	r = 1 w = 0	0010	00	DIAG_IOL.OUTn									00 <sub>H</sub>
0	1	0010	01	DIAG_OSM.OUTn									00 <sub>H</sub>
r = 0 w = 1	r = 1 w = 0	0011	00	HWCR .ACT	HWCR .RST	(reserved)			HWCR.PAR			00 <sub>H</sub>	
r = 0 w = 1	r = 1 w = 0	0011	01	HWCR_OCL.OUTn									00 <sub>H</sub>

**Table 20 Addressable registers (advanced functions)**

15	14	13-10	9	8	7	6	5	4	3	2	1	0	Default
r = 0 w = 1	r = 1 w = 0	0000	01	BIM.OUTn								00 <sub>H</sub>	
r = 0 w = 1	r = 1 w = 0	0010	10	DIAG_OLON.OUTn						(reserved)		00 <sub>H</sub>	

## Serial Peripheral Interface (SPI)

Table 20 Addressable registers (advanced functions)

15	14	13-10	9	8	7	6	5	4	3	2	1	0	Default
r = 0 w = 1	r = 1 w = 0	0010	11		(reserved)				DIAG_OLONEN.MUX				0F <sub>H</sub>
r = 0 w = 1	r = 1 w = 0	0011	10		HWCR_PWM.ADJ				(reserved)		HWCR_PWM.PWM 1	HWCR_PWM.PWM 0	80 <sub>H</sub>
r = 0 w = 1	r = 1 w = 0	0100	PWM_CR0.FR EQ		PWM_CR0.DC								000 <sub>H</sub>
r = 0 w = 1	r = 1 w = 0	0101	PWM_CR1.FR EQ		PWM_CR1.DC								000 <sub>H</sub>
r = 0 w = 1	r = 1 w = 0	1001	00		PWM_OUT.OUTn								00 <sub>H</sub>
r = 0 w = 1	r = 1 w = 0	1001	01		PWM_MAP.OUTn								00 <sub>H</sub>

### 10.6.4 SPI command quick list

A summary of the most used SPI commands (read and write operations on all registers) is shown in [Table 21](#)

Table 21 SPI command quick list

Register	“read” command”	“write” command	content written
OUT	4002 <sub>H</sub>	80XX <sub>H</sub>	XX <sub>H</sub> = xxxxxxxx <sub>B</sub>
BIM	4102 <sub>H</sub>	81XX <sub>H</sub>	XX <sub>H</sub> = xxxxxxxx <sub>B</sub>
MAPIN0	4402 <sub>H</sub>	84XX <sub>H</sub>	XX <sub>H</sub> = xxxxxxxx <sub>B</sub>
MAPIN1	4502 <sub>H</sub>	85XX <sub>H</sub>	XX <sub>H</sub> = xxxxxxxx <sub>B</sub>
INST	4602 <sub>H</sub>	n.a. (read-only)	–
DIAG_IOL	4802 <sub>H</sub>	88XX <sub>H</sub>	XX <sub>H</sub> = xxxxxxxx <sub>B</sub>
DIAG_OSM	4902 <sub>H</sub>	n.a. (read-only)	–
DIAG_OLON	4A02 <sub>H</sub>	8AXX <sub>H</sub>	XX <sub>H</sub> = xxxxxxxx <sub>B</sub>
DIAG_OLONEN	4B02 <sub>H</sub>	8BXX <sub>H</sub>	XX <sub>H</sub> = xxxxxxxx <sub>B</sub>
HWCR	4C02 <sub>H</sub>	8CXX <sub>H</sub>	XX <sub>H</sub> = xxxxxxxx <sub>B</sub>
HWCR_OCL	4D02 <sub>H</sub>	8DXX <sub>H</sub>	XX <sub>H</sub> = xxxxxxxx <sub>B</sub>
HWCR_PWM	4E02 <sub>H</sub>	8EXX <sub>H</sub>	XX <sub>H</sub> = xxxxxxxx <sub>B</sub>
PWM_CR0	5002 <sub>H</sub>	90XX <sub>H</sub>	0XX <sub>H</sub> = 00xxxxxxxx <sub>B</sub>
		91XX <sub>H</sub>	1XX <sub>H</sub> = 01xxxxxxxx <sub>B</sub>
		92XX <sub>H</sub>	2XX <sub>H</sub> = 10xxxxxxxx <sub>B</sub>
		93XX <sub>H</sub>	3XX <sub>H</sub> = 11xxxxxxxx <sub>B</sub>
PWM_CR1	5402 <sub>H</sub>	94XX <sub>H</sub>	0XX <sub>H</sub> = 00xxxxxxxx <sub>B</sub>
		95XX <sub>H</sub>	1XX <sub>H</sub> = 01xxxxxxxx <sub>B</sub>
		96XX <sub>H</sub>	2XX <sub>H</sub> = 10xxxxxxxx <sub>B</sub>
		97XX <sub>H</sub>	3XX <sub>H</sub> = 11xxxxxxxx <sub>B</sub>

---

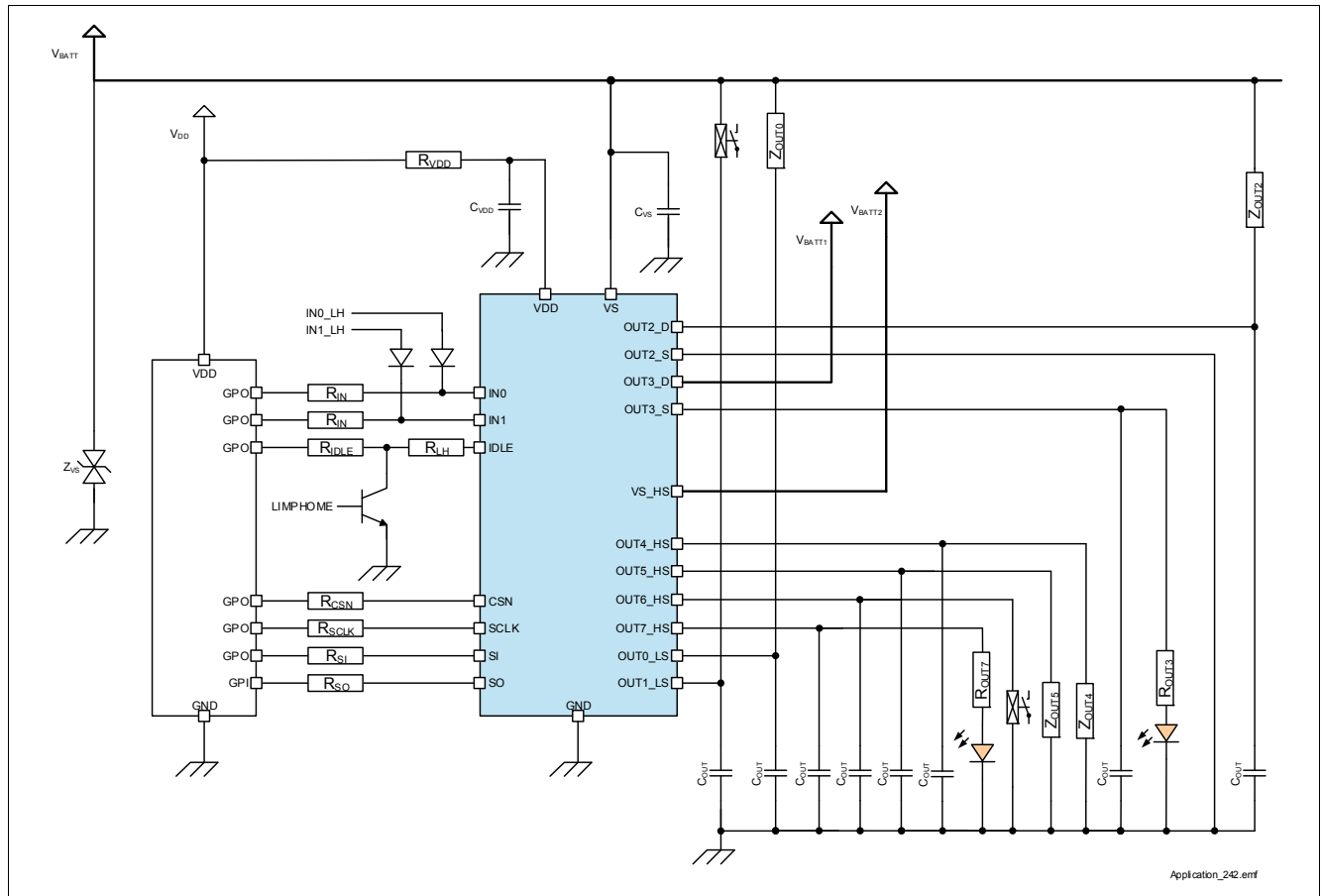
Serial Peripheral Interface (SPI)

**Table 21** SPI command quick list (cont'd)

Register	“read” command”	“write” command	content written
PWM_OUT	6402 <sub>H</sub>	A4XX <sub>H</sub>	XX <sub>H</sub> = xxxxxxxx <sub>B</sub>
PWM_MAP	6502 <sub>H</sub>	A5XX <sub>H</sub>	XX <sub>H</sub> = xxxxxxxx <sub>B</sub>

## 11 Application Information

*Note: The following information is given as a hint for the implementation of the device only and shall not be regarded as a description or warranty of a certain functionality, condition or quality of the device.*



**Figure 42** TLE75242-EMH Application Diagram

*Note: This is a very simplified example of an application circuit. The function must be verified in the real application.*

**Table 22      Suggested Component values**

Reference	Value	Purpose
$R_{IN}$	4.7 k $\Omega$	Protection of the micro-controller during Over Voltage and Reverse Polarity Guarantee TLE75242-EMH channels OFF during Loss of Ground
$R_{IDLE}$	4.7 k $\Omega$	Protection of the micro-controller during Over Voltage and Reverse Polarity Guarantee TLE75242-EMH channels OFF during Loss of Ground
$R_{CSN}$	500 $\Omega$	Protection of the micro-controller during Over Voltage and Reverse Polarity
$R_{SCLK}$	500 $\Omega$	Protection of the micro-controller during Over Voltage and Reverse Polarity
$R_{SI}$	500 $\Omega$	Protection of the micro-controller during Over Voltage and Reverse Polarity
$R_{SO}$	500 $\Omega$	Protection of the micro-controller during Over Voltage and Reverse Polarity
$R_{VDD}$	100 $\Omega$	Logic supply voltage spikes filtering
$C_{VDD}$	100 nF	Logic supply voltage spikes filtering
$C_{VS}$	68 nF	Analog supply voltage spikes filtering

**Table 22 Suggested Component values (cont'd)**

Reference	Value	Purpose
$Z_{VS}$	P6SMB30	Protection of device during Over Voltage. Zener diode
$C_{OUT}$	10 nF	Protection of TLE75242-EMH against ESD and BCI

## 11.1 Further Application Information

- Please contact us for information regarding the Pin FMEA
- For further information you may contact <http://www.infineon.com/>

## 12 Package Outlines

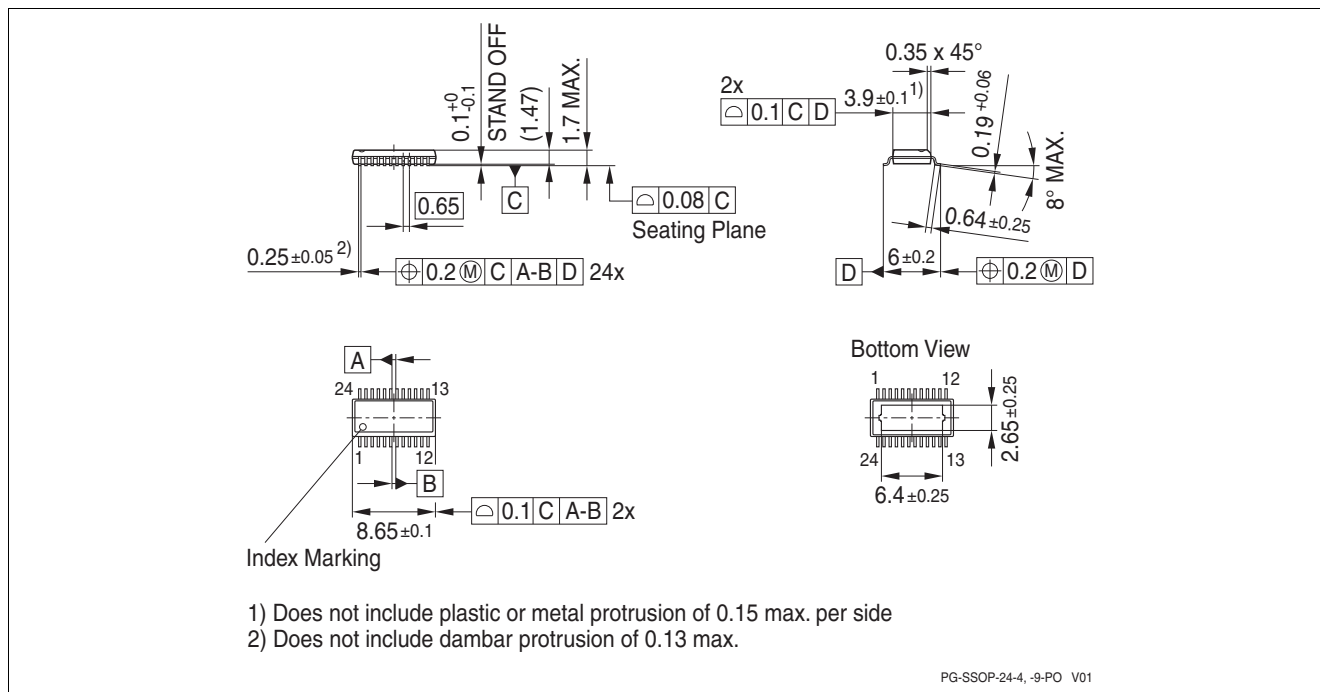


Figure 43 PG-SSOP-24-9 Package drawing

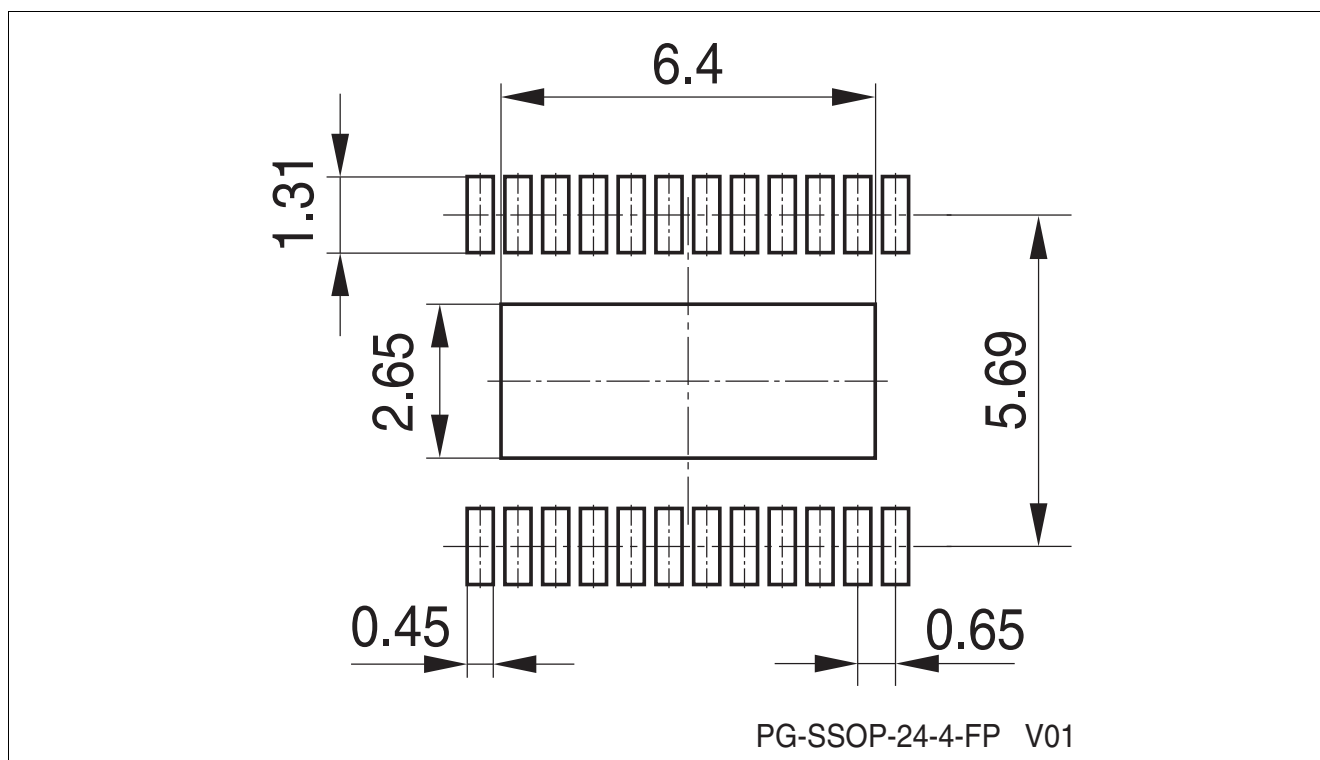


Figure 44 TLE75242-EMH Package pads and stencil

*Note: Although the package footprint refer to PG-SSOP-24-4, they can be used as reference also the PG-SSOP-24-9 (physical dimensions are the same).*

**Green Product (RoHS compliant)**

To meet the world-wide customer requirements for environmentally friendly products and to be compliant with government regulations the device is available as a green product. Green products are RoHS-Compliant (i.e Pb-free finish on leads and suitable for Pb-free soldering according to IPC/JEDEC J-STD-020).

## 13 Revision History

Page or Item	Changes since previous revision
All	
<b>Rev. 1.0, 2016-06-22</b>	
TLE75242-EMH	Datasheet released
LED package	

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